

# STIC Search Report

## STIC Database Tracking Number 143378

TO: Victor Mandala

**AU 2826** 

Location: JEF-4C29

2/10/2005 10/020,004 From: Jeff Harrison

Location: STIC-EIC2800

**JEF-4B68** 

Phone: 22511

Email: harrison, jeff

## Search Notes

Re: An individual-semiconductor-nanowire as a bio/chem sensor

Attached are edited results from Chemical Abstracts and nonpatent literature. See especially the asterisk-tagged items at the top of the results – some of these talk about individual semiconductor/carbon nanotube/nanowire as a chem or bio sensor.

All attached results have either a pre-2001 publication date or a pre-2001 priority date.

If you have questions or comments or would like further searching, let me know.

Respectfully, Jeff

Jeff Harrison Team Leader, STIC-EIC2800 JEF-4B68, 571-272-2511



SEARCH REQUEST FORM Scientific and Technical Information Center - EIC2800  Rev 3/15/2004 This is an experimental format Please give suggestions or comments to Jeff Harrison, JEF-4B68, 272-2511.							
Date 1-25-05   Serial # 10/020, 004   Priority Application Date 12-11-00							
Mar Name Victor Mandala Examiner # 79234							
AU 2826 Phone X 1918 Room 4029							
In what format would you like your results? Paper is the default. PAPER DISK EMAIL							
If submitting more than one search, please prioritize in order of need.							
The EIC searcher normally will contact you before beginning a prior art search. If you would like to sit with a searcher for an interactive search, please notify one of the searchers.							
Where have you searched so far on this case? Circle: USPT DWPI EPO Abs JPO Abs IBM TDB							
Other: East word search on all available databases							
What relevant art have you found so far? Please attach pertinent citations or Information Disclosure Statements.							
What types of references would you like? Please checkmark:							
Primary Refs X Nonpatent Literature X Other Secondary Refs X Foreign Patents							
Teaching Refs							
What is the topic, such as the <u>novelty</u> , motivation, utility, or other specific facets defining the desired <u>focus</u> of this search? Please include the concepts, synonyms, keywords, acronyms, registry numbers, definitions, structures, strategies, and anything else that helps to describe the topic. Please attach a copy of the abstract and pertinent claims.							
seniconductor (nanowire nanotube) & Sensor.							
Additional detail:							
Sensor - senses chemical or biological reaction entity							
Look at claims 1 & 2							
A sheet is attached listing all analytes.							
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Staff Use Only  Searcher: HARRISON Structure (#) STN							
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## STIC Search Results Feedback Form

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Questions about the scope or the results of the search? Contact the EIC searcher or contact:

Jeff Harrison, EIC 2800 Team Leader 571-272-2511, JEF 4B68

Voluntary Results Feedback Form						
> I am an examiner in Workgroup: Example: 2810						
Relevant prior art <b>found</b> , search results used as follows:						
☐ 102 rejection						
☐ 103 rejection						
Cited as being of interest.						
Helped examiner better understand the invention.						
Helped examiner better understand the state of the art in their technology.						
Types of relevant prior art found:						
☐ Foreign Patent(s)						
<ul> <li>Non-Patent Literature         (journal articles, conference proceedings, new product announcements etc.)     </li> </ul>						
> Relevant prior art <b>not found:</b>						
Results verified the lack of relevant prior art (helped determine patentability).						
Results were not useful in determining patentability or understanding the invention.						
Comments:						

Drop off or send completed forms to STICIZICION, CP4-9C18



## 10feb05 15:45:12 User259284 Session D3065.2

## File 305:Analytical Abstracts 1980-2005/Feb W1 (c) 2005 Royal Soc Chemistry

Description Items Set SEMICOND????????? (3N) NANO?????????? 21 S1

10feb05 15:46:28 User259284 Session D3065.3

#### 5:Biosis Previews(R) 1969-2005/Feb W1 ·File (c) 2005 BIOSIS

Items Description Set

SEMICOND????????? (3N) NANO?????????? 94

Sl S1 AND (NT OR NTS OR SWNT? ? OR DWNT? ? OR NANOTUB? OR NAN-S2 OFIB? OR NANOWIR? OR NANO(2N) (TUBE?? OR WIRE?? OR WIRING?? OR FIBR????? OR FIBER???))

## 10feb05 15:49:12 User259284 Session D3065.4

## File 94:JICST-EPlus 1985-2005/Dec W4 (c) 2005 Japan Science and Tech Corp(JST)

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S4	15	S2 NOT S3
S5	0	S1 AND NANOSENS?
S6	0	S1 AND NANOBIOSENS?
<b>S</b> 7	2	S1 AND BIOSENS?
S8	0	S1 AND BIODETECT?
S9	20	S1 AND DETECT?????
S10	9	S1 AND SENS????
<b>S11</b>	27	\$5:\$10
S12	19	S11/2001-2005
S13	8	S11 NOT S12

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     FILE 'HCAPLUS' ENTERED AT 13:35:09 ON 10 FEB 2005
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                     (L1 OR L2)
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L3
           381 S
                     L3 AND 1996/PY
L4
                     L3 AND 1996-2000/PY
           1739 S
L5
                     L2 AND 1996-2000/PY
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L8
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L13
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           17818 S
  L41
            31150 S
  L42
  SWNT OR DWNT OR NTS OR (SEMICOND###### OR "C" OR CARBON####) (2A)NT)
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                5 S
   L64
   DETECT######)/TI
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HCAPLUS COPYRIGHT 2ACS on STN
ΑN
     2000:516335 HCAPLUS Full-text
DN
     133:230866
     Entered STN: 31 Jul 2000
ED
     Chemical control of nanotube electronics
TΙ
ΑU
     Peng, Shu; Cho, Kyeongjae
     Division of Mechanics and Computation, Stanford University, Stanford, CA,
CS
     94305, USA
     Nanotechnology (2000), 11(2), 57-60
SO
     CODEN: NNOTER; ISSN: 0957-4484
     Institute of Physics Publishing
PΒ
DT
     Journal
LA
     English
     76-2 (Electric Phenomena)
      The possibility of modifying the electronic properties of nanotubes using gas mol. adsorption
AΒ
      is investigated using the first-principles total energy d. functional calcns. Detailed anal.
      of the electronic structures and energetics is performed for the semiconducting (10,0) single-
      walled carbon nanotube interacting with several representative gas mols. (NO2, NH3, CO, O2,
      and H2O). The results elucidate the mechanisms of the adsorption-induced nanotube doping and
      illustrate an example of the simulation-based design characterization of nanoelectronic
     chem control carbon nanotube electronics
ST
TI
     Nanotubes
     RL: PRP (Properties)
         (carbon; chemical control of nanotube electronics)
     Electronic properties
ΙT
         (chemical control of nanotube electronics)
               THERE ARE 15 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
RE .
(1) Charlier, J; Appl Phys A 1998, V67, P79
(2) Chico, L; Phys Rev Lett 1996, V76, P971 HCAPLUS
(3) Cornwell, C; Chem Phys 1998, V109, P763 HCAPLUS
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(6) Iijima, S; J Chem Phys 1996, V104, P2089 HCAPLUS
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(9) Payne, M; Rev Mod Phys 1992, V64, P1045 HCAPLUS
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(11) Service, R; Science 1999, V285, P2053 HCAPLUS
(12) Srivastava, D; Phys Rev Lett 1999, V83, P2973 HCAPLUS
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ANSWER 8 OF 10 HCAPLUS COPYRIGHT ACS on STN
     2000:88136 HCAPLUS
     132:201560
DN
     Entered STN: 08 Feb 2000
     Nanotube molecular wires as chemical
TI
     Kong, Jing; Franklin, Nathan R.; Zhou, Chongwu; Chapline, Michael G.;
ΑU
     Peng, Shu; Cho, Kyeongjae; Dailt, Hongjie
     Department of Chemistry, Stanford University, Stanford, CA, 94305, USA
CS
     Science (Washington, D. C.) (2000), 287(5453), 622-625
SO
     CODEN: SCIEAS; ISSN: 0036-8075
     Chemical sensors based on individual single-walled C nanotubes (SWNTs) are demonstrated. Upon
AB
      exposure to gaseous mols. such as NO2 or NH3, the elec. resistance of a semiconducting SWNT
      dramatically increases or decrease. This serves as the basis for nanotube mol. sensors. The
      nanotube sensors exhibit a fast response and a substantially higher sensitivity than that of
      existing solid-state sensors at room temperature Sensor reversibility is achieved by slow
      recovery under ambient conditions or by heating to high temps. The interactions between mol.
      species and SWNTs and the mechanisms of mol. sensing with nanotube mol. wires are studied.
IT
     Nanotubes
     RL: AMX (Analytical matrix); PEP (Physical, engineering or chemical
     process); PRP (Properties); TEM (Technical or engineered material use);
     ANST (Analytical study); PROC (Process); USES (Uses)
         (carbon; nanotube mol. wires as chemical
        sensors)
IT
     Wires
         (mol.; nanotube mol. wires as chemical
         sensors)
     Electric conductivity
IT
     Electric current-potential relationship
      Electric resistance
      Sensors
         (nanotube mol. wires as chemical
      7664-41-7, Ammonia, analysis 10102-44-0, Nitrogen dioxide, analysis
IT
      RL: ANT (Analyte); ANST (Analytical study)
         (nanotube mol. wires as chemical
         sensors)
      7440-44-0, Carbon, properties
TT
      RL: AMX (Analytical matrix); PEP (Physical, engineering or chemical
      process); PRP (Properties); TEM (Technical or engineered material use);
      ANST (Analytical study); PROC (Process); USES (Uses)
         (nanotube; nanotube mol. wires as chemical sensors)
              THERE ARE 27 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT 27
  (1) Anon; MRS Bull 1999, V24
 (2) Baughman, R; Science 1999, V284, P1340 HCAPLUS
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  (21) Shimizu, Y; MRS Bull 1999, V24, P18 HCAPLUS
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  (23) Soh, T; Appl Phys Lett 1999, V75, P627
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  (26) Wong, S; Nature 1998, V394, P52 HCAPLUS
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(27) Zhou, C; in preparation

#### REPORTS

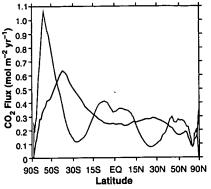


Fig. 3. Zonal mean anthropogenic CO<sub>2</sub> accumulation rate in the ocean (black line) and zonal mean anthropogenic CO<sub>2</sub> flux into the ocean (magenta line), by latitude band (averaged over land and ocean areas for 1995). The latitude axis is scaled so that equal horizontal distances represent equal areas on Earth's surface. On this scale, the total flux or accumulation into the ocean is proportional to the area under the appropriate curve. The Southern Ocean is an area with the highest anthropogenic CO<sub>2</sub> fluxes, but the Antarctic Convergence is the area with the largest anthropogenic CO<sub>2</sub> accumulation.

ern Ocean was much more vigorous in the period from  $\sim$ 1350 to 1880 A.D. than in the recent past. Our simulations reflect primarily late-20th century oceanographic conditions and support the conclusion of a subordinate role for deep convection in the Southern Ocean during this time period (21).

Our conclusion that present-day Southern Ocean uptake of anthropogenic carbon is large, but Southern Ocean storage is relatively small, has implications for the mechanisms governing future changes in the ocean carbon cycle. If most of the anthropogenic carbon entering the Southern Ocean is being transported northward isopycnally to the Antarctic Convergence, then a reduction in deep convection would have little impact on Southern Ocean uptake of anthropogenic carbon. Thus, the particular scenario described in (6) seems unlikely to occur. Changes in ocean circulation, reduction in sea ice coverage, temperature-dependent changes in CO2 solubility, and changes in biological activity will impact oceanic CO2 uptake (6, 15). Nevertheless, if global climate change reduces the density of surface waters in the Southern Ocean (6, 15), isopycnal surfaces that are now ventilated would become isolated from the atmosphere; this would tend to diminish Southern Ocean carbon uptake.

References and Notes

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   The horizontal sizes of regions of brine-induced convection are very small in comparison to the grid cells in our model. Thus, a first-order representation of

- this subgrid-scale convection process is to sink rejected salt without mixing other tracers (10, 13).
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- 19. Evidence of deep penetration of CFCs in the Southern Ocean [A. H. Orsi, G. C. Johnson, J. L. Bullister, Prog. Oceanogr. 43, 55 (1999)] may appear to contradict the conclusions drawn here. However, CFCs equilibrate with the atmosphere much more rapidly than CO<sub>2</sub> does, and the solubility of CFCs is much more sensitive to changes in temperature than the solubility of CO<sub>2</sub> is. These two factors increase the ratio of CFC to anthropogenic CO<sub>2</sub> concentrations in the Southern Ocean.
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- These conclusions are echoed by a study showing deep convection to play a subordinate role in tracer transport in the North Atlantic [A. J. Watson et al., Nature 401, 902 (1999)].
- Nature 401, 902 (1999)].

  22. We thank N. Gruber, R. M. Key, and C. L. Sabine for their insightful papers and access to the data underlying them. K.C. was supported by the NASA Oceanography Program and the U.S. Department of Energy Center for Research on Ocean Carbon Sequestration. P.B.D. was supported by the Lawrence Livermore National Laboratory Laboratory Directed Research and Development program.

15 July 1999; accepted 2 December 1999

## Nanotube Molecular Wires as Chemical Sensors

Jing Kong, 1\* Nathan R. Franklin, 1\* Chongwu Zhou, 1
Michael G. Chapline, 1 Shu Peng, 2 Kyeongjae Cho, 2 Hongjie Dai 1†

Chemical sensors based on individual single-walled carbon nanotubes (SWNTs) are demonstrated. Upon exposure to gaseous molecules such as  $\mathrm{NO_2}$  or  $\mathrm{NH_3}$ , the electrical resistance of a semiconducting SWNT is found to dramatically increase or decrease. This serves as the basis for nanotube molecular sensors. The nanotube sensors exhibit a fast response and a substantially higher sensitivity than that of existing solid-state sensors at room temperature. Sensor reversibility is achieved by slow recovery under ambient conditions or by heating to high temperatures. The interactions between molecular species and SWNTs and the mechanisms of molecular sensing with nanotube molecular wires are investigated.

Carbon nanotubes are molecular-scale wires with high mechanical stiffness and strength. A SWNT can be metallic, semiconducting, or semimetallic, depending on its chirality (1). Utilization of these properties has led to applications of individual nanotubes or ensembles of nanotubes as scanning probes (2, 3), electron field emission sources (4), actuators

(5), and nanoelectronic devices (6). Here, we report the realization of individual semiconducting-SWNT (S-SWNT)—based chemical sensors capable of detecting small concentrations of toxic gas molecules.

Sensing gas molecules is critical to environmental monitoring, control of chemical processes, space missions, and agricultural and medical applications (7). The detection of NO<sub>2</sub>, for instance, is important to monitoring environmental pollution resulting from combustion or automotive emissions (8). Detection of NH<sub>3</sub> is needed in industrial, medical, and living environments (9). Existing electrical sensor materials include semicon-

<sup>&</sup>lt;sup>1</sup>Department of Chemistry, <sup>2</sup>Department of Mechanical Engineering, Stanford University, Stanford, CA 94305, USA.

<sup>\*</sup>These authors contributed equally to this work. †To whom correspondence should be addressed. Email: hdai@chem.stanford.edu

ducting metal oxides (7-9), silicon devices (10, 11), organic materials (12, 13), and carbon black-polymer composites (14). Semiconducting metal oxides have been widely used for NO2 and NH3 detection (7-9). These sensors operate at high temperatures (200° to 600°C) in order to achieve enhanced chemical reactivity between molecules and the sensor materials for substantial sensitivity (7). Conducting polymers (12) and organic phthalocyanine semiconductors (12, 13) have also been investigated for NO2 or NH3 sensing. The former exhibit limited sensitivity (12), whereas the latter tend to have very high resistivity (sample resistance of >10 gigohms) (13). In this report, we show that the electrical resistance of individual semiconducting SWNTs change by up to three orders of magnitude within several seconds of exposure to NO, or NH, molecules at room temperature. Miniaturized chemical sensors based on individual SWNTs are thus demonstrated. Furthermore, we combine theoretical calculations with experiments to address the underlying fundamental question regarding how molecular species interact with nanotubes and affect their electrical properties.

Semiconducting SWNTs are chiral (m, n) tubes with  $m - n \neq 3 \times$  integer. The band gap  $E_g$  of an S-SWNT scales with its diameter d as  $E_g \sim 1/d$  ( $E_g \propto 0.5$  eV for  $d \sim 1.4$  nm) (1). It

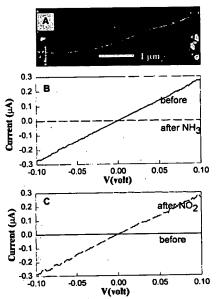
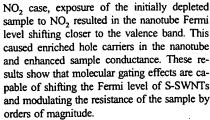


Fig. 1. Changes of electrical characteristics of a semiconducting SWNT in chemical environments. (A) Atomic force microscopy image of a metal/S-SWNT/metal sample used for the experiments. Nanotube diameter is  $\sim$ 1.8 nm. The metal electrodes consist of 20-nm-thick Ni, with 60-nm-thick Au on top. (B) Current versus voltage curves recorded before and after exposure to NH<sub>3</sub>. (C) Current versus voltage curves recorded under  $V_g=+4$  V, before and after NO<sub>2</sub> exposure.

was previously found that when two metal contacts were used to connect an S-SWNT, the metal/S-SWNT/metal system exhibits p-type transistor characteristics with several orders of magnitude change in conductance under various gate voltages (6, 15, 16). Our nanotube chemical sensors were based on these S-SWNT transistors, obtained by controlled chemical vapor deposition growth of individual SWNTs from patterned catalyst islands on SiO<sub>2</sub>/Si substrates (Fig. 1A) (16, 17). Gas-sensing experiments were carried out by placing an S-SWNT sample in a sealed 500-ml glass flask with electrical feedthrough and flowing diluted NO, [2 to 200 parts per million (ppm)] or NH<sub>3</sub> (0.1 to 1%) in Ar or air (flow rate of 700 ml/min) through the flask while monitoring the resistance of the SWNT.

We observed that the conductance of S-SWNT samples can be substantially increased or decreased by exposure to NO2 or NH3. A current versus voltage (I-V) curve recorded with an S-SWNT sample after a 10-min exposure to NH<sub>3</sub> showed an ~100-fold conductance depletion (Fig. 1B). Exposure to NO2 molecules increased the conductance of the SWNT sample by about three orders of magnitude (Fig. 1C) when the SWNT sample was initially depleted by a back-gate voltage  $(V_g)$  of +4 V (6, 15, 16). The SWNT is a hole-doped semiconductor, as can be gleaned from the current versus gate voltage  $(I-V_a)$  curve shown in Fig. 2 (middle curve), where the conductance of the SWNT is observed to decrease by three orders of magnitude under positive gate voltages (6, 15, 16). The I-V curve recorded after the S-SWNT sample was exposed to NH3 exhibits a shift of -4 V (Fig. 2, left curve). In contrast, the I-V, curve was shifted by +4 V after NO<sub>2</sub> exposure (Fig. 2, right curve). The low resistance (~360 kilohms) of the SWNT under zero gate voltage suggests substantial hole carriers existing in the p-type nanotube at room temperature. Exposure to NH, effectively shifts the valence band of the nanotube away from the Fermi level, resulting in hole depletion and reduced conductance. For the



The conductance of the SWNT sample increased sharply by about three orders of magnitude after 200 ppm of NO2 was introduced (Fig. 3A). We investigated five S-SWNT samples and found that the response times (defined as time duration for resistance change by one order of magnitude) of the samples to 200 ppm of NO2 were in the range of 2 to 10 s. The sensitivity [defined as the ratio between resistance after  $(R_{\text{after}})$  and before  $(R_{\text{before}})$  gas exposure] is ~100 to 1000. After the NO<sub>2</sub> flow was replaced by pure Ar, the conductance of the SWNT samples was observed to slowly recover, and the typical recovery time was ~12 hours. This suggests slow molecular desorption from the nanotube sample and that the SWNT chemical sensors can be reversibly used. Heating the exposed sample in air at 200°C led to recovery in ~1 hour. For comparison, a high-performance metal oxide sensor (Cd-doped SnO2) operates at 250°C for detecting 100 ppm of NO2 with a response time of ~50 s, a recovery time of ~8 min, and a sensitivity of ~300 (8, 18). A polypyrole-conducting polymer sensor can detect 0.1% NO<sub>2</sub> by an  $\sim 10\%$  resistance change in  $\sim 5$ to 10 min at room temperature (12). Thus, the S-SWNT sensors have the advantage of room temperature operation with sensitivity up to 103 over these materials.

 $\mathrm{NH_3}$ -sensing results were obtained with the same SWNT sample after recovery from  $\mathrm{NO_2}$  detection (Fig. 3C). The conductance of the SWNT sample was observed to decrease  $\sim 100$ -fold after exposure to a 1%  $\mathrm{NH_3}$  flow. The response times to 1%  $\mathrm{NH_3}$  for five SSWNT samples were  $\sim 1$  to 2 min, and the sensitivity was  $\sim 10$  to 100. For comparison,

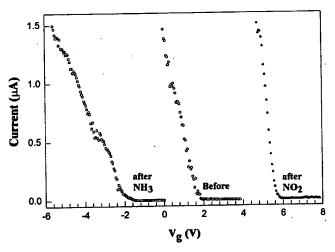


Fig. 2. Chemical gating effects to the semiconducting SWNT. Current versus gate voltage curves before NO<sub>2</sub> (circles), after NO<sub>2</sub> (triangles), and after NH<sub>3</sub> (squares) exposures. The measurements with NH<sub>3</sub> and NO<sub>2</sub> were carried out successively after sample recovery.

metal oxide NH<sub>3</sub> sensors typically operate at  $300^{\circ}$  to  $500^{\circ}$ C, with a response time of  $\sim 1$  min and a sensitivity of  $\sim 1$  to 100 toward 200 ppm to 1% NH<sub>3</sub> (8). Conducting polymer sensors can detect 1% NH<sub>3</sub> with a response time of  $\sim 5$  to 10 min by an  $\sim 30\%$  resistance change at room temperature (12).

For the S-SWNT samples, lowering the NO2 concentration to 20 and 2 ppm led to response times of ~0.5 to 1 min and ~5 min, respectively (Fig. 3B). Lowering the concentration of NH, to 0.1% led to a response time of ~10 min (Fig. 3D). Thus, for detecting an ~10-fold resistance change of individual S-SWNT samples within minutes of gas exposure, the lower concentration limit is ~2 ppm for NO, and ~0.1% for NH<sub>3</sub>. Similar sensing results were obtained when Ar or air was used as the carrier gas. This suggests that NH<sub>2</sub> or NO<sub>2</sub> dominates the response of the SWNT samples over molecules in the ambient environment. Over time, repeated sensing and recovery experiments with the S-SWNT samples obtained reproducible results.

To understand the chemical gating effects and the nanotube gas-sensing mechanism, we first considered the fact that S-SWNT samples appear to be hole doped (*p*-type) before the molecular sensing experiments. Hole doping in S-SWNTs has been observed by several groups (6, 15, 16). Possible hole-doping mechanisms include metal electrode-tube work function mismatch (6) and electrostatic effects due to charged species existing on the SiO<sub>2</sub> surface or bulk (19). Because our nanotubes are long (>3)

μm), we suggested a hole-doping mechanism (for example, charged chemical groups on SiO<sub>2</sub>) operating throughout the nanotube length. As a result of the hole doping, the Fermi level of an S-SWNT is typically located at ~25 meV above the valence band (19), which is responsible for the observed conductance of S-SWNT samples at room temperature (typical resistance of 300 kilohms to 5 megohms). Next, we considered the chemical nature of the molecules. NO2 has an unpaired electron and is known as a strong oxidizer. Upon NO2 adsorption, charge transfer is likely to occur from an SWNT to NO, because of the electron-withdrawing power of the NO, molecules. NH,, on the other hand, is a Lewis base with a lone electron pair that can be donated to other species. However, it is necessary to investigate whether these qualitative pictures represent the correct mechanisms of molecular sensing with SWNTs.

We carried out first-principles calculations on molecule-SWNT complexes using density functional theory (20).  $NO_2$  is found to bind with a semiconducting (10, 0) tube with an adsorption energy  $E_{\rm a}\sim 0.9$  eV (18.6 kcal/mol) and 0.1 electron charge transfer from the tube to a  $NO_2$  molecule. Charge transfer from the nanotube to  $NO_2$  should be the mechanism for increased hole carriers in an S-SWNT and enhanced conductance. For the  $NH_3$ -SWNT system, calculations found no binding affinity between  $NH_3$  molecules and the (10, 0) tube. We suggest two possible indirect routes through which  $NH_3$  molecules may affect S-SWNTs. The first is that  $NH_3$ 

binds to hydroxyl groups on the SiO<sub>2</sub> substrate (21), which could partially neutralize the negatively charged groups on the SiO<sub>2</sub> surface and lead to positive electrostatic gating to the S-SWNT. Second, interactions may exist between NH<sub>3</sub> molecules and an SWNT through other species. It was previously found that NH<sub>3</sub> can interact strongly with adsorbed oxygen species on graphite (22). Preadsorbed oxygen species on a nanotube could interact with NH<sub>3</sub> and affect its electrical properties. These possible mechanisms require further experimental and theoretical investigations.

We also investigated the electrical properties of metallic SWNTs in various chemical environments. A metallic tube was identified by small changes in the conductance with gate voltage (a typical resistance of  $\sim$ 20 to 200 kilohms) (16). We found that, for a typical metallic SWNT, exposure to NO<sub>2</sub> or NH<sub>3</sub> increased or decreased, respectively, the conductance of the sample by  $\leq$ 30%. The explanation for these small changes is that, for a metallic SWNT, small shifts of the Fermi level do not result in a substantial change in the density of states at the Fermi level and, thus, in the charge carriers in the nanotube.

The interactions between NO<sub>2</sub> and NH<sub>3</sub> with graphite have been previously investigated (22-25). For SWNTs, molecular interaction effects have been studied in the case of Br and I intercalation with bulk samples of SWNT ropes (26, 27). The intercalation leads to substantially enhanced sample conductance (26, 27). Our report is concerned with molecular interactions with individual semiconducting and metallic

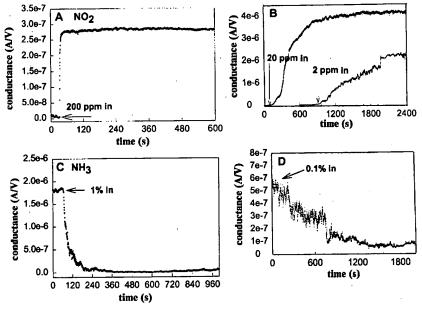


Fig. 3. Electrical response of a semiconducting SWNT to gas molecules. (A) Conductance (under  $V_{\rm g}=+4$  V, in an initial insulating state) versus time in a 200-ppm NO<sub>2</sub> flow. (B) Data for a different S-SWNT sample in 20- and 2-ppm NO<sub>2</sub> flows. The two curves are shifted along the time axis for clarity. (C) Conductance ( $V_{\rm g}=0$ , in an initial conducting state) versus time recorded with the same S-SWNT sample as in (A) in a flow of Ar containing 1% NH<sub>3</sub>. (D) Data recorded with a different S-SWNT sample in a 0.1% NH<sub>3</sub> flow. Read 3.5e-7, for example, as 3.5  $\times$  10<sup>-7</sup>.

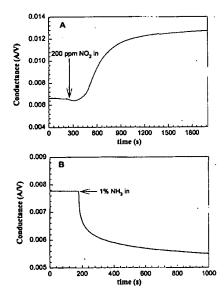


Fig. 4. Electrical response of bulk SWNT mats to  $NO_2$  and  $NH_3$  molecules. (A) Conductance versus time data recorded with an SWNT mat in 200 ppm of  $NO_2$ . (B) Conductance versus time recorded with an SWNT mat in 1%  $NH_3$ .

#### REPORTS

SWNTs. We have also investigated the effects of NO2 and NH3 on the electrical properties of mats of SWNT ropes made from as-grown laser ablation materials. In a 200-ppm NO2 flow, the resistance of an SWNT mat is found to decrease from R = 150 to 80 ohms  $(R_{\text{before}}/R_{\text{after}} \sim 2)$  in ~10 min (Fig. 4A). In a 1% NH, flow, the resistance of a second SWNT mat increases from 120 to 170 ohms  $(R_{\text{after}}/R_{\text{before}} \sim 1.5)$  in ~10 min (Fig. 4B). In these bulk SWNT samples, the molecular interaction effects are averaged over metallic and semiconducting tubes. Also, the inner tubes in SWNT ropes are blocked from interacting with NO2 and NH3 because the molecules are not expected to intercalate into SWNT ropes. This explains the small resistance change of bulk SWNT mats by gas exposure compared to that of an individual S-SWNT.

The main feature of individual S-SWNT sensors, besides their small sizes, is that they operate at room temperature with sensitivity as high as 103. An individual nanotube sensor can be used to detect different types of molecules. The selectivity is achieved by adjusting the electrical gate to set the S-SWNT sample in an initial conducting or insulating state. The fast response of a nanotube sensor can be attributed to the full exposure of the nanotube surface area to chemical environments. Thus, nanotube molecular wires should be promising for advanced miniaturized chemical sensors.

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1 October 1999; accepted 24 November 1999

## Single-File Diffusion of Colloids in One-Dimensional Channels

Q.-H. Wei,\*† C. Bechinger,\* P. Leiderer

Single-file diffusion, prevalent in many processes, refers to the restricted motion of interacting particles in narrow micropores with the mutual passage excluded. A single-filing system was developed by confining colloidal spheres in one-dimensional circular channels of micrometer scale. Optical video microscopy study shows evidence that the particle self-diffusion is non-Fickian for long periods of time. In particular, the distribution of particle displacement is a Gaussian function.

Single-file diffusion (SFD) occurs when the individual pores of the medium are so narrow that the particles are unable to pass each other (1, 2). The sequence of particles remains unchanged over time, and thus, the basic principle of diffusion as a physical mixing process comes into question. The concept of SFD was originally introduced more than 40 years ago in biophysics to account for the transport of water and ions through molecular-sized channels in membranes (3); since then, in addition to biological systems (4, 5), SFD is also discussed in the context of interaction of Markov chains in statistics (6), the transportation of adsorbate molecules through zeolites (2), and charge-carrier migration in one-dimensional (1D) polymer and superionic conductors (7). Furthermore, SFD is also related to surface growth phenomena through some mapping (8).

As the mutual passage of particles is prohibited in single-filing (SF) systems, the movements of individual particles are correlated, even at long time periods, because the displacement of a given particle over a long distance necessitates the motion of many other particles in the same direction. This correlation is reflected in the long-time behavior of the mean-square displacement (MSD), which has been predicted for an infinite system to be (6, 7, 9-11)

$$\langle \Delta x^2 \rangle = 2F\sqrt{t} \tag{1}$$

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†Present address: Department of Physics and Astronomy, University of Pittsburgh, Pittsburgh, PA 15260, where F is the SF mobility and t is time. Accordingly, SFD processes, in contrast to 2D and 3D self-diffusion seen in colloidal systems (12), cannot be described by a diffusion coefficient; that is, the SFD does not obey Fick's laws.

Experimental evidence confirming non-Fickian behavior was unavailable for a long time because of the lack of ideal experimentally accessible SF systems. Recently, measurements of SFD became feasible in artificial crystalline zeolites. Adsorbate molecules, like methane or CF<sub>4</sub> with diameters of 3.8 and 4.7 Å, respectively, confined in AlPO<sub>4</sub> - 5 zeolite with a pore size of 7.3 Å, are considered to be good realizations of SF systems. Although some experimental evidence for the occurrence of SFD was found by pulsed field gradient nuclear magnetic resonance study (13, 14), some results from different groups and experimental methods are still in contradiction, even for the same system (15, 16), as indicated by Hahn and Kärger (17), who suggest and explore several possible reasons. Other effects, such as attractive particle interaction (18), the possible existence of correlations between particles of neighboring pores (19), have also been shown to play a vital role in the mechanism and rates of intracrystalline diffusion. Because of the shortage of structural information on the atomic level, the mechanism of molecular diffusion in zeolites, however, is still under debate.

We created a well-defined SFD model system by confining paramagnetic colloidal spheres of several micrometers in a set of circular trenches fabricated by photolithography. The channels are well-characterized, and the particle-particle interaction can be precisely adjusted by an external magnetic field. Moreover, because the time and length scales in such a colloidal system are easily accessed

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ΑN
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    Bending and buckling of carbon nanotubes under large strain
     Falvo, M. R.; Clary, G. J.; Taylor, R. M., II; Chi, V.; Brooks, F. P.,
AU
     Jr.; Washburn, S.; Superfine, R.
     Dep. Physics and Astronomy, Univ. North Carolina, Chapel Hill, NC, 27599,
CS
     USA
     Nature (London) (1997), 389(6651), 581-584
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     CODEN: NATUAS; ISSN: 0028-0836
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     English
     65-5 (General Physical Chemistry)
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     The curling of a graphitic sheet to form carbon nanotubes produces a class of materials that
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     seem to have extraordinary elec. and mech. properties. In particular, the high elastic modulus
     of the graphite sheets means that the nanotubes might be stiffer and stronger than any other
     known material, with beneficial consequences for their application in composite bulk materials
     and as individual elements of nanometer-scale devices and sensors. The mech. properties are
     predicted to be sensitive to details of their structure and to the presence of defects, which
     means that measurements on individual nanotubes are essential to establish these properties.
     Here we show that multi-walled carbon nanotubes can be bent repeatedly through large angles
     using the tip of an atomic force microscope, without undergoing catastrophic failure. We
     observe a range of responses to this high-strain deformation, which together suggest that
     nanotubes are remarkably flexible and resilient.
ΙT
     Atomic force microscopes
     Bending
     Deformation (mechanical)
     Flexibility
     Strain
        (bending and buckling of carbon nanotubes under large strain using atomic
        force microscope tip)
     Nanotubes
TΤ
     Nanotubes
     RL: PEP (Physical, engineering or chemical process); PRP (Properties);
        (carbon fibers; bending and buckling of carbon nanotubes under large
        strain using atomic force microscope tip)
     Carbon fibers, properties
TΨ
     Carbon fibers, properties
     RL: PEP (Physical, engineering or chemical process); PRP (Properties);
     PROC (Process)
        (nanotube; bending and buckling of carbon nanotubes under large strain
        using atomic force microscope tip)
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ANSWER 1 OF 10 HCAPLUS COPYRIGHT ACS on STN
    2002:632853 HCAPLUS
    137:162911
    Entered STN: 22 Aug 2002
     Use of carbon nanotubes as chemical sensors
    by incorporation of fluorescent molecules within the tube
     Yedur, Sanjay K.; Singh, Bhanwar; Choo, Bryan K.
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     Advanced Micro Devices, Inc., USA
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     A system for analyzing a film and detecting a defect associated therewith includes a scanning
     probe microscope having a nanotube tip with a material associated therewith which exhibits a
AB
     characteristic that varies with respect to a film composition at a location corresponding to
     the nanotube tip. The system also includes a detection system for detecting the material
     characteristic and a controller operatively coupled to the detection system and the scanning
     probe microscope. The controller configured to receive information associated with the
     detected characteristic and use the information to determine whether the film contains a
      defect at the location corresponding to the nanotube tip. The invention also includes a
     method of detecting a film composition at a particular location of a film or substrate. The
      method includes associating a material exhibiting a characteristic which varies with respect
      to a film composition with a nanotube tip of a scanning probe microscope and detecting the
      characteristic. The method then includes the step of determining a composition of a portion
      of the film using the detected characteristic.
     carbon nanotube sensor fluorescent mol tube
ST
     Nanotubes
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         (carbon; system and method for detection of defects on or in various
         films in semiconductor processing using carbon
         nanotubes containing fluorescent mols. as chemical
      Defects in solids
 IT
      Films
      Fluorescent substances
      Optical detectors
      Scanning probe microscopes
      Spectrometers
         (system and method for detection of defects on or in various films in
         semiconductor processing using carbon nanotubes
         containing fluorescent mols. as chemical sensors)
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    135:40137
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    Entered STN: 22 Jun 2001
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     Carbon nanotube devices
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     Board of Trustees of the Leland Stanford Junior University, USA
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     This invention provides an assembly of novel nanotube devices that can be employed in a
ΑB
     variety of applications. In particular, the nanotube devices of the present invention provide
     a new class of versatile chemical and biol. sensors. The present invention describes methods
     for growing individual nanotubes in a controlled fashion and for manipulating and integrating
     the nanotubes into functional devices. It further provides methods for modifying the
     nanotubes such that their sensitivity to a wide range of chemical and biol. species can be
     achieved.
     Biosensors
IT
     Dopants
     Semiconductor materials
        (design, fabrication and operation of nanotube based sensors
        and biosensors)
IT
     Enzymes, uses
     Thiols (organic), uses
     RL: ARG (Analytical reagent use); DEV (Device component use); ANST
     (Analytical study); USES (Uses)
        (design, fabrication and operation of nanotube based sensors
        and biosensors)
     Oxides (inorganic), analysis
     RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST
     (Analytical study); USES (Uses)
        (design, fabrication and operation of nanotube based sensors
        and biosensors)
ΤТ
     Hydrocarbons, processes
     RL: PEP (Physical, engineering or chemical process); PROC (Process)
        (design, fabrication and operation of nanotube based sensors
        and biosensors)
IT
        (island; design, fabrication and operation of nanotube based
        sensors and biosensors)
                                  7440-06-4, Platinum, uses
                                                              7440-16-6,
     7440-05-3, Palladium, uses
TΤ
                                             13463-67-7, Titanium oxide (TiO2),
     Rhodium, uses
                    7440-57-5, Gold, uses
     uses
     RL: ARG (Analytical reagent use); DEV (Device component use); ANST
     (Analytical study); USES (Uses)
        (design, fabrication and operation of nanotube based sensors
        and biosensors)
     1309-37-1, Ferric oxide, analysis
                                        1344-28-1, Alumina, analysis
IT
     7429-90-5, Aluminum, analysis 7439-89-6, Iron, analysis 7439-98-7,
                           7440-02-0, Nickel, analysis 7440-18-8, Ruthenium,
     Molybdenum, analysis
               7440-21-3, Silicon, analysis 7440-32-6, Titanium, analysis
                                  7440-47-3, Chromium, analysis
                                                                  7440-48-4,
     7440-44-0, Carbon, analysis
                        7440-66-6, Zinc, analysis 7631-86-9, Silica, analysis
     Cobalt, analysis
     12033-89-5, Silicon nitride, analysis 12670-46-1 14808-60-7, Quartz,
```

L35 ANSWER 1 OF 3 HCAPLUS COPYRIGHT 2005 ACS on STN

```
L65 ANSWER 1 OF 35 HCAPLUS COPYRIGHT ACS on STN
     2002:488087 HCAPLUS
ΑN
     137:40967
DN
     Entered STN: 28 Jun 2002
ED
     Fabrication of conductive/non-conductive nanocomposites by laser
ΤI
     McGill, R. Andrew; Chrisey, Douglas B.; Pique, Alberto
     The United States of America as represented by the Secretary of the Navy,
IN
PA
     USA
                                            APPLICATION NO.
                                                                   DATE
                         KIND
                                DATE
     PATENT NO.
                                            _____
                                _____
                         ____
     _____
                                                                   20011001 <--
                                            US 2001-966772
                                20020627
     US 2002081397
                         A1
PΙ
                                20031209
                          B2
     US 6660343
                                19990127
                                          <--
PRAI US 1999-117467P
                          Р
                                20000127 <--
                          A3
     US 2000-492071
      A composite layer of a sorbent, chemoselective, non-elec.-conducting polymer and nano-
<--
      particles of an elec. conducting material dispersed throughout the polymer is formed on a
AΒ
      substrate by pulsed laser deposition, matrix assisted pulsed laser evaporation or matrix
      assisted pulsed laser evaporation direct writing.
     fabrication conductive nanocomposite evapn; chem sensor
     conductive nanoparticle chemselective sorbent polymer
     Nanotubes
        (carbon; fabrication of conductive/non-conductive nanocomposites by
 ΙT
         laser evaporation)
      Vapor deposition process
         (chemical, laser-assisted, pulsed; fabrication of conductive/non-
 TT
         conductive nanocomposites by laser evaporation)
      Composites
 IT
      Sensors
      Sorbents
         (fabrication of conductive/non-conductive nanocomposites by laser
 IT
      Fullerenes
      RL: TEM (Technical or engineered material use); USES (Uses)
         (fabrication of conductive/non-conductive nanocomposites by laser
         evaporation)
      Metals, uses
 ΙT
      RL: TEM (Technical or engineered material use); USES (Uses)
          (nanoparticles; fabrication of conductive/non-conductive nanocomposites
         by laser evaporation)
      24969-06-0, Polyepichlorohydrin
      RL: POF (Polymer in formulation); TEM (Technical or engineered material
 IT
       use); USES (Uses)
          (fabrication of conductive/non-conductive nanocomposites by laser
          evaporation)
       7782-42-5, Graphite, uses
  IT.
       RL: TEM (Technical or engineered material use); USES (Uses)
          (particles; fabrication of conductive/non-conductive nanocomposites by
          laser evaporation)
```

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L32 ANSWER 8 OF 82 HCAPLUS COPYRIGHT ACS on STN
    2002:466304 HCAPLUS
AN
     137:40958
DN
    Entered STN: 21 Jun 2002
ΕD
    Lieber, Charles M.; Park, Hongkun; Wei, Quinqiao; Cui, Yi; Liang, Wenjie
                                           APPLICATION NO. DATE
                       KIND DATE
     PATENT NO.
                                _____
                                                                   20011211 <--
                                            WO 2001-US48230
                                20020620
    WO 2002048701
                         A2
PΙ
                                20030424
                         A3
     WO 2002048701
                                20030918
                         C2
     WO 2002048701
                          C1
                                20031106
     WO 2002048701
                                            CA 2001-2430888
                                                                    20011211 <--
                                20020620
     CA 2430888
                         AA
                                                                    20011211 <--
                                            AU 2002-29046
                                20020624
                          Α5
     AU 2002029046
                                                                    20011211 <--
                                            US 2001-20004
                          Α1
                                20020829
     US 2002117659
                                                                    20011211 <---
                                            EP 2001-990181
                                20030910
                          A2
     EP 1342075
                                                                    20011211 <--
                                             JP 2002-549958
                                20040527
                          Т2
     JP 2004515782
                                                                    20020520
                                20041118
                                             JP 2003-511316
                          Т2
     JP 2004535066
                                20001211
PRAI US 2000-254745P
                          P
                                20010518
                          Р
     US 2001-292035P
     US 2001-291896P
                          Ρ
                                20010518
                          Ρ
                                20010518
     US 2001-292045P
                                20010518
                          Ρ
     US 2001-292121P
                                20010822
                          Α
      US 2001-935776
                                20011109
      US 2001-348313P
                          Ρ
                                 20011211
                          Α
      US 2001-20004
                                 20011211
      WO 2001-US48230
                           W
                                 20020206
                           Ρ
      US 2002-354642P
       Elec. devices comprised of nanowires are described, along with methods of their manufacture and use. The
      WO 2002-US16133
       nanowires can be nanotubes and nanowires. The surface of the nanowires may be selectively functionalized.
 AΒ
       Nanodetector devices are described.
     Nanotubes
         (carbon; design and operation of nanowire based
         nanosensors for chemical and biol. anal.)
 IT
      Dopants
      Field effect transistors
      Films
      Glass substrates
      Hydrogels
      Linking agents
      Polymer chains
      Quantum dot devices
      Quantum wire devices
        Sensors
       p-n Semiconductor junctions
          (design and operation of nanowire based nanosensors
          for chemical and biol. anal.)
       Lipids, analysis
       Steroids, analysis
       RL: ANT (Analyte); ANST (Analytical study)
          (design and operation of nanowire based nanosensors
          for chemical and biol. anal.)
       Antibodies and Immunoglobulins
       Antigens
       Carbohydrates, uses
       DNA
       Enzymes, uses
       Nucleic acids
       Oxides (inorganic), uses
        Polyamides, uses
       Polyesters, uses
        Polyimides, uses
        Proteins
        Selenides
        Sulfides, uses
        RL: ARG (Analytical reagent use); DEV (Device component use); ANST
        (Analytical study); USES (Uses)
           (design and operation of nanowire based nanosensors
           for chemical and biol. anal.)
                                      124-38-9, Carbon dioxide, analysis
        50-99-7, D-Glucose, analysis
   IT
        7782-44-7, Oxygen, analysis RL: ANT (Analyte); ANST (Analytical study)
           (design and operation of nanowire based nanosensors
```

L32 ANSWER 9 OF 82 HCAPLUS COPYRIGHT ACS on STN

AN 2002:367184 HCAPLUS

DN 136:375354

ED Entered STN: 16 May 2002

TI Method for making surfactant-templated thin films

IN Brinker, C. Jeffrey; Lu, Yunfeng; Fan, Hongyou

PA Sandia Corporation, USA

PRAI US 2000-517873 20000302 <--

Disclosed is an evaporation-induced self-assembly method to prepare a porous, surfactant-templated, thin film by mixing a SiO2 sol, a solvent, a surfactant, and an interstitial compound, evaporating a portion of the solvent to form a liquid, crystalline thin film mesophase material, and then removal of the surfactant template. Coating onto a substrate produces a thin film with the interstitial compound either covalently bonded to the internal surfaces of the ordered or disordered mesostructure framework or phys. entrapped within the ordered or disordered mesostructured framework. Particles can be formed by aerosol processing or spray drying rather than coating onto a substrate. The selection of the interstitial compound provides a means for developing thin films for applications including membranes, sensors, low dielec. constant films, photonic materials and optical hosts.

IT 7440-22-4P, Silver, preparation

RL: SPN (Synthetic preparation); PREP (Preparation)
(nanowire; preparation method of silver nanowire using surfactant-templated thin film)

```
L62 ANSWER 2 OF 14 HCAPLUS COPYRIGHT ACS on STN
    2002:315247 HCAPLUS
AN
    136:321690
DN
    Entered STN: 26 Apr 2002
ΕD
    Sensors comprising a semi-conductive polymer
    Bohanian, Hamed S.; Handy, Erik S.; Meuse, Arthur J.; Jahngen, Edwin Georg
ΤI
     Triton Systems, Inc., USA
PA
                                                                  DATE
                                           APPLICATION NO.
     PATENT NO.
                       KIND
                                DATE
                                            ______
                                _____
     _____
                        ____
                                                                  20011012 <--
                                           WO 2001-US31917
                                20020425
                         A2
     WO 2002033732
PI
                                20020906
                         A3
     WO 2002033732
                         C2
                                20030515
     WO 2002033732
                                20001014 <--
PRAI US 2000-240152P
                         P
     Disclosed is an implementation for detecting at least one analyte in a sample. In one
     embodiment, the implementation includes a sensor array featuring one or a plurality of test
      sensors. Typically, each of the test sensors includes a set of electrodes configured with a
      insulating surface to form a chamber. The implementation further includes a semi-conductive
      film positioned at least in the chamber; and a polyfunctional linker comprising a first end
      attached to a receptor and a second end. Also provided are methods for making and using the
      implementation.
     Antibodies and Immunoglobulins
IT
     RL: ARU (Analytical role, unclassified); ANST (Analytical study)
         (IgG; sensors comprising a semi-conductive polymer)
     Prion proteins
     RL: ARU (Analytical role, unclassified); ANST (Analytical study)
         (PrPSc; sensors comprising a semi-conductive polymer)
 IT
         (carbon; sensors comprising a semi-conductive polymer)
 IT
      RL: ARU (Analytical role, unclassified); ANST (Analytical study)
         (derivs.; sensors comprising a semi-conductive polymer)
      Nucleic acids
      RL: ARU (Analytical role, unclassified); PEP (Physical, engineering or
 IT
      chemical process); PYP (Physical process); ANST (Analytical study); PROC
      (Process)
         (derivs.; sensors comprising a semi-conductive polymer)
 TΤ
         (enzyme-linked immunosorbent assay; sensors comprising a
         semi-conductive polymer)
      Electrodes
 IT
         (interdigitated; sensors comprising a semi-conductive polymer)
      Microarray technology
 TT
         (sensor array; sensors comprising a semi-conductive polymer)
      Atomic force microscopy
 ΤT
        Biosensors
      Cell
       Computer program
       Electric capacitance
       Electric conductivity
       Electric resistance
       Flow
       Food poisoning
       Fungi
       Gel permeation chromatography
       Langmuir-Blodgett films
       Light scattering
       Molecular association
       Molecular orientation
       Mycobacterium tuberculosis
       Nanostructures
       Pumps
       Self-assembly
       Streptococcus pneumoniae
       Thermogravimetric analysis
       UV radiation
```

Virus

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L62 ANSWER 3 OF 14 HCAPLUS COPYRIGHT ACS on STN
     2002:309809 HCAPLUS
AN
     136:289940
DN
     Entered STN: 25 Apr 2002
     Apparatus and method for the analysis of nucleic acids hybridization on
ED
TI
     high density DNA chips
     Poponin, Vladimir
IN
     Virtual Pro, Inc., USA
PA
                                            APPLICATION NO.
                                                                   DATE
                        KIND
                                DATE
     PATENT NO.
                                            _____
                                _____
                        ____
                                                                   19991006
                                            US 1999-413596
                                20020423
                         В1
     US 6376177
ΡI
                                                                   20010607 <--
                                20020905
                                          US 2001-876298
                          A1
     US 2002123050
                          A3 19991006 <--
PRAI US 1999-413596
      The invention generally relates to a new gene probe biosensor employing near field surface
      enhanced Raman scattering (NFSERS) for direct spectroscopic detection of hybridized mols.
AΒ
      (such as hybridized DNA) without the need for labels, and the invention also relates to
      methods for using the biosensor. The invention provides direct spectroscopic detection of
      DNA-DNA, DNA-RNA, and RNA-RNA hybridization.
     Apparatus
IT
       Biosensors
      DNA microarray technology
      IR lasers
      Microarray technology
      Nucleic acid hybridization
      Optical recording
         (apparatus and method for the anal. of nucleic acids hybridization on high
      UV lasers
         d. DNA chips)
      Laser radiation
         (argon ion; apparatus and method for the anal. of nucleic acids
 IT
         hybridization on high d. DNA chips)
         (carbon, colloid covered plates as SRS substrate; apparatus and method for
      Nanotubes
 TΨ
         the anal. of nucleic acids hybridization on high d. DNA chips)
      Peptide nucleic acids
      RL: BUU (Biological use, unclassified); BIOL (Biological study); USES
 IT
          (chips as SERS substrate; apparatus and method for the anal. of nucleic
       (Uses)
          acids hybridization on high d. DNA chips)
  IT
       DNA
       RL: ANT (Analyte); ANST (Analytical study)
          (double-stranded, detection; apparatus and method for the anal. of nucleic
          acids hybridization on high d. DNA chips)
       Optical instruments
          (near field coupling; apparatus and method for the anal. of nucleic acids
  IT
          hybridization on high d. DNA chips)
  IT
       DNA
       RL: ANT (Analyte); ANST (Analytical study)
          (samples; apparatus and method for the anal. of nucleic acids hybridization
          on high d. DNA chips)
           (surface enhanced; apparatus and method for the anal. of nucleic acids
       Raman spectra
  IT
           hybridization on high d. DNA chips)
                                                  7440-22-4, Silver, biological
       7440-06-4, Platinum, biological studies
   IT
                 7440-57-5, Gold, biological studies
       RL: BUU (Biological use, unclassified); BIOL (Biological study); USES
           (colloid covered plates as SRS substrate; apparatus and method for the anal.
        (Uses)
           of nucleic acids hybridization on high d. DNA chips)
```

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L32 ANSWER 10 OF 82 HCAPLUS COPYRIGHT ACS on STN
     2002:158133 HCAPLUS
AN
     136:209112
DN
     Entered STN: 01 Mar 2002
ED
     Doped elongated semiconductors, growing such semiconductors, devices
TI
     including such semiconductors, and fabricating such devices Lieber, Charles M.; Cui, Ying; Duan, Xiangfeng; Huang, Yung-Sheng
IN
     President and Fellows of Harvard College, USA
PA
     PCT Int. Appl., 173 pp.
     CODEN: PIXXD2
DT
     Patent
     English
LA
     ICM H01L021-00
IC
     76-3 (Electric Phenomena)
CC
     Section cross-reference(s): 9, 73, 75, 77
FAN.CNT 2
                                                                    DATE
                                             APPLICATION NO.
                         KIND
                                DATE
     PATENT NO.
                                             ______
                                -----
      _____
                         ____
                                             WO 2001-US26298
                                                                    20010822 <--
                                20020228
                          A2
     WO 2002017362
PΙ
                                20021121
                          C1
     WO 2002017362
                                                                    20010822 <--
                                             CA 2001-2417992
                                 20020228
                          AA
      CA 2417992
                                                                    20010822 <--
                                            AU 2001-86649
                        A5
                                 20020304
      AU 2001086649
                                                                    20010822 <--
                                            US 2001-935776
                          A1
                                 20020919
      US 2002130311
                                                                    20010822 <--
                                           EP 2001-966109
                          A2
                                 20030528
      EP 1314189
                                                                    20010822 <--
                                            JP 2002-521336
                                 20040304
                          Т2
      JP 2004507104
                                                                    20020520
                                           JP 2003-511316
                                 20041118
                           T2
      JP 2004535066
                                 20000822 <--
 PRAI US 2000-226835P
                           Ρ
                                 20001211
                                           <--
                          Ρ
      US 2000-254745P
                                 20010518
                          Р
      US 2001-291896P
                                 20010518
                           Ρ
      US 2001-292035P
                           Ρ
                                 20010518
      US 2001-292045P
                                 20010518
                           Ρ
      US 2001-292121P
                                 20010822
                           Α
      US 2001-935776
                                 20010822
```

20011109

20011211

20020206

W 20020520 WO 2002-US16133 A bulk-doped semiconductor that is at least one of the following: a single crystal, an elongated and bulk-doped semiconductor that, at any point along its longitudinal axis, has a AB largest cross-sectional dimension <500 nm, and a free-standing and bulk-doped semiconductor with at least one portion having a smallest width of <500 nm. Such a semiconductor may comprise an interior core comprising a 1st semiconductor; and an exterior shell comprising a different material than the 1st semiconductor. Such a semiconductor may be elongated and may have, at any point along a longitudinal section of such a semiconductor, a ratio of the length of the section to a longest width which is >4:1, or >10:1, or >100:1, or even >1000:1. At least one portion of such a semiconductor may a smallest width of <200 nm, or <150 nm, or <100 nm, or <80 nm, or <70 nm, or <60 nm, or <40 nm, or <20 nm, or <10 nm, or even <5 nm. Such a semiconductor may be a single crystal and may be free-standing. Such a semiconductor may be either lightly n-doped, heavily n-doped, lightly p-doped or heavily p-doped. Such a semiconductor may be doped during growth. Such a semiconductor may be part of a device, which may include any of a variety of devices and combinations thereof, and a variety of assembling techniques may be used to fabricate devices from such a semiconductor. Two or more of such a semiconductors, including an array of such semiconductors, may be combined to form devices, for example, to form a crossed p-n junction of a device. Such devices at certain sizes may exhibit quantum confinement and other quantum phenomena, and the wavelength of light emitted from one or more of such semiconductors may be controlled by selecting a width of such semiconductors. Such semiconductors and device made therefrom may be used for a variety of applications.

elongated doped semiconductor device fabrication ST

W

Р

Α

P

Memory devices IT

WO 2001-US26298

US 2001-348313P

US 2002-354642P

US 2001-20004

(DRAM (dynamic random access); preparation of elongated doped semiconductor for devices)

Memory devices IT

(SRAM (static random access); preparation of elongated doped semiconductor for devices)

Sensors IT

L32 ANSWER 3 OF 82 HCAPLUS COPYRIGHT ACS on STN

141:198384 2004:681364 DN

Entered STN: 20 Aug 2004 ED

Semiconductor and device nanotechnology and methods for their manufacture ΤI Yadav, Tapesh; Routkevitch, Dmitri; Mardilovich, Peter; Govyadinov, Alex; IN

Hooker, Stephanie; Williams, Stephen S.

	Hooker, Stephanie; PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
		<b>-</b> - A1	20040819	US 2004-783629	20040220 <
ΡI	US 2004161949	B1	20020205	US 1999-274517	19990323 <
	US 6344271	A1	20020203	US 2001-790036	20010220 <
	US 2002014182	A1	20020207	US 2001-4258	20011024 <
	US 2002118027	B2	20040316		
	US 6705152	A1	20020502	US 2001-996471	20011127 <
	US 2002051883	B2	20040330		
	US 6713176 US 2002079476	A1	20020627	US 2001-996500	20011127 <
		B2	20030819		
	US 6607821 US 2002160190	A1	20021031	US 2002-147835	20020517 <
	US 6602543	B2	20030805		
	US 2002170593	A1	20021121	US 2002-150201	20020517 <
	US 6607779	B2	20030819		
	US 2002176987	A1	20021128	US 2002-150722	20020517 <
	US 6602595	B2	20030805		_
	US 2003012952	A1	20030116	US 2002-147599	20020517 <
	US 6569518	В2	20030527		
	US 2003012953	A1	20030116	US 2002-147636	20020517 <
	US 6569490	В2	20030527		
	US 6554609	В2	20030429	US 2002-147837	20020517 <
	US 2002160191	A1	20021031		00000517
	US 6562495	B2	20030513	US 2002-150140	20020517 <
	US 2002172826	A1	20021121		20020517 <
	US 6572672	B2	20030603	US 2002-147829	20020517 <==
	US 2002164482	A1	20021107		20020517 <
	US 6576355	. B2	20030610	US 2002-147954	20020317 <
	US 2002168522	A1	20021114	•	
PR#	I US 1998-107318P	P	19981106	<	
	US 1998-111442P	P	19981208	<	
	US 1999-274517	A3	19990323		
	US 2000-242905P	P	20001024		
•	US 2001-4258	A1	20011024		
	US 2001-996471	A2	20011127	,	
	. US 1998-83893	A3	19980522	<	ates is described.
AB	Device nanotechn	ol. base	ed on Si war	ers and other substra	low integration of

Methods for preparing such devices are discussed. The teachings allow integration of current semiconductor device, sensor device and other device fabrication methods with nanotechnol. Integration of nanotubes and nanowires to wafers is discussed. Sensors , electronics, biomedical and other devices are presented.

Semiconductor gas sensors Semiconductor nanostructures Semiconductor sensors

## L32 ANSWER 4 OF 82 HCAPLUS COPYRIGHT ACS on STN

A2

2004:80239 HCAPLUS AN

US 1999-236949

US 2002-80608

140:144705 DN

Entered STN: 01 Feb 2004

Nanostructures containing antibody or Ig fragment, and non-antibody joining element and functional element for nanoscale devices

Makowski, Lee; Williams, Mark K.; Goldberg, Edward B. IN DATE APPLICATION NO. KIND DATE PATENT NO. \_\_\_\_\_\_ \_\_\_\_ US 2003-371067 20030221 <--20040129 A1 US 2004018587 ΡI US 1994-322760 19941013 19990302 Α US 5877279 US 1995-542003 19951012 <--19990126 Α US 5864013 . 19990125 <--US 1999-236949 20020820 US 6437112 B1 US 2002-80608 20020221 20031023 US 2003198956 Α1 20020429 <--US 2002-136225 20031225 A1 US 2003236390 A2 19941013 <--PRAI US 1994-322760 19951012 <--A3 US 1995-542003 <--19990125 A3

20020221

A2 20020429 US 2002-136225 Nanostructures are made that include at least one species of assembly unit that is an antibody assembly unit in which at least one joining element, structural element or functional element AB is an antibody or antibody fragment. Antibody assembly units may have more than one antibody element. In addition, the antibody assembly units may contain non-antibody structural, functional or joining elements. The nanostructure is suitably prepared using a staged assembly method. In this method, a nanostructure intermediate having at least one unbound joining element is contacted with an assembly unit having a plurality of different joining elements. None of the joining elements of the assembly unit can interact with itself or with another joining element of the same assembly unit. However, one of the joining elements of the assembly unit can interact with the unbound joining element of the nanostructure intermediate, so that the assembly unit is non-covalently bound to the nanostructure intermediate to form a new nanostructure intermediate for use in subsequent cycles. Unbound assembly units are removed and the cycles is repeated for a sufficient number of cycles to form a nanostructure. The assembly units in at least one cycle are antibody assembly units.

#### Biosensors IT

Nanotubes

Nanowires

Quantum dot devices Semiconductor devices

Semiconductor nanostructures

#### L62 ANSWER 1 OF 14 HCAPLUS COPYRIGHT ACS on STN 2003:485026 HCAPLUS DN 139:59559 Entered STN: 25 Jun 2003 Amperometric biomimetic enzyme sensors based on modified cyclodextrin as electrocatalysts Chen, Ellen T. ΤN United States Dept. of Health and Human Services, USA PΑ PATENT NO. KIND DATE APPLICATION NO. DATE \_\_\_\_\_\_ ----\_\_\_\_\_ \_\_\_\_\_ 19991130 <--20030624 US 1999-451141 US 6582583 В1 PΙ 19981130 <--P PRAI US 1998-110470P The present invention provides a novel biosensor for the detection of chems. of interest. novel biosensor of the present invention comprises an electrode having a catalytically active cyclodextrin attached thereto. The present invention will be useful for the detection of materials in a wide variety of samples. In particular, the present invention will permit the detection of nitrophenyl esters. biosensor enzyme cyclodextrin deriv electrocatalyst phenol ST Biosensors (amperometric biomimetic enzyme sensors based on modified cyclodextrin IT as electrocatalysts) Enzymes, analysis ΙT RL: AMX (Analytical matrix); ANST (Analytical study) (amperometric biomimetic enzyme sensors based on modified cyclodextrin as electrocatalysts) Phenols, analysis ΙT RL: ANT (Analyte); ANST (Analytical study) (amperometric biomimetic enzyme sensors based on modified cyclodextrin as electrocatalysts for) Polyoxyalkylenes, uses IT Polyoxyalkylenes, uses RL: NUU (Other use, unclassified); USES (Uses) (biosensor comprising electrode with catalytically active cyclodextrin containing) Nanotubes TΤ (biosensor comprising electrode with catalytically active

cyclodextrin forming)

20010518 <--

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L32 ANSWER 5 OF 82 HCAPLUS COPYRIGHT ACS on STN
    2003:97136 HCAPLUS
AN
    138:155821
DN
    Entered STN: 07 Feb 2003
ED
    Metal oxide having nanotube- or nanowire shape and its
TΙ
     manufacture for solar-cell electrode and catalyst
     Adachi, Motonari; Yoshikawa, Akira; Harada, Makoto; Murata, Yusuke
IN
     Japan Science and Technology Corporation, Japan
PΑ
                                          APPLICATION NO.
                                                                DATE
                              DATE
                        KIND
     PATENT NO.
                                          _____
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\_\_\_\_\_

\_\_\_\_\_ JP 2001-150030 20030207 JP 2003034531 A2 20000519 <--PRAI JP 2000-149038 Α Α 20010514

\_\_\_\_

CLASS

The title metal oxide nanotube or nanowire is manufactured by mixing a metal compound or its solution containing an organic solvent, a surfactant, and water and then solidifying. Also AΒ claimed process comprises mixing a solution containing Ti alkoxide and an organic solvent with an aqueous solution containing  $\leq 0.5$  mol/L surfactant showing pH 2-5 and then solidifying to give a TiO2 nanotube. Alternatively, a TiO2 nanowire is manufactured by mixing a Ti alkoxide solution containing an organic solvent and a surfactant with water at mol ratio  $H2O/Ti \le 2$  and then solidifying. The resulting TiO2 nanotube provides high photocatalytic activity. The resulting metal oxide nanotube or nanowire has high dye sensitizing ability and electron transporting ability. Also claimed is an electrode using the metal oxide for a dye-sensitized solar cell. The metal oxide is also suitable for a catalyst or a catalyst support.

Electrodes IT Hydrolysis

Nanotubes

Nanowires

JP 2001-143930

Photolysis catalysts

Solar cells

(metal oxide having nanotube- or nanowire shape manufactured by hydrolysis for solar-cell electrode and catalyst)

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L32 ANSWER 6 OF 82 HCAPLUS COPYRIGHT ACS on STN
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2002:964603 HCAPLUS AN

138:48054 DN

Entered STN: 20 Dec 2002

Fabrication of electronic and optoelectronic devices from nanostructured ΕD ΤI

Kalkan, Kaan A.; Fonash, Stephen J. IN

The Penn State Research Foundation, USA PA DATE APPLICATION NO. DATE KIND PATENT NO. \_\_\_\_\_ \_\_\_\_\_ \_\_\_\_\_ \_\_\_\_ WO 2002-US17909 20020606 20021219 A2 WO 2002101352 PΙ 20030605 WO 2002101352 A3

20030814 C1 WO 2002101352 20020513 <--US 2002-144456 A1 20021212 US 2002187312 20010608 P PRAI US 2001-296857P 20020322 Α

US 2002-104759 20020513 US 2002-144456 Α 20000530 <--US 2000-580105 A2 20010514 P US 2001-290876P

The invention relates to the fabrication of electronic and optoelectronic devices from composites consisting of an interpenetrating network configuration of nanostructured thin AB films with high surface-to-volume ratios and an organic/inorg. material. The nanostructured film material is deposited onto an electrode substrate such that the nanoscale basic elements are embedded in a void matrix while having elec. connectivity with the electrode substrate. For example, the film material may consist of an array of nanoprotrusions elec. connected to the electrode substrate and separated by a void matrix. The interpenetrating network is formed by introducing an appropriate organic/inorg. material into the void volume of the film material. Further electrodes are defined onto the film or intra-void material to fabricate a device. Potential devices include charge separation devices, charge injection devices, charge storage devices, field effect devices, ohmic contacts, and chemical sensors.

Capacitors IT

Optical detectors

Photoelectric devices

Photolithography

#### Sensors

(fabrication of electronic and optoelectronic devices from nanostructured thin films)

Ceramics IT

Nanoparticles

Nanotubes

## Nanowires

(nanostructured material; fabrication of electronic and optoelectronic devices from nanostructured thin films)

7440-74-6, Indium, 7440-55-3, Gallium, uses 7440-56-4, Germanium, uses 13494-80-9, 7782-49-2, Selenium, uses 7631-86-9, Silica, uses

Tellurium, uses RL: DEV (Device component use); USES (Uses)

(nanostructured material; fabrication of electronic and optoelectronic devices from nanostructured thin films)

```
L58 ANSWER 2 OF 10 HCAPLUS COPYRIGHT ACS on STN
     2002:107196 HCAPLUS
AN
     136:147446
DN
     Entered STN: 10 Feb 2002
ED
     Methods and kits for solid phase nanoextraction and desorption
TI
     Singh, Rajendra; Cromer, Remy; Natan, Michael J.
IN
     Surromed, Inc., USA
PA
                                            APPLICATION NO.
                                                                   DATE
                         KIND
                                DATE
     PATENT NO.
                                            _____
                                _____
                         ____
     _____
                                                                   20010801 <--
                                20020207
                                            WO 2001-US24191
     WO 2002009836
                          A2
PI
                                                                   20001013 <--
                                            US 2000-688063
                                20041005
                          В1
     US 6800490
                                                                   20010801 <--
                                            AU 2001-78133
                                20020213
                          Α5
     AU 2001078133
                                                                   20010801 <--
                                            US 2001-920440
                                20020321
                          A1
     US 2002034827
                                         <--
                                20000801
                          Ρ
PRAI US 2000-222214P
                                          <--
                                20001005
     US 2000-238181P
                          Р
                                          <--
                                20001012
     US 2000-239662P
                          ₽
                                20001013
     US 2000-688063
                          Α
                          Ρ
                                20010201
     US 2001-265790P
                                20010202
                         P
      US 2001-266146P
                                20000314
                                          <--
                         P
      US 2000-189151P
                                          <--
                                20000317
                          Ρ
      US 2000-190247P
                                          <--
                                20000405
                          P
      US 2000-194616P
                                20010801
      Methods for and material for separation and anal. of complex materials, including biol.
                          W
      WO 2001-US24191
      materials, are discussed. Boronic acid-derivatized magnetic particles, streptavidinated
 AB
      particles, and carboxy-modified latex particles were used to sep. glucose, biotin-fluorescein
      conjugate and dioxadodecanediamine.
                                7440-57-5, Gold, uses
      7440-22-4, Silver, uses
 IT
      RL: DEV (Device component use); USES (Uses)
         (mercapto aminodextran coating of nanorods containing; methods
         and kits for solid-phase nanoextn. and desorption)
                                    2321-07-5D, Fluorescein, conjugates with
      50-99-7, D-Glucose, analysis
 TT
      biotin
               7300-34-7
      RL: ANT (Analyte); ANST (Analytical study)
          (methods and kits for solid-phase nanoextn. and desorption)
      13780-71-7D, Boronic acid, conjugates with magnetic particles
 IT
      RL: ARG (Analytical reagent use); ANST (Analytical study); USES (Uses)
          (methods and kits for solid-phase nanoextn. and desorption)
       50-89-5DP, Deoxythymidine, biotinylated oligomers, complexes with
                                   58-85-5DP, Biotin, conjugates with oligomer,
  IT
       streptavidin nanoparticles
       complexes with streptavidin nanoparticles
       RL: ARG (Analytical reagent use); SPN (Synthetic preparation); ANST
       (Analytical study); PREP (Preparation); USES (Uses)
          (methods and kits for solid-phase nanoextn. and desorption)
                                                2885-00-9, 1-Octadecanethiol
       108-30-5, Succinic anhydride, reactions
  IT
                                 37293-51-9, Aminodextran 49594-30-1,
       9013-20-1, Streptavidin
                                          68181-17-9, SPDP
                                                             71310-21-9
       3-Mercapto-1-propanesulfonic acid
                                                 394657-66-0
                                    113630-26-5
       11-Mercaptoundecanoic acid
       RL: RCT (Reactant); RACT (Reactant or reagent)
          (methods and kits for solid-phase nanoextn. and desorption)
       9013-20-1DP, Streptavidin, conjugates with segmented nanoparticles
       RL: RCT (Reactant); SPN (Synthetic preparation); PREP (Preparation); RACT
       (Reactant or reagent)
           (methods and kits for solid-phase nanoextn. and desorption)
       9004-54-0D, Dextran, carboxy-terminated
       RL: ARU (Analytical role, unclassified); DEV (Device component use); RCT
  TΤ
        (Reactant); ANST (Analytical study); RACT (Reactant or reagent); USES
           (segmented nanoparticles coated with; methods and kits for solid-phase
          nanoextn. and desorption)
```

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L58 ANSWER 3 OF 10 HCAPLUS COPYRIGHT ACS on STN
    2002:72382 HCAPLUS
AN
    136:115068
DN
    Entered STN: 25 Jan 2002
ΕD
    Multimeric biopolymers as structural elements, sensors and actuators in
    Madou, Marc; Bachas, Leonidas G.; Daunert, Sylvia
IN
    The Ohio State University Research Foundation, USA; University of Kentucky
PA
    Research Foundation
    PCT Int. Appl., 26 pp.
SO
    CODEN: PIXXD2
DT
    Patent
    English
LA
     ICM G01N
     9-1 (Biochemical Methods)
     Section cross-reference(s): 47
FAN.CNT 1
                                                              DATE
                                       APPLICATION NO.
                              DATE
                       KIND
     PATENT NO.
                                        -----
                                                              20010713 <--
                              20020124 WO 2001-US22224
                     - A2
     WO 2002006789
PΙ
                                                              20010713 <--
                                        CA 2001-2419156
                              20020124
                       AA
     CA 2419156
                              20020130 AU 2001-80552
                                                              20010713 <--
                       A5
     AU 2001080552
                                                              20010713 <--
                                         US 2001-905041
                       A1
                              20020606
     US 2002068295
                                                              20010713 <--
                                        EP 2001-958947
                              20030416
                       A2
     EP 1301585
        R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
            IE, SI, LT, LV, FI, RO, MK, CY, AL, TR
                     P
                              20000713
 PRAI US 2000-218036P
                        W
                              20010713
     WO 2001-US22224
 CLASS
                CLASS PATENT FAMILY CLASSIFICATION CODES
  PATENT NO.
                      ______
 WO 2002006789
                       G01N
      Biomol. complexes hereinafter referred to as multimeric biopolymers are described which can be
               ICM
```

used as the foundation of chemical control systems capable of both sensing the presence of a target analyte and actuating some mech. response. The biomol. complexes are multimeric biopolymers comprising at least two monomeric units. The monomeric units are selected from the group consisting of full-length proteins, polypeptides, nucleic acid mols., and peptide nucleic acids. At least one of the monomeric units binds to the target analyte. In one highly preferred embodiment the multimeric biopolymers of the present invention undergo a detectable conformational change in response to exposure to an analyte. The present invention also provides micromachined and nanomachined devices and systems which employ the multimeric biopolymers to sense the presence of a target analyte, to actuate a response to the presence of a target analyte, or the perform both functions.

Semiconductor devices TT

(microscale; multimeric biopolymers as structural elements and sensors and actuators in microsystems)

IT Films

(multimeric biopolymer covalently bound to; multimeric biopolymers as structural elements and sensors and actuators in microsystems)

TТ Actuators

Anions

#### Biosensors

Cations

Conducting polymers Drug delivery systems Electric potential Electrochemical analysis Fluorometry Microactuators Microarray technology Micromachines Nanomachines

### Nanotubes

Porous materials Sensors Spectroscopy Нα

```
ANSWER 1 OF 5 HCAPLUS COPYRIGHT ACS on STN
L64
     2001:828915 HCAPLUS
AN
DN
     135:366147
     Entered STN: 15 Nov 2001
     Electrochemical sensors made from conductive polymer composite
ED
TΙ
     materials and methods of making same
     Foulger, Stephen H.
IN
     Pirelli Cables and Systems Llc, USA
PΑ
     U.S., 23 pp.
SO
                                            APPLICATION NO.
                         KIND
                                DATE
     PATENT NO.
                                            ______
                                                                   _____
                                _____
                         ____
     -----
                                                                   19990316
                                           US 1999-268884
                                20011113
     US 6315956
                         В1
                                                                  20000315 <--
                                           CA 2000-2300722
                         AA
                                20000916
     CA 2300722
                                19990316 <--
      An electrochem. sensor which is tailored for sensitivity to specific chemical analytes by
PRAI US 1999-268884
      selecting proper constituents. The electrochem. sensor is comprised of an immiscible polymer
      blend of at least two polymers in which a conductive filler is dispersed in one of the
      polymers of the blend through a multiple percolation approach to compounding. When in the
      presence of a chemical analyte which is in either a liquid or vapor phase, one phase of the
      dual immiscible polymer blend swells, effecting a decrease in the conductivity, or increase in
      resistivity, of the polymer blend. The electrochem. sensor is reversible in that when the
      chemical analyte evaps. or is removed, the polymer blend returns to its original conductivity
      With the multiple percolation approach it is possible to make a single composite material
      identifiably sensitive to various chemical analytes by incorporating several major phase
      materials into the immiscible polymer blend, each having an affinity for swelling for a
      different analyte. Further, the multiple percolation approach allows sensors to be made at
       extremely low cost.
      Antiblocking agents
 IT
      Antioxidants
      Conducting polymers
      Coupling agents
      Crosslinking agents
      Crystal whiskers
      Dyes
      Electronic device fabrication
       Fillers
       Fireproofing agents
       Lubricants
       78-93-3, Methyl ethyl ketone, analysis 109-99-9, Tetrahydrofuran,
 ·IT
       RL: ANT (Analyte); ANST (Analytical study)
          (fabrication of electrochem. sensors based on conductive polymer
          composites)
       7782-42-5, Graphite, uses 9002-88-4, Polyethylene
       RL: ARG (Analytical reagent use); DEV (Device component use); ANST
  IT
       (Analytical study); USES (Uses)
          (fabrication of electrochem. sensors based on conductive polymer
```

composites)

```
L62 ANSWER 4 OF 14 HCAPLUS COPYRIGHT ACS on STN
    2001:693653 HCAPLUS
AN
     135:254050
DN
     Entered STN: 21 Sep 2001
ED
     Cross-reactive biosensor system for liquid analytes
     Walt, David R.; Schauer, Caroline L.; Steemers, Frank J.
IN
     Trustees of Tufts College, USA
                                                                   DATE
                                            APPLICATION NO.
                                DATE
     PATENT NO.
                        KIND
                                            ______
                         ____
                                                                   20010314 <--
                                            WO 2001-US8126
                                20010920
                         A2
     WO 2001069245
PΙ
                                20020502
                         A3
     WO 2001069245
                                20000314 <--
PRAI US 2000-189200P
                         P
      The present invention provides a novel cross-reactive sensor system utilizing cross-reactive
      recognition elements. In the inventive system, each of said one or more cross-reactive
      recognition elements is capable of interacting with more than one species of liquid analyte of
      interest, whereby each of said one or more cross-reactive recognition elements reacts in a
      different manner with each of said one or more species of liquid analytes of interest to
      produce a detectable agent of each analyte of interest, whereby said detectable agent is
      analyzed and the information is processed for data acquisition and interpretation. In certain
      preferred embodiments, the detectable agent and/or change is detected directly, while in
      certain other preferred embodiments, the detectable agent and/or change is detected with the
      help of a transducing agent capable of relaying information about each detectable agent
      generated for each of said species of liquid analyte of interest, whereby said information is
      processed for data acquisition and interpretation. The present invention also provides method
      for the anal. of analytes comprising contacting one or more analytes with the inventive system
      described above.
 IT
      Biosensors
         (acoustic plate mode; cross-reactive biosensor system for
         liquid analytes)
      Physical properties
 IT
         (adiabatic change; cross-reactive biosensor system for liquid
         analytes)
      Receptors
 TT
      RL: ARG (Analytical reagent use); ANST (Analytical study); USES (Uses)
         (aza-clefts; cross-reactive biosensor system for liquid
         analytes)
      Metacyclophanes
      RL: ARG (Analytical reagent use); ANST (Analytical study); USES (Uses)
          (calixarenes; cross-reactive biosensor system for liquid
         analytes)
      Inclusion compounds
 IT
      RL: ARG (Analytical reagent use); ANST (Analytical study); USES (Uses)
          (carceplexes; cross-reactive biosensor system for liquid
          analytes)
 IT
       Sensors
          (chemo; cross-reactive biosensor system for liquid
          analytes)
       Inclusion compounds
       RL: ARG (Analytical reagent use); ANST (Analytical study); USES (Uses)
  IT
          (coraplexes; cross-reactive biosensor system for liquid
          analytes)
       Acoustic transducers
  IT
       Amperometry
         Biosensors
       Micelles
       Microtiter plates
       Molecular recognition
         Nanotubes
       Potentiometry
       Process control
       SERS (Raman scattering)
       Spectrometers
       Spheres
       Stripping potentiometry
        Surface acoustic wave
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Transducers Virus

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L65 ANSWER 2 OF 35 HCAPLUS COPYRIGHT ACS on STN
     2001:676892 HCAPLUS
ΑN
     135:237555
DN
     Entered STN: 14 Sep 2001
ED
     Integrated nucleic acid hybridization devices for improved kinetics,
     sensitivity and discrimination power
    Hogan, Michael; Powdrill, Thomas; Iverson, Bonnie; Belosludtsev, Yuri Y.;
IN
     Belosludtsev, Inna Y.
     Genometrix Genomix, Inc., USA
PA
                                                                   DATE
                                           APPLICATION NO.
                        KIND
                               DATE
     PATENT NO.
                                           ______
                                _____
     ______
                                          WO 2000-US23438
                                                                   20000824 <--
                                20010913
     WO 2001066687
                         A1
                                20000309 <--
PRAI US 2000-522240
                         A1
                                20000810 <--
     US 2000-636268
                          A1
     The invention provides devices and methods for enhanced and selective association or binding
AB
     between biol. materials, such as nucleic acids, e.g., DNA or RNA, or polypeptides, and an
      immobilized oligonucleotide probe. In one embodiment, the invention provides an association
      device comprising a plurality of nucleic acid probes or polypeptide probes or a combination
      thereof linked to a solid substrate. The solid substrate comprises a substrate surface
      comprising an external substrate surface and a plurality of internal pores, wherein the pores
      comprise a proximal end opening to the external surface to allow passage of fluid into a pore,
      and wherein the pore surfaces comprise an association surface. The association surface
      comprises a charged surface comprising net pos. (cationic) charge d. under conditions
      comprising a pH lower than the pI of the association surface. Methods for making these
      hybridization/association devices are also provided. Covalent and noncovalent probe
      immobilization methodologies are employed for surface hybridization modeling studies.
      Incorporating low ionic strength, low pH buffers (together with a net cationic charge d. on
      the device surface) as hybridization conditions provides significant increases in the
      kinetics, sensitivity, and discrimination power of nucleic acid-based and polypeptide-based
      biosensors and related hybridization techniques. For example, the devices and methods of the
      invention can be used in nucleic acid-based diagnostic tests. The devices and methods of the
      invention can be used, e.g., for detecting the association of a nucleic acid in a sample to a
      nucleic acid probe or purifying a nucleic acid from a sample.
      nucleic acid hybridization device; polypeptide polynucleotide
      immobilization hybridization device; cationic charge density nucleic acid
      hybridization device
      Spheres
 ΙT
         (beads, porous; integrated nucleic acid hybridization devices for
         improved kinetics, sensitivity and discrimination power)
      Nanotubes
 IT
      RL: DEV (Device component use); USES (Uses)
         (carbon, monodispersed; integrated nucleic acid hybridization devices
         for improved kinetics, sensitivity and discrimination power)
      Fibers
 IT
      RL: DEV (Device component use); USES (Uses)
         (hollow, porous; integrated nucleic acid hybridization devices for
         improved kinetics, sensitivity and discrimination power)
      DNA microarray technology
 IT
      Immobilization, biochemical
      Nucleic acid hybridization
         (integrated nucleic acid hybridization devices for improved kinetics,
         sensitivity and discrimination power)
      DNA
 TT
```

RL: ANT (Analyte); PEP (Physical, engineering or chemical process); ANST

(integrated nucleic acid hybridization devices for improved kinetics,

(integrated nucleic acid hybridization devices for improved kinetics,

RL: BUU (Biological use, unclassified); BIOL (Biological study); USES

(Analytical study); PROC (Process)

Probes (nucleic acid)

IT

(Uses)

sensitivity and discrimination power)

sensitivity and discrimination power)

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ANSWER 4 OF 10 HCAPLUS COPYRIGHT ACS on STN
1.58
     2001:636312 HCAPLUS
ΑN
     135:196798
DN
     Entered STN: 31 Aug 2001
ED
     Method for obtaining macroscopic fibers and strips from colloidal
TТ
     particles and in particular carbon nanotubes
     Poulin, Philippe; Vigolo, Brigitte; Penicaud, Alain; Coulon, Claude
IN
     Centre National de la Recherche Scientifique (C.N.R.S.), Fr.
PA
                                             APPLICATION NO.
                                DATE
                         KIND
     PATENT NO.
                         ____
                                                                    20010223 <--
                                             WO 2001-FR544
                                 20010830
                          A1
     WO 2001063028
ΡI
                                                                    20000223
                                             FR 2000-2272
                                 20010824
                          A1
     FR 2805179
                                 20020927
                          В1
     FR 2805179
                                                                    20010223 <--
                                             CA 2001-2397564
                                 20010830
                          AΑ
     CA 2397564
                                                                     20010223 <--
                                 20010903
                                             AU 2001-37491
                          Α5
     AU 2001037491
                                                                     20010223 <--
                                             EP 2001-909894
                                 20030102
                          A1
     EP 1268894
                                                                     20010223 <--
                                             BR 2001-8656
                          Α
                                 20030429
     BR 2001008656
                                                                     20010223 <--
                                             JP 2001-561830
                                 20030812
                          T2
      JP 2003524084
                                                                     20020822 <--
                                             NO 2002-3996
                                 20021008
                          Α
     NO 2002003996
                                                                     20021209 <--
                                             US 2002-204794
                                 20030605
                           Α1
      US 2003102585
                                 20000223
                                           <--
 PRAI FR 2000-2272
                           Α
                                 20010223
                           W
      WO 2001-FR544
```

The invention concerns a method for obtaining fibers and strips with improved elec. and mech. <-properties from colloidal particles such as C nanotubes, characterized in that it consists in: AB (1) dispersing said particles in a solvent optionally using a surfactant; (2) injecting the resulting dispersion solution through ≥1 orifice emerging into a flow of an external solution, preferably, having a higher viscosity than said dispersion, the viscosity levels being measured in the same temperature and pressure conditions, so as to cause said particles to agglomerate into fibers or strips by destabilizing the particle dispersions and optionally aligning said particles.

fiber manuf carbon nanotube surfactant; extrusion colloidal particle dispersion fiber manuf

Sensors IT

ST

(chemical; obtaining macroscopic fibers and strips by extrusion of dispersions of colloidal particles such as carbon nanotubes for chemical detectors)

Semiconductor materials IT

(obtaining macroscopic fibers and strips by extrusion of dispersions of colloidal particles such as carbon nanotubes for semiconductive materials)

9004-34-6, Cellulose, uses 9002-89-5, Polyvinyl alcohol TT

RL: NUU (Other use, unclassified); USES (Uses)

(in obtaining macroscopic fibers and strips by extrusion of dispersions of colloidal particles such as carbon nanotubes)

THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT RE

- (1) Akzo Nobel Uk Limited; WO 9936604 A 1999 HCAPLUS
- (2) Andrews, R; APPLIED PHYSICS LETTERS 1999, V75(9) HCAPLUS
- (3) Sfec; FR 2088130 A 1972 HCAPLUS
- (4) The Carborundum Company; GB 1174959 A 1969 HCAPLUS

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L58 ANSWER 5 OF 10 HCAPLUS COPYRIGHT ACS on STN
     2001:453349 HCAPLUS
DN
     135:40137
     Entered STN: 22 Jun 2001
ED
     Carbon nanotube devices
TΙ
     Dai, Hongjie; Kong, Jing
IN
     Board of Trustees of the Leland Stanford Junior University, USA
PA
     PCT Int. Appl., 33 pp.
so
     CODEN: PIXXD2
DT
     Patent
LA
     English
     ICM G01N027-12
IC
     79-2 (Inorganic Analytical Chemistry)
CC
     Section cross-reference(s): 9, 80
FAN.CNT 2
                                                                    DATE
                                             APPLICATION NO.
                         KIND
                                 DATE
     PATENT NO.
                                             _____
                                 _____
                         ____
     _____
                                             WO 2000-US42186
                                                                    20001115 <--
                          A1
                                 20010621
     WO 2001044796
                                 20030130
     WO 2001044796
                          C2
                                                                    20000519 <--
                                            us 2000-574393
                          В1
                                 20030304
EP 1247089 A1
JP 2003517604 T2
US 2003068432 A1
PRAI US 1999-171200P P
US 1998-133948 A3
US 2000-574393
     US 6528020
                                                                    20001115 <--
                                           EP 2000-992511
                                20021009
                                                                    20001115 <--
                                            JP 2001-545835
                               20030527
                                                                    20021118 <--
                                           US 2002-299610
                               20030410
                                19991215 <--
                                19980814 <--
                                 20000519 <--
                         W
                                 20001115 <--
      WO 2000-US42186
      This invention provides an assembly of novel nanotube devices that can be employed in a
      variety of applications. In particular, the nanotube devices of the present invention provide
AB
      a new class of versatile chemical and biol. sensors. The present invention describes methods
      for growing individual nanotubes in a controlled fashion and for manipulating and integrating
      the nanotubes into functional devices. It further provides methods for modifying the
      nanotubes such that their sensitivity to a wide range of chemical and biol. species can be
      achieved.
      Nanotubes
 TΤ
      RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST
      (Analytical study); USES (Uses)
         (carbon; design, fabrication and operation of nanotube based
         sensors and biosensors)
 IT
      Biosensors
      Dopants
      Electric conductors
      Electric contacts
      Films
      Nanoparticles
        Nanotubes
         Semiconductor device fabrication
         Semiconductor materials
       Sensors
          (design, fabrication and operation of nanotube based sensors
          and biosensors)
       Enzymes, uses
  IT
       Thiols (organic), uses
       RL: ARG (Analytical reagent use); DEV (Device component use); ANST
       (Analytical study); USES (Uses)
          (design, fabrication and operation of nanotube based sensors
          and biosensors)
       Oxides (inorganic), analysis
  ΙT
       RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST
       (Analytical study); USES (Uses)
          (design, fabrication and operation of nanotube based sensors
          and biosensors)
       Hydrocarbons, processes
  ΤT
       RL: PEP (Physical, engineering or chemical process); PROC (Process)
          (design, fabrication and operation of nanotube based sensors and biosensors)
```

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L32 ANSWER 12 OF 82 HCAPLUS COPYRIGHT ACS on STN
     2001:281627 HCAPLUS
AN
     135:39344
DN
     Entered STN: 20 Apr 2001
F.D
     Coulomb blockade in single tunnel junction connected to nanowire
TI
     and carbon nanotube
     Haruyama, J.; Takesue, I.; Sato, Y.; Hijioka, K.
ΑU
     Dept. Electrical Engineering and Electronics, Aoyama Gkuin University,
CS
     Tokyo, 157-8572, Japan
     NATO Science Series, Series C: Mathematical and Physical Sciences (2000),
SO
     559(Quantum Mesoscopic Phenomena and Mesoscopic Devices in
     Microelectronics), 145-160
     CODEN: NSCMFG; ISSN: 1389-2185
     Kluwer Academic Publishers
PΒ
     Journal
DT
     English
LA
     76-3 (Electric Phenomena)
CC
     Section cross-reference(s): 77
      It is well known that Coulomb blockade (CB) in single tunnel junction (STJ) system strongly
      depends on its external electromagnetic environment (EME), so called phase correlation theory.
AB
      Tunneling electron can transfer its charging energy Ec to the EME and charges on junction
      surface can be isolated from external phase fluctuation, only when the impedance of EME is
      larger than resistance quantum (RQ = h/e2 \approx 25.8 k\Omega)\,. It is quite interesting condition
      because of pure requirement from quantum mechanics. Here, some mesoscopic phenomena can also
      yield high impedance. In this work, we connect STJ directly to Ni nanowire and multi-walled C
      nanotube (MWNT). It is, for the 1st time, confirmed that mutual Coulomb interaction (MCI) in
      the Ni wire and weak localization (WL) in the MWNT can play the role of high impedance EME of
      CB. The CB is very sensitive to phase fluctuation of EME.
      tunnel junction aluminum alumina nickel nanowire Coulomb
      blockade; carbon nanotube aluminum alumina tunnel junction Coulomb
      blockade
      Coulomb blockade
 IT
        Nanowires (metallic)
      Tunnel junctions
         (Coulomb blockade in Al/Al203 single tunnel junction connected to Ni
         nanowire and multiwalled C nanotube)
      Electric impedance
 TT
         (Coulomb blockade in Al/Al203 single tunnel junction connected to Ni
         nanowire and multiwalled C nanotube yielding high)
 IT
      Nanotubes
      RL: PEP (Physical, engineering or chemical process); PRP (Properties);
      PROC (Process)
          (carbon, multiwalled; Coulomb blockade in Al/Al203 single tunnel
         junction connected to Ni nanowire and multiwalled C nanotube)
      Magnetic field effects
 IΤ
          (magnetic field dependence of impedance of Al/Al2O3 single tunnel
          junction connected to Ni nanowire and multiwalled C nanotube)
      1344-28-1, Alumina, properties 7429-90-5, Aluminum, properties
      7440-02-0, Nickel, properties 7440-44-0, Carbon, properties
       RL: PEP (Physical, engineering or chemical process); PRP (Properties);
       PROC (Process)
          (Coulomb blockade in Al/Al2O3 single tunnel junction connected to Ni
          nanowire and multiwalled C nanotube)
               THERE ARE 33 CITED REFERENCES AVAILABLE FOR THIS RECORD
  RE.CNT 33
  RE
  (1) Abrahams, E; Phys Rev Lett 1979, V42, P673
  (2) Altshuler, B; Electron-electron Interactions in Disordered Systems 1985
  (3) Altshuler, B; J Phys C 1982, V15, P7367 HCAPLUS
  (4) Altshuler, B; Solid State Comm 1979, V30, P115 HCAPLUS
  (5) Anderson, P; Phys Rev 1958, V109, P1492 HCAPLUS
  (6) Averin, D; Mesoscopic Phenomena in Solids 1991, P173
  (7) Averin, D; Single Charge Tunneling 1991
  (8) Bachtold, A; Nature 1999, V397, P673 HCAPLUS
  (9) Cleland, A; Phys Rev Lett 1990, V64, P1565
  (10) Davydov, D; Phys Rev B 1998, V57, P13550 HCAPLUS
  (11) Delsing, P; Phys Rev Lett 1989, V63, P1180 HCAPLUS
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( L32 ANSWER 13 OF 82 HCAPLUS COPYRIGHT ACS on STN
   2001:217673 HCAPLUS
AN
    Entered STN: 28 Mar 2001
ED
    Tactile sensor comprising nanowires and method for
    making the same
    Jin, Sungho
IN
    Lucent Technologies Inc., USA
                                      APPLICATION NO.
    PATENT NO. KIND DATE
                                                             _____
                                       _____
                      ----
                             20010328 EP 2000-307853
                                                             20000911 <--
                      A2
    EP 1087413
                             20021002
                      A3
    EP 1087413
                             19990924 <--
                      A
PRAI US 1999-405641
CLASS
              CLASS PATENT FAMILY CLASSIFICATION CODES
 PATENT NO.
              .
                      но1но01-06
               ICM
 EP 1087413
                      но1но03-16; но1но01-00
               ICS
               ECLA H01H001/00M; H01H001/06
 EP 1087413
     A tactile sensor device is disclosed that can be used for high resolution tactile sensing.
     The sensor may be used as a tactile shear sensor. It comprises a circuit substrate; an array
     of contact pads on the circuit substrate, and a set of nanowires attached to each of the
     contact pads. The contact pads may be isolated or formed from a matrix of interconnecting
      strips of material. Each set of nanowires comprises at least one and preferably a plurality
      of nanowires that are desirably vertically aligned and equal in length. When an object
      contacts at least one of the plurality of sets of nanowires, it causes at least one set of
      nanowires to bend and make contact along a portion of the length thereof with at least another
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set of nanowires. The position and movement activity of the object can be sensed by elec. interrogating pairs of contact pads to determine whether a connection has been made between

them.

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L32 ANSWER 14 OF 82 HCAPLUS COPYRIGHT ACS ON STN
     2001:186063 HCAPLUS
AN
     134:201658
DN
     Entered STN: 16 Mar 2001
ED
     Strongly textured atomic ridges and dots in a MOSFET device
TΙ
     Kendall, Don; Guttag, Mark
IN
     Starmega Corporation, USA
PA
                                            APPLICATION NO.
                                                                   DATE
                        KIND
                                DATE
     PATENT NO.
                                            -----
                                                                   _____
                                                                   20000908 <--
                                            WO 2000-US24815
                                20010315
                         A1
     WO 2001018866
PΙ
                                                                   19981109 <--
                                            JP 2000-519926
                          Т2
                                20011120
     JP 2001523049
                                                                   19981109 <--
                                            US 1998-187730
                          B1
                                20031223
     US 6667492
                                                                   20000908 <--
                                            US 2000-657533
                                20020702
     US 6413880
                          В1
                                                                   20000908 <--
                                            EP 2000-966708
                                20020710
     EP 1221179
                          Α1
                                                                   20000908 <--
                                            US 2000-658878
                                20021015
                          В1
     US 6465782
                                                                   20000908 <--
                                            US 2000-658599
                                20030121
                          B1
     US 6509619
                                                                   20030930 <--
                                            us 2003-673378
                                20040401
                          Α1
     US 2004061103
                                19971110 <--
                          P
PRAI US 1997-65082P
                                19990910 <--
     US 1999-153088P
                          P
                                19981109
                                          <--
     US 1998-187730
                          A
                                19981109
                                          <--
                          W
     WO 1998-US23875
                                          <--
```

W 20000908 The present invention provides a MOSFET device comprising: a substrate including a plurality WO 2000-US24815 of atomic ridges, each of the atomic ridges including a semiconductor layer comprising Si and AB a dielec. layer comprising a Si compound; a plurality nanogrooves between the atomic ridges;  $\geq$ 1 elongated mol. located in  $\geq$ 1 of the nanogrooves; a porous gate layer located on top of the plurality of atomic ridges. The present invention also provides a membrane comprising: a substrate; and a plurality of nanowindows in the substrate and a method for forming nanowindows in a substrate. The present invention also provides a multi-tip array device comprising: a substrate; a multi-tip array of atomic tips on the substrate, the multi-tip array having a pitch of 0.94-5.4 nm between adjacent tips in  $\geq 1$  direction; and means for moving the substrate. The present invention also provides an atomic claw comprising: a mounting block; a paddle having a multi-tip array thereon, the multi-tip array having a pitch of 0.94-5.4 nm between adjacent tips in  $\geq 1$  direction; and a cantilever connected to the paddle and the mounting block, in which the cantilever allows the paddle to be moved in  $\geq 1$  arcuate direction.

#### Nanowires (metallic) IT

(gold, silver; strongly textured atomic ridges and dots in a nanostructured MOSFET device)

#### IT DNA

Peptides, uses

RNA

RL: NUU (Other use, unclassified); USES (Uses) (long chain mols.; strongly textured atomic ridges and dots in a nanostructured MOSFET device)

Cantilevers (components) IT

Sensors

(strongly textured atomic ridges and dots in a nanostructured MOSFET device)

## 10102-44-0, Nitrogen oxide (NO2), analysis

RL: ANT (Analyte); ANST (Analytical study)

(detection by nanotubes; strongly textured atomic ridges and dots in a nanostructured MOSFET device)

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L62 ANSWER 5 OF 14 HCAPLUS COPYRIGHT ACS on STN
     2001:168012 HCAPLUS
AN
     134:221448
     Entered STN: 09 Mar 2001
ED
     Antibodies specific for fullerenes
TΙ
     Erlanger, Bernard F.; Chen, Bi-Xing
IN
     The Trustees of Columbia University in the City of New York, USA
PA
                                                                       DATE
                                              APPLICATION NO.
                                  DATE
                          KIND
     PATENT NO.
                                                                       _____
                          ____
                                                                       20000829 <--
                                              WO 2000-US23629
                                  20010308
                           Α1
     WO 2001016155
ΡĬ
                                              US 1999-386658
                                                                       19990831
                                  20030715
                           В1
     US 6593137
                                                                       20000829 <--
                                              CA 2000-2383015
                                  20010308
                           AΑ
     CA 2383015
                                                                       20000829 <--
                                              EP 2000-957880
                           A1
                                  20020703
     EP 1218396
                                  20040922
     EP 1218396
                           В1
                                                                       20000829 <--
                                               JP 2001-519717
                                  20030304
                           Т2
     JP 2003508035
                                                                       20000829 <--
                                              AT 2000-957880
                           E
                                  20041015
     AT 277083
                                  19990831 <--
PRAI US 1999-386658
                           Α
                                  20000829 <--
     WO 2000-US23629
                            W
      This invention provides antibodies specific for a fullerene or derivative thereof, a single-
      walled fullerene nanotube, and a multi-walled fullerene nanotube, wherein the fullerene is
AB
      selected from the group consisting of a fullerene carbon compound having from 20 to 540 carbon
      atoms. The antibodies may be monoclonal or polyclonal antibodies. This invention provides a
      hybridoma produced by the fusion of a mouse antibody-producing cell and a mouse myeloma which
      is designated 1-10F-8A and deposited with the ATCC under Accession Number PTA-279, said
      hybridoma producing a monoclonal antibody which binds to fullerene C60. This invention
      provides a mouse monoclonal antibody specific for a fullerene-C60 and produced by the mouse
      monoclonal antibody-producing hybridoma designated 1-10F-8A. This invention also provides
      methods of determining a serum concentration of a fullerene in a subject and of purifying a
       fullerene from a sample. This invention provides methods of preparing nonascale devices which
       comprise manipulating a single-walled or a multi-walled fullerene nanotube(s) with the above-
       described antibodies specific for single-walled or multi-walled fullerene nanotubes to
       assemble electronic or chemical components of the nanoscale device.
      Immunoglobulins
      RL: ARG (Analytical reagent use); BPN (Biosynthetic preparation); BSU
      (Biological study, unclassified); PRP (Properties); THU (Therapeutic use);
      ANST (Analytical study); BIOL (Biological study); PREP (Preparation); USES
      (Uses)
         (G; antibodies specific for fullerenes)
      Blood serum
      Chemiluminescent substances
      DNA sequences
      Dyes
      Fluorescent substances
      Hybridoma
      Immunoassay
      Labels
      Protein sequences
         (antibodies specific for fullerenes)
      Antibodies
      RL: BPN (Biosynthetic preparation); BSU (Biological study, unclassified);
      THU (Therapeutic use); BIOL (Biological study); PREP (Preparation); USES
       (Uses)
         (antibodies specific for fullerenes)
      Fullerenes
      RL: BPR (Biological process); BSU (Biological study, unclassified); BIOL
       (Biological study); PROC (Process)
          (antibodies specific for fullerenes)
      Immunoglobulins
  IT
       RL: ARG (Analytical reagent use); BPN (Biosynthetic preparation); BSU
       (Biological study, unclassified); PRP (Properties); THU (Therapeutic use);
       ANST (Analytical study); BIOL (Biological study); PREP (Preparation); USES
       (Uses)
          (heavy chains; antibodies specific for fullerenes)
       Immunoglobulins
  IT
       RL: ARG (Analytical reagent use); BPN (Biosynthetic preparation); BSU
       Analytical apparatus
  IT
          (nanoscale device; antibodies specific for fullerenes)
       Biosensors
       Electric apparatus
       Optical instruments
          (nanoscale; antibodies specific for fullerenes)
```

# L65 ANSWER 3 OF 35 HCAPLUS COPYRIGHT ACS on STN

- 2000:798080 HCAPLUS AΝ
- Entered STN: 14 Nov 2000 ED
- DNA conformation switching using a templated conducting polymer. TΙ
- Nagarajan, Ramaswamy; Tripathy, Sukant K.; Kumar, Jayant; Bruno, Ferdinando F.; Samuelson, Lynne
  - Department of Chemistry, Center for Advanced Materials, University of
  - Massachusetts, Lowell, MA, 01854, USA Abstracts of Papers, 220th ACS National Meeting, Washington, DC, United
- SO States, August 20-24, 2000 (2000) PMSE-311 CODEN: 69FZC3
- American Chemical Society
- Journal; Meeting Abstract DT
- English LA

CS

DNA has been used as a biol. template for the enzymic synthesis of conducting polyaniline. AB Template (polyelectrolyte) assisted, enzymic synthetic approach has yielded a water-soluble and conducting complex of polyaniline and the template used. The mild and near neutral pH conditions of this enzymic approach are unique and allow for the use of DNA as the polyelectrolyte to form an electro-responsive DNA/polyaniline mol. complex. UV-Vis and CD spectroscopy confirm that the polyaniline macromols. formed mimic the DNA template contour. The secondary structure of the DNA may in turn be reversibly controlled through the redox state of the polyaniline. These studies suggest new opportunities towards the development of DNA based nano-wires, biosensors and diagnostic tools.

- ANSWER 2 OF 5 HCAPLUS COPYRIGHT ACS on STN L64
- 2000:798006 HCAPLUS AN
- Entered STN: 14 Nov 2000 ΕD
- Elaboration of conducting polymer nanostructures: Applications as responsive materials in gas sensors and biosensors.
- Demoustier-Champagne, Sophie M.; Stavaux, Pierre-Yves; Delvaux, Marc ΑU
- Department of Materials, Universite catholique de Louvain, CS Louvain-la-Neuve, B-1348, Belg.
- Abstracts of Papers, 220th ACS National Meeting, Washington, DC, United SO States, August 20-24, 2000 (2000) PMSE-240 CODEN: 69FZC3
- American Chemical Society PB
- Journal; Meeting Abstract DT
- English LA
- The use of nanoporous particle track-etched membranes (nano-PTM) as templates for the AB preparation of perfectly cylindrical and very smooth conducting polymer nanotubes has been considered. Chemical and electrochem. processes allowing the deposition of conducting polymers within the pores of nano-PTM have been developed and optimized. Electrodeposition has several advantages over chemical deposition process. In particular, it allows an easy control of the growth rate and of the nanotubes length and it offers the possibility of immobilizing enzymes in a one-step procedure during the electrochem. deposition of the conducting polymers within the pores of the template. Compared to the existing sensors based on conducting polymer films, electroactive polymer nanotubes provide a larger surface area per unit volume and present enhanced elec. conductivity with respect to the bulk form (2 orders of magnitude for narrow nanotubes). These properties can lead to an enhancement of the sensibility of gas sensors and biosensors.

## L65 ANSWER 4 OF 35 HCAPLUS COPYRIGHT ACS on STN

- 2000:795406 HCAPLUS
- Entered STN: 14 Nov 2000
- Quantative determination of functional groups on chemical modified carbon ΤI nanotube.
- Sun, Yi; Wilson, Stephen R. AU
- Department of Chemistry, New York University, New York, NY, 10003, USA CS
- Abstracts of Papers, 220th ACS National Meeting, Washington, DC, United States, August 20-24, 2000 (2000) IEC-156 CODEN: 69FZC3
- American Chemical Society PB
- Journal; Meeting Abstract DT
- English LA
- Because of their unique electronic and mech. properties, carbon nanotubes have proved to be AΒ important new materials and may find application in many fields-- from microelectronic devices to chem . probes. The chemical modification of carbon nanotubes is important in tailoring their properties and many applications are expected to derive from functionalized carbon nanotubes. However, quantative determination of functional groups on chemical modified carbon nanotubes has not well established. Herein, a quantative method was developed to determine the active amine groups on the surface of functionalized carbon nanotube. A novel hybrid of amine-derived carbon nanotube and 9-fluorenylmethyloxycarbonyl (Fmoc) has been constructed. Subsequent cleavage of Fmoc group from above hybrid by piperidine can release Fmoc-piperidine adduct, which can be measured quntatively by UV spectra. This method has provided us a rapid, accurate and quantative way to determine active amine groups on carbon nanotube .

DIALOG(R)File 94:JICST-EPlus (c) Japan Science and Tech Corp(JST). All rts. reserv. JICST ACCESSION NUMBER: 02A0411622 FILE SEGMENT: JICST-E Advanced microstructure and magnetism controls of alloy cluster aggregates for creating cluster-based advanced materials. SUMIYAMA KENJI (1) (1) Nagoya Inst. of Technol. Kyokugen Kankyo Jotai ni okeru Gensho Shinpojiumu. Koen Yoshishu. Heisei 12nen, 2000, PAGE.5-8, FIG.4 JOURNAL NUMBER: N20020693P UNIVERSAL DECIMAL CLASSIFICATION: 539.18/.19CLUSTER 537.6 548.5.07 COUNTRY OF PUBLICATION: Japan LANGUAGE: Japanese DOCUMENT TYPE: Conference Proceeding ARTICLE TYPE: Commentary MEDIA TYPE: Printed Publication The investigation is conducted for creating advanced materials from clusters of the uniform size of nanometer order. Typical results obtained are explained. 1) Mono-dispersed clusters of metals and alloys are produced with an experimental apparatus that is to deposit condensed clusters in plasma and gas consisting of a metal evaporation method by sputtering, and a cooling and condensation process with rare gas. 2) Cadmium selenide cluster is prepared by an inverse micelle method. The size selectivity of the process is enhanced by liquid chromatographic studies. The background theory is studied, namely, a growth process in one direction of metallic atoms in the cluster forming apparatus is simulated by considering collisions of the metallic atoms with other metallic atoms, rare gas atoms and the internal wall of the apparatus. 3) The first principle calculation is conducted for validating the stability of the magic numbers that are obtained by observing the clusters prepared by the methods mentioned above. 4) The basic properties are explained. Various applications of the clusters and aggregates are present in many fields. The magnetic transition of cobalt clusters at room temperature from a super paramagnetic state/a ferromagnetic state is an example for metallic clusters. An improvement of magnetic anisotropy by alloying is expected. The magnetic resistance effect is expected in the composite materials of cobalt/cobalt oxide. The clusters can be expected to be applied to magnetic sensors and gas sensors. 5) One of the applications of semiconductor and oxide clusters is the controls of the size and shape by changing the adsorbed amount and species of surface active agents on growing cluster surfaces and controls of the species and amounts of the agents introduced into the systems. 6) The photocatalytic effect (hydrogen gas generation) of sulfide semiconductor nano-clusters is DESCRIPTORS: cobalt; microcluster; cobalt oxide; nanostructure; magnetic transition; crystal growth; semiconductor material; magnetoresistance effect; cadmium selenide; sputtering; gas evaporation method; silicon carbide; iodide; nitrate(salt); hydrogen evolution reaction; cadmium sulfide; zinc sulfide; silicon; reverse micelle; plasma application; superparamagnetism; ferromagnetism; magnetic recording material; magnetic anisotropy; lead compound; fullerene C60; gold; cluster formation; photocatalytic reaction; cluster; growth IDENTIFIERS: metallic cluster; cluster growth BROADER DESCRIPTORS: fourth row element; element; iron group element; transition metal; metallic element; metal oxide; oxide; chalcogenide; oxygen group element compound; oxygen compound; cobalt compound; iron group element compound; transition metal compound; structure; magnetic property; phase transition; electric material; material; galvanomagnetic effect; magnetic field effect; effect; cadmium compound ; 2B group element compound; selenide(chalcogenide); selenium compound; setting(solidification); silicon compound; carbon group element compound; carbide; carbon compound; halide; halogen compound; iodine compound; nitrogen oxoate; oxoate; nitrogen compound; nitrogen group element compound; chemical reaction; sulfide(chalcogenide); sulfur compound; zinc compound; third row element; carbon group element; micelle; utilization; magnetism; recording material; magnetic material; anisotropy; property; fullerene; molecular cluster; molecule; carbon; second row element; 1B group element; phenomenon; photochemical reaction; catalytic reaction

CLASSIFICATION CODE(S): BH090300; BM06010M; BK13020B

13/9/3 DIALOG(R) File 94: JICST-EPlus (c) Japan Science and Tech Corp(JST). All rts. reserv. JICST ACCESSION NUMBER: 00A0154454 FILE SEGMENT: JICST-E Fluorescence-label of biomolecules using semiconductor nano fine particles. YAMANA KAZUSHIGE (1) (1) Himeji Inst. of Technol. Kagaku(Chemistry), 2000, VOL.55, NO.1, PAGE.72-73, FIG.5, REF.6 ISSN NO: 0451-1964 CODEN: KAKYA JOURNAL NUMBER: F0095AAJ UNIVERSAL DECIMAL CLASSIFICATION: 543-4 COUNTRY OF PUBLICATION: Japan LANGUAGE: Japanese DOCUMENT TYPE: Journal ARTICLE TYPE: Commentary MEDIA TYPE: Printed Publication This paper explains the titled particle (I) technology on the following items: 1) ABSTRACT: Features of luminescence characteristics, useful as fluorescence detection systems, 2) core-shell type CdSe-ZnS fine semiconductor particles covered with ZnS having higher band gap, followed by chemical modification or covalently bonding with protein or DNA, along with the application as a fluorescence probe for biomolecules, 3) applications to cell inside; observation of nucleus of mouse fibroblast, actin filaments and nuclear membranes by two chemically modified semiconductor fine particles with different size and 4) incorporation of semiconductor particles modified with transferrin into Hela cells by endocytosis via receptor bonds. DESCRIPTORS: ultrafine particle; fluorescent labeling; semiconductor; cadmium selenide; zinc sulfide; endocytosis; forbidden band; HeLa cell; fibroblast; transferrin; urea compound; carboxylic acid; nitrogen heterocyclic compound; coenzyme; sulfur heterocyclic compound IDENTIFIERS: nanoparticle BROADER DESCRIPTORS: fine particle; particle; labeling method; cadmium compound; 2B group element compound; transition metal compound; selenide(chalcogenide); chalcogenide; oxygen group element compound; selenium compound; zinc compound; sulfide(chalcogenide); sulfur compound; cell physiology; energy gap; band structure; energy level; tumor cell; idioblast; cell(cytology); cultured cell; blast cell; blood protein; blood component; component; animal protein; protein; chromoprotein; heterocyclic compound CLASSIFICATION CODE(S): CC02030D

## L65 ANSWER 5 OF 35 HCAPLUS COPYRIGHT ACS on STN

- AN 2000:795398 HCAPLUS
- ED Entered STN: 14 Nov 2000
- TI Chemical modification of carbon nanotube sidewalls: Quantum chemistry calculations and molecular simulations.
- AU Jaffe, Richard L.
- CS Computational Chemistry Branch, NASA Ames Research Center, Moffett Field, CA, 94035, USA
- SO Abstracts of Papers, 220th ACS National Meeting, Washington, DC, United States, August 20-24, 2000 (2000) IEC-148 CODEN: 69FZC3
- PB American Chemical Society
- DT Journal; Meeting Abstract
- LA English
- The remarkable properties of carbon nanotubes make them attractive candidates for nanostructured materials, mol.—scale electronic devices and biol., chemical and mech. sensors. However, many concepts for utilizing nanotubes for these applications require chemical modification of the sidewall to increase solubility, promote self-assembly and to enhance the elec. response of the device or sensor. We have studied likely approaches to chemical modification of nanotube sidewalls using quantum chemical calcums. to identify stable products and reaction pathways with modest activation barriers. We have also carried out mol. mechanics and dynamics simulations of functionalized nanotubes to assess the changes that occur in mech. and electronic properties. Results for fluorinated and methylated carbon nanotubes will be presented along with results for several hypothetical cycloaddn. reactions.

## L32 ANSWER 15 OF 82 HCAPLUS COPYRIGHT ACS on STN

- AN 2000:795269 HCAPLUS
- ED Entered STN: 14 Nov 2000
- TI Self assembling and nanostructured materials through supramolecular chemistry.
- AU Stupp, Samuel I.
- CS Materials Science, Chemistry, Medicine, Northwestern University, Evanston,
- SO Abstracts of Papers, 220th ACS National Meeting, Washington, DC, United States, August 20-24, 2000 (2000) IEC-020 CODEN: 69FZC3
- PB American Chemical Society
- DT Journal; Meeting Abstract
- LA English
- Learning how to program organic mols. for self assembly into anostructures with specific shapes and chemical maps on their surfaces is of critical importance in nanotechnol. and in the development of advanced materials. Zero-dimensional objects of low symmetry shapes could pack lattices with large periodicities and cavities with useful functions such as sensing, catalysis, selective transport, templating, and bioactivity. As individual nanostructures they could be used to modify the surfaces and bulk properties of known materials, build nanoscale devi es, and change the behavior of cells through targeted interactions. One-dimensional nanostructures having any desired chemical structure are also an important target to template nanowires, reinforce polymers, and interconnect cells. This lecture will describe examples of OD and 1D structures formed by a toolbox of triblock mols. having rodcoil and dendron rodcoil architecture. The examples to be described include, 10 nm wide ribbons which transform polymeric glasses and rubbers into ordered structures, and also template semiconducting nanowires, as well as amphiphilic and fluorescent aggregates that travel to the nuclei of cells and could therefore be extremely useful in bioengineering.

#### L32 ANSWER 16 OF 82 HCAPLUS COPYRIGHT ACS on STN

- AN 2000:794431 HCAPLUS
- ED Entered STN: 14 Nov 2000
- TI Direct measurement of the conductance of single conducting polymer nanowire and its application in biological nanosensor.
- AU He, H. X.; Li, C. Z.; Tao, N. J.
- CS Department of Physics, Florida International University, Miami, FL, 33199,
- SO Abstracts of Papers, 220th ACS National Meeting, Washington, DC, United States, August 20-24, 2000 (2000) COLL-239 CODEN: 69FZC3
- PB American Chemical Society
- DT Journal; Meeting Abstract
- LA English
- The conductance of a single conducting polymer nanowire has been directly measured, for the first time, using scanning tunneling microscope (STM) setup. The experiment takes advantage of STM for picoampere current detection and Angstrom-level position control. In the experiment, the STM tip was held at a certain distance from an Au substrate while polyaniline was electrochem. deposited from aniline monomer solution onto the tip and substrate until a bridge was formed between. When bridged, we observed a sharp increase of current at the electrochem. potential where polyaniline is of highest conductivity After bridging, the Au substrate was pulled away using a DC motor and the current was simultaneously monitored. As the Au substrate retracts, the cross-section of the polyaniline bridge decreases down to nanometer scale as the length increases. At the very beginning, the current fluctuates and then decreases in a stepwise fashion until the nanowire finally breaks up. The mechanism of the conductance change upon elongation will be discussed. The potential of the conducting polymer nanowire as a biol. nanosensor will also be discussed.

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L32 ANSWER 17 OF 82 HCAPLUS COPYRIGHT ACS on STN
AN
     2000:724406 HCAPLUS
DN
     134:12599
     Entered STN: 13 Oct 2000
ED
ΤI
     Microwires coated by glass: a new family of soft and hard magnetic
ΑU
     Zhukov, A.; Gonzalez, J.; Blanco, J. M.; Vazquez, M.; Larin, V.
     Donostia International Physics Center, San Sebastian, 20018, Spain
CS
     Journal of Materials Research (2000), 15(10), 2107-2113
SO
     CODEN: JMREEE; ISSN: 0884-2914
PR
     Materials Research Society
DT
     Journal
LA
     English
     77-8 (Magnetic Phenomena)
CC
     Section cross-reference(s): 55, 56
      The Taylor-Ulitovski technique was employed for fabrication of tiny ferromagnetic amorphous
AB
      and nanocryst. metallic wires covered by an insulating glass coating with magnetic properties
      of great technol. interest. A single and large Barkhausen jump was observed for microwires
      with pos. magnetostriction. Neg. magnetostriction microwires exhibited almost unhysteretic
      behavior with an easy axis transverse to the wire axis. Enhanced magnetic softness (initial
      permeability, µL, up to 14000) and giant magneto impedance (GMI) effect (up to 140% at 10 MHz)
      was observed in amorphous CoMnSiB microwires with nearly zero magnetostriction after adequate
      heat treatment. Large sensitivity of GMI and magnetic characteristics on external tensile
      stresses was observed Upon heat treatment, FeSiBCuNb amorphous microwires devitrified into a
      nanocryst. structure with enhanced magnetic softness. The magnetic bistability was observed
      even after the 2nd crystallization process (increase of switching field by >2 orders of
      magnitude up to 5.5 kA/m). Hard magnetic materials were obtained as a result of decomposition
      of metastable phases in Co-Ni-Cu and Fe-Ni-Cu microwires fabricated by Taylor-Ulitovski
      technique when the coercivity increased up to 60 kA/m. A magnetic sensor based on the
      magnetic bistability was designed.
     Magnetostriction
       Nanowires (metallic)
         (magnetic properties of amorphous and nanocryst. ferromagnetic glass
        coated microwires)
              THERE ARE 27 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
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L32 ANSWER 19 OF 82 HCAPLUS COPYRIGHT ACS on STN
     2000:598689 HCAPLUS
AN
DN
     133:245740
     Entered STN: 29 Aug 2000
ED
     Coulomb blockade in a silicon-on-sapphire nanowire
ΤI
     Dovinos, D.; Hasko, D. G.; Helin, Z.
ΑU
     Microelectronics Research Centre, Cavendish Laboratory, University of
CS
     Cambridge, Cambridge, CB3 OHE, UK
     Microelectronic Engineering (2000), 53(1-4), 199-202
SO
     CODEN: MIENEF; ISSN: 0167-9317
     Elsevier Science B.V.
PB
DT
     Journal
LA
     English
     76-3 (Electric Phenomena)
CC
      The use of single electron devices as photon detectors, in the IR wavelength range, is
AB
      explored. The operating mechanism uses photon assisted tunneling so that the device current
      in a single electron transistor (SET) with a bias voltage of less than the Coulomb gap voltage
      depends on the rate of interaction with the photons. Coupling between the photons and the SET
      requires the use of a planar antenna structure so that the greatest response is from the
      substrate side. The use of an IR transparent substrate, such as sapphire, is important to
      maximize the detection sensitivity. The fabrication and elec. behavior of SETs made using
      silicon-on-sapphire is described and the detection performance is predicted.
      Coulomb blockade silicon sapphire nanowire
ST
      Optical detectors
TT
         (IR; coulomb blockade in a silicon-on-sapphire nanowire)
      Coulomb blockade
 IT
      Electric current
        Nanowires (metallic)
         (coulomb blockade in a silicon-on-sapphire nanowire)
 ΙT
      Tunneling
         (photon-assisted; coulomb blockade in a silicon-on-sapphire
         nanowire)
 IT
      Transistors
         (single electron; coulomb blockade in a silicon-on-sapphire
         nanowire)
                            7440-21-3, Silicon, uses
      1317-82-4, Sapphire
 IT
      RL: DEV (Device component use); USES (Uses)
         (coulomb blockade in a silicon-on-sapphire nanowire)
               THERE ARE 7 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT
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## L19 ANSWER 1 OF 5 HCAPLUS COPYRIGHT ACS on STN

- AN 2000:598845 HCAPLUS
- DN 133:260021
- ED Entered STN: 29 Aug 2000
- TI Nanoimprint- and UV-lithography: Mix&Match process for fabrication of interdigitated nanobiosensors
- AU Montelius, L.; Heidari, B.; Graczyk, M.; Maximov, I.; Sarwe, E-L.; Ling, T. G. I.
- CS Div. Solid State Physics, Dept. Physics, University of Lund, Lund, S-21 00, Swed.
- SO Microelectronic Engineering (2000), 53(1-4), 521-524 CODEN: MIENEF; ISSN: 0167-9317
- PB Elsevier Science B.V.
- DT Journal
- LA English
- CC 76-3 (Electric Phenomena)
   Section cross-reference(s): 1
- AB A complete nanobiosensor structure consisting of a 200 µm + 200 µm area containing 100 nm sized interdigitated nanoelectrodes with varied interelectrode distances has been fabricated using nanoimprint lithog. (NIL) in combination with UV-lithog. The complete structure has been characterized with admittance spectroscopy. In the paper are discussed the needs and key issues for nanosensors and the capability offered by using NIL for fabrication of such sensors.
- ST interdigitated nanobiosensor nanoimprint UV lithog
- IT Photolithography
  - (UV; process for fabrication of interdigitated nanobiosensors for nanoimprint- and UV-lithog.)
- IT Biosensors
  - Lithography
    - (process for fabrication of interdigitated nanobiosensors for nanoimprint- and UV-lithog.)
- RE.CNT 5 THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD

RE

- (1) Anon; Technology Roadmap for Nanoelectronics, <a href="http://www.cordis.lu/esprit/sr">http://www.cordis.lu/esprit/sr</a> c/melari.htm 1999
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- (5) Montelius, L; J Vac Sci Techn A 1995, V13, P1755 HCAPLUS

#### L19 ANSWER 2 OF 5 HCAPLUS COPYRIGHT ACS on STN 2000:590982 HCAPLUS AN 133:292953 DN Entered STN: 25 Aug 2000 ED The development of optical nanosensors for biological measurements TΙ Cullum, B. M.; Vo-Dinh, T. AU Advanced Monitoring Development Group, Oak Ridge National Laboratory, Oak CS Ridge, TN, 37831-6101, USA Trends in Biotechnology (2000), 18(9), 388-393 SO CODEN: TRBIDM; ISSN: 0167-7799 Elsevier Science Ltd. PB Journal; General Review DT English LA 9-0 (Biochemical Methods) CC A review with 38 refs. This article discusses and documents the basic concepts of, and AB developments in, the field of optical nanosensors and nanobiosensors. It describes the progression of this field of research from its birth up to the present, with emphasis on the . techniques of sensor construction and their application to biol. systems. After a brief overview of the techniques for fabricating nanometer-sized optical fibers, we describe the various types of transducer and bioreceptor mol. presently used for nanosensor and nanobiosensor fabrication. optical nanosensor biol system review; biosensor nanosensor biol review ST Biosensors IT (nanobiosensors; development of optical nanosensors and nanobiosensors for biol. measurements) Optical sensors (nanosensors; development of optical nanosensors and nanobiosensors for biol. measurements) THERE ARE 40 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT RE (1) Alarie, J; Anal Chim Acta 1990, V229, P169 HCAPLUS (2) Alarie, J; Polycyclic Aromat Compounds 1996, V8, P45 HCAPLUS (3) Anon; Scanning Microscopy Technology and Applications 1988, V897 (4) Barker, S; Anal Chem 1998, V70, P100 HCAPLUS (5) Barker, S; Anal Chem 1998, V70, P4902 HCAPLUS (6) Barker, S; Anal Chem 1998, V70, P971 HCAPLUS (7) Betzig, E; Appl Phys Lett 1987, V51, P2088 (8) Betzig, E; Science 1991, V251, P1468 (9) Betzig, E; Science 1993, V262, P1422 HCAPLUS (10) Bui, J; J Neurosci Methods 1999, V89, P9 MEDLINE (11) Clark, H; Anal Chem 1999, V71, P4831 HCAPLUS (12) Clark, H; Anal Chem 1999, V71, P4837 HCAPLUS (13) Cordek, J; Anal Chem 1999, V71, P1529 HCAPLUS (14) Cullum, B; Anal Biochem 2000, V277, P25 HCAPLUS (15) Davis, J; Enzyme Microb Technol 1995, V17, P1030 HCAPLUS (16) Deckert, V; Anal Chem 1998, V70, P2646 HCAPLUS (17) Diamond, D; Principles of Chemical and Biological Sensors 1988 (18) Durig, U; J Appl Phys 1986, V59, P3318 (19) Harootunian, A; Appl Phys Lett 1986, V49, P674 HCAPLUS (20) Hoffmann, P; Ultramicroscopy 1995, V61, P165 HCAPLUS (21) Koronczi, I; Sens Actuat B 1998, V51, P188 (22) Lieberman, K; Science 1990, V247, P59 (23) McCulloch, S; IEEE Proc Optoelectron 1995, V144, P162 (24) Munkholm, C; Anal Chem 1987, V58, P1427 (25) Munkholm, C; J Am Chem Soc 1990, V112, P2608 HCAPLUS (26) Pohl, D; Advances in Optical and Electron Microscopy 1984, P1084 (27) Pohl, D; Appl Phys Lett 1984, V44, P651 (28) Samuel, J; Mater Lett 1994, V21, P431 HCAPLUS (29) Seitz, W; Anal Chem 1984, V56, P16A HCAPLUS (30) Song, A; Anal Chem 1997, V69, P863 HCAPLUS (31) Stockle, R; Appl Phys Lett 1999, V75, P160 HCAPLUS (32) Tan, W; Anal Chem 1992, V64, P2985 HCAPLUS (33) Tan, W; Anal Chem 1999, V71, P606A HCAPLUS (34) Tan, W; Science 1992, V258, P778 HCAPLUS (35) Tan, W; Sens Actuat B 1995, V28, P157 (36) Turner, D; US 4469554 1984 HCAPLUS

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L65 ANSWER 8 OF 35 HCAPLUS COPYRIGHT ACS on STN
     2000:584953 HCAPLUS
ΑN
     133:282167
DN
ED
     Entered STN: 23 Aug 2000
     Biochemical synthesis and unusual conformational switching of a molecular
     complex of polyaniline and DNA
     Nagarajan, Ramaswamy; Tripathy, Sukant K.; Kumar, Jayant; Samuelson, Lynne
ΑU
     A.; Bruno, Ferdinando F.
     Department of Chemistry and Physics, Center for Advanced Materials,
CS
     University of Massachusetts Lowell, Lowell, MA, 01854, USA
     Materials Research Society Symposium Proceedings (2000), 600 (Electroactive
SO
     Polymers (EAP)), 249-254
     CODEN: MRSPDH; ISSN: 0272-9172
     Materials Research Society
DT
     Journal
LA
     English
     35-7 (Chemistry of Synthetic High Polymers)
CC
     Section cross-reference(s): 6, 36
      Polyaniline (PANI) conducting polymer with unique redox tunability was prepared via template
AB
      assisted, enzymic synthesis, obtaining a water-soluble and conducting complex of polyaniline
      and DNA used as template. The oxidative polymerization was carried out in a Thymus DNA
      solution in citrate buffer at pH 4 containing aniline and a catalytic amount of Horseradish
      peroxidase by drop-wise addition of H2O2 over a period of 240 s. The mild reaction conditions
      in this approach allow use of delicate biol. systems as template materials. The redox
      behavior of PANI induces reversible conformational changes in the secondary structure of DNA
      which prior to formation of PANI is present as the B polymorph. The DNA template provides the
      counterions necessary for charge compensation and maintains PANI in the doped form while the
      helical template induces a macro-asymmetry in PANI. Thus, CD results suggest that the
      secondary structure of DNA can be reversibly switched through manipulation of the redox state
      of polyaniline by varying the pH of the solution via addition of a solution of NaOH. The
      complex can be used for fabrication of nano- wires, biosensors, and diagnostic tools as well
      as for probing the microstructure and function of DNA.
     polyaniline prepn DNA template redox mol complex; oxidative polymn aniline
ST
     DNA template pH reversibility; conformational switching DNA polyaniline
     mol complex; enzyme catalyzed oxidative polymn polyaniline prepn
     Conformation
IT
     Helix (conformation)
         (DNA; enzyme catalyzed oxidative polymerization of aniline on DNA template to
        obtain mol. complexes and redox-induced conformational switching of
        DNA)
      Conducting polymers
IT
         (enzyme catalyzed oxidative polymerization of aniline on DNA template to
        obtain mol. complexes and redox-induced conformational switching of
         DNA)
 TT
      Polyanilines
      RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)
         (enzyme catalyzed oxidative polymerization of aniline on DNA template to
         obtain mol. complexes and redox-induced conformational switching of
         DNA)
 TΤ
      Polymerization
         (oxidative; enzyme catalyzed oxidative polymerization of aniline on DNA
         template to obtain mol. complexes and redox-induced conformational
         switching of DNA)
      Redox reaction
 IT
         (reversible, pH induced; enzyme catalyzed oxidative polymerization of aniline
         on DNA template to obtain mol. complexes and redox-induced
         conformational switching of DNA)
 ΙT
      RL: NUU (Other use, unclassified); PRP (Properties); USES (Uses)
         (template; enzyme catalyzed oxidative polymerization of aniline on DNA
         template to obtain mol. complexes and redox-induced conformational
```

(templates; enzyme catalyzed oxidative polymerization of aniline on DNA template to obtain mol. complexes and redox-induced conformational

switching of DNA) Materials processing

switching of DNA) 25233-30-1P, Polyaniline

IT

IT

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L62 ANSWER 6 OF 14 HCAPLUS COPYRIGHT ACS on STN
ΑN
     2000:566200 HCAPLUS
     133:232016
DN
     Entered STN: 16 Aug 2000
ED
     Elaboration of conducting polymer nanostructures. applications as
ΤI
     responsive materials in gas sensors and biosensors
     Demoustier-Champagne, Sophie; Stavaux, Pierre-Yves; Delvaux, Marc
ΑU
     Universite catholique de Louvain Unite de Physique et de Chimie des Hauts
CS
     Polymeres, Louvain-la-Neuve, B-1348, Belg.
     Polymeric Materials Science and Engineering (2000), 83, 498
     CODEN: PMSEDG; ISSN: 0743-0515
     American Chemical Society
PB
DΤ
     Journal
     English
LA
     79-2 (Inorganic Analytical Chemistry)
CC
     Section cross-reference(s): 35
     Chemical and electrochem. preparation of polypyrrole (PPy) and polyaniline (PANi) nanotubes
AΒ
      obtained by using home-made polycarbonate nanoporous particle track-etched membranes as
      templates is reported. In all cases (chemical or electrochem. preparation of PPy or PANi)
      nanotubes were obtained. The tube thickness depends on the pore diameter of the template
      membrane and on the counter ion (for electropolymn.). An increase of conductivity was
      observed when the outer diameter of the tubes decreases.
     polypyrrole polyaniline nanotube electrochem sensor
ST
IT.
     Biosensors
     Gas sensors
         (electrochem.; preparation of polypyrrole and polyaniline nanotubes
        and applications as responsive materials in gas sensors and
        biosensors)
     Conducting polymers
IT
       Nanotubes
         (preparation of polypyrrole and polyaniline nanotubes and
         applications as responsive materials in gas sensors and
        biosensors)
      Polyanilines
IT
      RL: ARU (Analytical role, unclassified); PRP (Properties); SPN (Synthetic
      preparation); ANST (Analytical study); PREP (Preparation)
         (preparation of polypyrrole and polyaniline nanotubes and
         applications as responsive materials in gas sensors and
         biosensors)
      Pore structure
 IT
         (preparation of polypyrrole and polyaniline nanotubes and
         applications as responsive materials in gas sensors and
         biosensors in relation to)
      Polycarbonates, reactions
 IT
      RL: RCT (Reactant); RACT (Reactant or reagent)
         (preparation of polypyrrole and polyaniline nanotubes using)
      30604-81-0P, Polypyrrole
      RL: ARU (Analytical role, unclassified); PRP (Properties); SPN (Synthetic
      preparation); ANST (Analytical study); PREP (Preparation)
         (preparation of polypyrrole and polyaniline nanotubes and
         applications as responsive materials in gas sensors and
```

biosensors)

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L32 ANSWER 21 OF 82 HCAPLUS COPYRIGHT ACS on STN
     2000:541196 HCAPLUS
ΑN
     133:214772
DN
     Entered STN: 08 Aug 2000
ED
     Electronic connection to the interior of a mesoporous insulator with
ΤI
     nanowires of crystalline RuO2
     Ryan, Joseph V.; Berry, Alan D.; Anderson, Michele L.; Long, Jeffrey W.;
ΑU
     Stroud, Rhonda M.; Cepak, Veronica M.; Browning, Valerie M.; Rollson,
     Debra R.; Merzbacher, Celia I.
     Naval Research Laboratory, Washington, DC, 20375, USA
CS
     Nature (London) (2000), 406(6792), 169-172
SO
     CODEN: NATUAS; ISSN: 0028-0836
PB
     Nature Publishing Group
DT
     Journal
LA
     English
     72-2 (Electrochemistry)
CC
     Section cross-reference(s): 67, 76
      Highly porous materials such as mesoporous oxides are of technol. interest for catalytic,
AB
      sensing and remediation applications: the mesopores (of size 2-50 nm) permit ingress by mols.
      and guests that are phys. excluded from microporous materials. Connecting the interior of
      porous materials with a nanoscale or 'mol.' wire would allow the direct electronic control
      (and monitoring) of chemical reactions and the creation of nanostructures for high-d.
      electronic materials. The challenge is to create an electronic pathway (i.e., a wire) within
      a mesoporous platform without greatly occluding its free volume and reactive surface area.
      Here the authors report the synthesis of an electronically conductive mesoporous composite-by
      the cryogenic decomposition of RuO4-on the nanoscale network of a partially densified silica
      aerogel. The composite consists of a three-dimensional web of interconnected (.apprx.4-nm in
      diameter) crystallites of RuO2, supported conformally on the nanoscopic silica network. The
      resulting monolithic (RuO2.dblvert.SiO2) composite retains the free volume of the aerogel and
      exhibits pure electronic conductivity In addition to acting as a wired mesoporous platform,
      the RuO2-wired silica aerogel behaves as a porous catalytic electrode for the oxidation of
      chloride to mol. chlorine.
     Electric insulators
 IT
         (electronic connection to interior of mesoporous insulator with
         nanowires of crystalline RuO2)
 IT
      Crystallites
         (of RuO2 on nanoscale of partially densified silica aerogel)
      Electric conductivity
 ΙT
         (of RuO4 in preparation of RuO2-silica aerogel composite)
 IT
      Aerogels
         (silica; electronic connection to interior of mesoporous insulator with
         nanowires of crystalline RuO2: RuO2-wired silica aerogel
         electrocatalyst for chlorine evolution)
      7782-50-5, Chlorine, properties
 IT
      RL: FMU (Formation, unclassified); PRP (Properties); FORM (Formation,
      nonpreparative)
         (RuO2-wired silica aerogel electrocatalyst for chlorine evolution)
      20427-56-9, Ruthenium oxide (RuO4)
· IT
      RL: RCT (Reactant); RACT (Reactant or reagent)
         (cryogenic decomposition in preparation of RuO2-silica aerogel composite)
      12036-10-1, Ruthenium oxide (RuO2)
 IT
      RL: CAT (Catalyst use); PEP (Physical, engineering or chemical process);
      PRP (Properties); PROC (Process); USES (Uses)
         (electronic connection to interior of mesoporous insulator with
         nanowires of crystalline RuO2: RuO2-wired silica aerogel
         electrocatalyst for chlorine evolution)
               THERE ARE 25 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT
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 (2) Ardizzone, S; Adv Colloid Interf Sci 1996, V64, P173 HCAPLUS
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     Processing 1989, P503
  (5) Ciesla, U; Micropor Mesapor Mater 1999, V27, P131 HCAPLUS
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L65 ANSWER 9 OF 35 HCAPLUS COPYRIGHT ACS on STN
     2000:537224 HCAPLUS
AN
     133:257167
DN
     Entered STN: 06 Aug 2000
ED
     Chemical and biological applications of porous silicon technology
ΤI
     Stewart, Michael P.; Buriak, Jillian M.
ΑU
     Department of Chemistry, Purdue University, West Lafayette, IN,
CS
     47907-1393, USA
     Advanced Materials (Weinheim, Germany) (2000), 12(12), 859-869
SO
     CODEN: ADVMEW; ISSN: 0935-9648
     Wiley-VCH Verlag GmbH
PB
     Journal; General Review
DT
LA
     English
     66-0 (Surface Chemistry and Colloids)
CC
     Section cross-reference(s): 6, 9, 76
     A review with 59 refs. describing some wet applications of porous silicon, including bio- and
AΒ
      chemical sensing, mass spectrometry, new material supports, m biocompatible materials, and in-
      vivo electronics. Topic discussed include: the architecture of porous silicon; the porous
      silicon technol. in silicon lithog.; sensing in chemical and biol. systems; porous silicon as
      support for chemical applications such as catalytic growth of carbon nanotubes; and porous
      silicon as support for biochem. reactions and proteomics.
     review porous silicon technol chem biol application
ST
IT
     Catalyst supports
     Lithography
     Porous materials
       Sensors
     Surface structure
         (chemical and biol. applications of porous silicon technol.)
      Functional groups
         (surface; chemical and biol. applications of porous silicon technol.)
     7440-21-3, Silicon, uses
TT
      RL: TEM (Technical or engineered material use); USES (Uses)
         (porous; chemical and biol. applications of porous silicon technol.)
               THERE ARE 82 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
RE
 (1) Allen, M; J Lumin 1999, V80, P29
 (2) Anderson, R; J Electrochem Soc 1993, V149, P1393
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 (8) Bateman, J; Angew Chem Int Ed 1998, V37, P2683 HCAPLUS
 (9) Bayliss, S; Adv Mater 1999, V11, P318 HCAPLUS
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 (18) Buriak, J; J Am Chem Soc 1998, V120, P1339 HCAPLUS
 (19) Buriak, J; J Am Chem Soc 1999, V121, P11491 HCAPLUS
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  (21) Canham, L; Adv Mater 1999, V11, P1505 HCAPLUS
  (22) Canham, L; Appl Phys Lett 1990, V57, P1049
  (23) Cullis, A; J Appl Phys 1997, V82, P909 HCAPLUS
 (24) Curtis, C; J Electrochem Soc 1993, V140, P3492 HCAPLUS
  (25) Dancil, K; J Am Chem Soc 1999, V121, P7925 HCAPLUS
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#### L65 ANSWER 10 OF 35 HCAPLUS COPYRIGHT ACS on STN 2000:535209 HCAPLUS AN 133:136801 DN Entered STN: 04 Aug 2000 Fabrication of conductive/non-conductive nanocomposites by laser Chrisey, Douglas B.; McGill, R. Andrew; Pique, Alberto IN United States Dept. of the Navy, USA PA DATE PATENT NO. KIND DATE APPLICATION NO. \_\_\_\_ WO 2000-US1650 20000127 <--20000803 WO 2000044822 A2 20000127 <--AU 2000-25149 Α5 20000818 AU 2000025149 P 19990127 PRAI US 1999-117467P 20000127 <--W WO 2000-US1650 A composite layer of a sorbent, chemoselective, non-elec.-conducting polymer and nano-AB particles of an elec. conducting material dispersed throughout the polymer is formed on a substrate by pulsed laser deposition, matrix assisted pulsed laser evaporation or matrix assisted pulsed laser evaporation direct writing. The process is useful in preparation of chemical sensors. Nanotubes IT RL: TEM (Technical or engineered material use); USES (Uses) (carbon; fabrication of conductive/non-conductive nanocomposites by laser evaporation) Vapor deposition process IT (chemical, laser-assisted, pulsed; fabrication of conductive/nonconductive nanocomposites by laser evaporation) IT Sensors Sorbents (fabrication of conductive/non-conductive nanocomposites by laser evaporation) TΤ Fullerenes RL: TEM (Technical or engineered material use); USES (Uses) (fabrication of conductive/non-conductive nanocomposites by laser evaporation) ΙT Metals, uses RL: TEM (Technical or engineered material use); USES (Uses) (nanoparticles; fabrication of conductive/non-conductive nanocomposites by laser evaporation) 24969-06-0, Polyepichlorohydrin IT RL: POF (Polymer in formulation); TEM (Technical or engineered material

(fabrication of conductive/non-conductive nanocomposites by laser

(particles; fabrication of conductive/non-conductive nanocomposites by

RL: TEM (Technical or engineered material use); USES (Uses)

use); USES (Uses)

evaporation)

TΤ

7782-42-5, Graphite, uses

laser evaporation)

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L65 ANSWER 11 OF 35 HCAPLUS COPYRIGHT ACS ON STN
     2000:460961 HCAPLUS
AN
     133:142702
DN
     Entered STN: 09 Jul 2000
ED
ΤI
     Controlling nanotube growth
ΑU
     Dai, Hongjie
     Department of Chemistry, Stanford University, Stanford, CA, 94305, USA
CS
     Physics World (2000), 13(6), 43-47
SO
     CODEN: PHWOEW; ISSN: 0953-8585
     Institute of Physics Publishing
PB
     Journal; General Review
DT
LA
     English
     75-0 (Crystallography and Liquid Crystals)
CC
     Section cross-reference(s): 76, 79
     A review with 5 refs. about C nanotubes from their 1st observation in 1991 to the growth of
AB
     perfect single walled species by CVD. Their elec. properties are described and advantages for
     nanoelectromech. devices and chemical sensors are outlined.
     review carbon nanotube CVD controlled growth; elec electromech
ST
     property carbon nanotube CVD review; chem
     sensor carbon nanotube CVD review
     Nanotubes
IT
     RL: ARU (Analytical role, unclassified); DEV (Device component use); PEP
     (Physical, engineering or chemical process); PRP (Properties); ANST
     (Analytical study); PROC (Process); USES (Uses)
        (carbon; controlling C nanotube growth by CVD, elec.
        characteristics, and applications as electromech devices and
        chemical sensors)
     Vapor deposition process
ΙT
         (chemical; controlling C nanotube growth by CVD, elec.
        characteristics, and applications as electromech devices and
        chemical sensors)
     Electric properties
TT
     Electromechanical effect
     Gas sensors
         (controlling C nanotube growth by CVD, elec. characteristics,
```

and applications as electromech devices and chemical

sensors)

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L32 ANSWER 23 OF 82 HCAPLUS COPYRIGHT ACS on STN
     2000:510956 HCAPLUS
ΑN
     133:213412
DN
     Entered STN: 28 Jul 2000
ED
     Electronic structures of atomic wires on a H-terminated Si(100) surface
ΤI
     Suwa, Yuji; Yajima, Akio; Tsukada, Masaru; Watanabe, Satoshi; Ichimura,
AU
     Masahiko; Onogi, Toshiyuki; Hashizume, Tomihiro
     Advanced Research Laboratory, Hitachi, Ltd., Saitama, 350-0395, Japan
CS
     Transactions of the Materials Research Society of Japan (1999), 24(2),
SO
     213-216
     CODEN: TMRJE3; ISSN: 1382-3469
     Materials Research Society of Japan
      We theor. predict the atomic and electronic structures of Ga, Al, and As atomic wires, which
PΒ
      are chemical bound to a dangling-bond wire on a H-terminated Si(100) surface, via first-
      principles calcns. within the local-d.-functional approach. We show the chemical trend and
      carrier-doping effect in the conducting properties of the atomic wires, sensitively depending
      on the different species and concentration of adsorbed atoms. As an intriguing byproduct, we
      found that the As-wire has an unusually flat (dispersion-less) energy band, where the flat
      band can be half-filled by electron-doping. According to so-called "flat-band ferromagnetism"
      theory, we show a novel possibility to create ferromagnetic nanowires, which are made up only
      of nonmagnetic atoms.
      electronic structure atomic wire hydrogen terminated silicon surface calcn
 ST
      Adsorbed substances
      Band structure
      Conduction electrons
      Electric conductivity
      Electron density
      Ferromagnetism
      Local density approximation
      Nanostructures
        Nanowires (metallic)
      Surface structure
         (electronic structures of atomic wires on a H-terminated Si(100) surface
         studied theor.)
      7440-21-3, Silicon, properties
 IT
      RL: MSC (Miscellaneous); PRP (Properties)
         (hydrogen-terminated silicon surface; electronic structures of atomic
         wires on a H-terminated Si(100) surface studied theor.)
      7429-90-5, Aluminum, properties
                                         7440-38-2, Arsenic, properties
      7440-55-3, Gallium, properties
      RL: MSC (Miscellaneous); PRP (Properties)
          (nanowire; electronic structures of atomic wires on a
         H-terminated Si(100) surface studied theor.)
                THERE ARE 18 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT 18
 RE
  (1) Anon; Proceedings of the NATO Advanced Research Workshop on Atomic and
      Molecular Wires 1997
  (2) Anon; Proceedings of the NATO Advanced Research Workshop on Nanowires 1997
  (3) Arita, R; Phys Rev B 1998, V57, PR6854 HCAPLUS
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  (6) Haye, M; Phys Rev B 1997, V56, PR1708 HCAPLUS
  (7) Hosoki, S; Appl Surf Sci 1992, V60/61, P643
  (8) Huang, D; J Vac Sci Technol 1994, VB12, P2429
  (9) Ichimura, M; Phys Rev B 1998, V58, P9595 HCAPLUS
  (10) Laasonen, K; Phys Rev B 1993, V47, P10142 HCAPLUS
  (11) Mielke, A; Commun Math Phys 1993, V158, P341
  (12) Shen, T; Phys Rev Lett 1997, V78, P1271 HCAPLUS
  (13) Tasaki, H; Prog Theor Phys 1998, V99, P489 HCAPLUS
  (14) Vanderbilt, D; Phys Rev B 1990, V41, P7892
  (15) Watanabe, S; Jpn J Appl Phys 1997, V36, PL929 HCAPLUS
  (16) Watanabe, S; Phys Rev B 1996, V54, PR17308
   (17) Yajima, A; Ph D thesis (Univ of Tokyo) 1998
   (18) Yajima, A; submitted to Phys Rev B
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L19 ANSWER 3 OF 5 HCAPLUS COPYRIGHT ACS on STN
     2000:400461 HCAPLUS
AN
     133:204907
DN
     Entered STN: 16 Jun 2000
ED
     Detection of the absorption of glucose molecules by living cells using
     atomic force microscopy
     de Souza Pereira, R.
ΑU
     Institute of Biomedical Sciences (ICB), Departamento de Parasitologia,
CS
     Universidade de Sao Paulo (USP), Sao Paulo, 05508-900, Brazil
     FEBS Letters (2000), 475(1), 43-46
SO
     CODEN: FEBLAL; ISSN: 0014-5793
PB
     Elsevier Science B.V.
     Journal
DΤ
LA
     English
     9-4 (Biochemical Methods)
CC
     Section cross-reference(s): 6, 7, 10
     A very small electrode (nanobiosensor) was constructed by immobilizing enzyme (glucose oxidase
AB
     or hexokinase) on the surface of the cantilever of the atomic force microscope in order to
      detect the absorption of glucose mols. by living cells. If glucose is present, the
     nanobiosensor deflects, probably due to the reaction heat evolved in the process.
     Nanobiosensors built with inactivated enzyme or cantilevers without immobilized enzyme were
      not capable of producing this type of signal (deflection). This technique will be very useful
      in detecting the passage of specific mols. through a cell wall (or a cell membrane for other
      types of cells).
     glucose absorption cell Saccharomyces atomic force microscopy enzyme
ST
     immobilization
IT
     Absorption
     Atomic force microscopy
     Biological transport
     Cantilevers (components)
     Cell
     Saccharomyces cerevisiae
         (detection of absorption of glucose mols. by living cells using atomic
         force microscopy)
     Immobilization, biochemical
IT
         (enzyme; detection of absorption of glucose mols. by living cells using
         atomic force microscopy)
     Biosensors
IT
         (nanobiosensor; detection of absorption of glucose mols. by
         living cells using atomic force microscopy)
      50-99-7, D-Glucose, analysis
IT
      RL: ANT (Analyte); BPR (Biological process); BSU (Biological study,
      unclassified); PEP (Physical, engineering or chemical process); ANST
      (Analytical study); BIOL (Biological study); PROC (Process)
         (detection of absorption of glucose mols. by living cells using atomic
         force microscopy)
                                  9001-51-8, Hexokinase
      9001-37-0, Glucose oxidase
 IT
      RL: ARU (Analytical role, unclassified); BAC (Biological activity or
      effector, except adverse); BPR (Biological process); BSU (Biological
      study, unclassified); DEV (Device component use); PEP (Physical,
      engineering or chemical process); ANST (Analytical study); BIOL
      (Biological study); PROC (Process); USES (Uses)
         (detection of absorption of glucose mols. by living cells using atomic
         force microscopy)
               THERE ARE 24 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT
 (1) Binning, G; Phys Rev Lett 1986, V56, P930
 (2) Brady, D; Biotechnol Bioeng 1994, V44, P297 HCAPLUS
 (3) Brady, D; Enzyme Microb Technol 1994, V16, P633 HCAPLUS
 (4) Brady, D; Lett Appl Microbiol 1994, V18, P245 HCAPLUS
 (5) Csuk, R; Chem Rev 1991, V91, P49 HCAPLUS
 (6) Dziezak, J; Food Technol 1987, V41, P104
 (7) Ikeda, T; J Electroanal Chem 1993, V361, P221 HCAPLUS
 (8) Mogren, H; Physiol Plant 1973, V29, P82 HCAPLUS
 (9) Pereira, R; Appl Biochem Biotechnol 1995, V55, P123 HCAPLUS
 (10) Pereira, R; Appl Biochem Biotechnol 1996, V59, P135 HCAPLUS
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ANSWER 6 OF 10 HCAPLUS COPYRIGHT ACS on STN
L58
AN
     2000:344067 HCAPLUS
     132:345119
DN
    Entered STN: 24 May 2000
ED
    Multi-array, multi-specific electrochemiluminescence testing
     Wohlstadter, Jacob N.; Wilbur, James; Sigal, George; Martin, Mark; Guo,
IN
     Liang-hong; Fischer, Alan; Leland, Jon
     Meso Scale Technologies, LLC, USA
PA:
                                                                 DATE
                                          APPLICATION NO.
                               DATE
     PATENT NO.
                       KIND
                                          _____
                               _____
                        ____
                                                                 19960306 <--
                                          US 1996-611804
                       A
                               20000523
     US 6066448
PΙ
                                                                 19960306 <--
                       AA
                               19960919
                                          CA 1996-2213854
     CA 2213854
                                                                 19960306 <--
                        Α
                                          CN 1996-193840
                               19980701
     CN 1186513
                                                                 19960306 <--
                                          TW 1996-85102864
                               20031001
     TW 555852
                        B
                                                                 19960308 <--
                                          ZA 1996-1925
     ZA 9601925
                        Α
                               19970805
                               20010327 US 1996-715163
                                                                19960917 <--
                        В1
     US 6207369
                               20001031
                                          US 1997-814085
                                                                 19970306 <--
                        Α
     US 6140045
                                                                 19970917 <--
                        В1
                             20040106
                                          US 1997-932110
     US 6673533
                                                                 20010129 <--
                                           US 2001-771796
                       A1
                              20010913
     US 2001021534
                                                                 20031024 <--
                                         US 2003-693441
                              20040506
     US 2004086423
                        A1
                       A2 19950310 <--
PRAI US 1995-402076
                       A2 19950310 <--
     US 1995-402277
                              19960306 <--
     US 1996-12957P
                        P
                             19960306 <--
                        A2
     US 1996-611804
                        A2
                               19960917 <--
     US 1996-715163
                               19970917 <--
                         A3
     US 1997-932110
     Materials and methods are provided for producing patterned multi-array, multi-sp. surfaces
AΒ
      which are electronically excited for use in electrochemiluminescence based tests. Materials
      and methods are provided for the chemical and/or phys. control of conducting domains and
      reagent deposition for use in flat panel displays and multiply specific testing procedures.
      Anti-prostate specific antigen (PSA) antibody immobilized on a patterned gold electrode
      (preparation given) was used as an electrochemiluminescent sensor for immunoassay of PSA in
      serum samples.
     Electric conductors
     Electric insulators
       Semiconductor materials
         (as supports; patterned multi-array, multi-sp. surfaces and porous,
        conductive electrodes for electrochemiluminescence binding assays)
IT
     Matrix media
         (containing carbon nanotubes or carbon black, as electrode;
        patterned multi-array, multi-sp. surfaces and porous, conductive
         electrodes for electrochemiluminescence binding assays)
 IT
     Fibril
         (electrodes; patterned multi-array, multi-sp. surfaces and porous,
         conductive electrodes for electrochemiluminescence binding assays)
 ΙT
         (immunol., optical; patterned multi-array, multi-sp. surfaces and
         porous, conductive electrodes for electrochemiluminescence binding
         assays)
 IT
      Biosensors
         (immunosensors, optical; patterned multi-array, multi-sp. surfaces and
         porous, conductive electrodes for electrochemiluminescence binding
         assays)
      Avidins
 TT
      Antibodies
 ΙT
      Nucleic acids
 IT
      Prostate-specific antigen
```

Carcinoembryonic antigen

α-Fetoproteins

IT

- L32 ANSWER 33 OF 82 HCAPLUS COPYRIGHT ACS on STN
- 2000:330483 HCAPLUS ΑN
- Entered STN: 19 May 2000 ED
- Nanomaterials: Evolving applications in membranes, energy production, and ТI analytical chemistry.
- Martin, Charles R. ΑU
- Department of Chemistry, University of Florida, Gainesville, FL, 32611, CS
- Book of Abstracts, 219th ACS National Meeting, San Francisco, CA, March 26-30, 2000 (2000), IEC-027 Publisher: American Chemical Society, SO Washington, D. C.
  - CODEN: 69CLAC
- Conference; Meeting Abstract DT
- English
- Nanomaterials constitute one of the most exciting new frontiers in the materals sciences. We LA have been exploring a general method for preparing nanomaterials called "template synthesis," AB which entails synthesizing nanoscopic particles of the desired material within the pores of a microporous membrane or other solid. Monodisperse nanowires, nanofibrils or nanotubules of the desired material are obtained. In addition to exploring the fundamental phys. and chemical properties of these nanoparticles, we are developing a variety of applications. This talk will review possible new applications in membranes for sensors and chemical sepns. and in electrochem. energy storage and production

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ANSWER 1 OF 4 HCAPLUS COPYRIGHT ACS on STN
L56
                                          Entered STN: 26 Apr 2000
                         133:86360 ED
     2000:270322 DN
AN
     Carbon nanotube atomic force microscopy tips: direct growth by
ΤI
     chemical vapor deposition and application to high-resolution imaging
     Cheung, Chin Li; Hafner, Jason H.; Lieber, Charles M.
AU
     Department of Chemistry and Chemical Biology, Harvard University,
CS
     Cambridge, MA, M02138, USA
     Proceedings of the National Academy of Sciences of the United States of
so
     America (2000), 97(8), 3809-3813
     CODEN: PNASA6; ISSN: 0027-8424
     National Academy of Sciences
PB
      Carbon nanotubes are potentially ideal atomic force microscopy probes because they can have
AB
      diams. as small as one nanometer, have robust mech. properties, and can be specifically
      functionalized with chem . and biol. probes at the tip ends. This communication describes
      methods for the direct growth of carbon nanotube tips by chemical vapor deposition (CVD) using
      ethylene and iron catalysts deposited on com. silicon-cantilever-tip assemblies. SEM and TEM
      measurements demonstrate that multiwalled nanotube and single-walled nanotube tips can be
      grown by predictable variations in the CVD growth conditions. Force-displacement measurements
      made on the tips show that they buckle elastically and have very small (≤ 100 pN) nonspecific
      adhesion on mica surfaces in air. Anal. of images recorded on gold nanoparticle stds. shows
      that these multi- and single-walled carbon nanotube tips have radii of curvature of 3-6 and 2-
      4 nm, resp. Moreover, the nanotube tip radii determined from the nanoparticle images are
      consistent with those determined directly by TEM imaging of the nanotube ends. These mol.-
      scale CVD nanotube probes have been used to image isolated IgG and GroES proteins at high-
      resolution
     Immunoglobulins
TT
         (G; direct growth of carbon nanotubes by chemical vapor
        deposition and application as high-resolution atomic force microscopy tips)
TT
     Chaperonins
         (GroES; direct growth of carbon nanotubes by chemical vapor
        deposition and application as high-resolution atomic force microscopy tips)
     Nanotubes
IT
         (carbon; direct growth of carbon nanotubes by chemical vapor
        deposition and application as high-resolution atomic force microscopy tips)
     7440-21-3, Silicon, uses
 IΤ
         (direct growth of carbon nanotubes by chemical vapor deposition
        and application as high-resolution atomic force microscopy tips)
              THERE ARE 38 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT
 (1) Akama, Y; J Vac Sci Technol A 1990, V8, P429 HCAPLUS
 (2) Bustamante, C; Biochemistry 1992, V31, P22 HCAPLUS
 (3) Bustamante, C; Curr Opin Struct Biol 1993, V3, P363 HCAPLUS
 (4) Bustamante, C; Curr Opin Struct Biol 1997, V7, P709 HCAPLUS
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 (15) Hansma, H; J Struct Biol 1997, V119, P99 HCAPLUS
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 (28) Noy, A; Langmuir 1998, V14, P1508 HCAPLUS
 (29) Perkins, S; J Mol Biol 1991, V221, P1345 HCAPLUS
  (30) Shao, Z; Adv Phys 1996, V45, P1 HCAPLUS
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(31) Sigler, P; Annu Rev Biochem 1998, V67, P581 HCAPLUS

- L64 ANSWER 3 OF 5 HCAPLUS COPYRIGHT ACS on STN
- AN 2000:212317 HCAPLUS
- ED Entered STN: 03 Apr 2000
- TI Analytical currents: nanotubes as chemical sensors
- AU Anon.
- SO Analytical Chemistry (2000), 72(7), 256A CODEN: ANCHAM; ISSN: 0003-2700
- PB American Chemical Society
- DT Journal; News Announcement
- LA English
- AB Unavailable

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L58 ANSWER 7 OF 10 HCAPLUS COPYRIGHT ACS on STN
     2000:181722 HCAPLUS
     132:272099
     Entered STN: 22 Mar 2000
TΤ
     Extreme oxygen sensitivity of electronic properties of carbon
ΑIJ
     Collins, Philip G.; Bradley, Ketih; Ishigami, Masa; Zettl, A.
CS
     Dep. Physics, Univ. California Berkeley, Berkeley, CA, 94720, USA
     Science (Washington, D. C.) (2000), 287(5459), 1801-1804
SO
     CODEN: SCIEAS; ISSN: 0036-8075
PB
     American Association for the Advancement of Science
DT
     Journal
LA
     English
     76-1 (Electric Phenomena)
CC
     Section cross-reference(s): 65, 66
     The electronic properties of single-walled carbon nanotubes are shown here to be extremely
AB
     sensitive to the chemical environment. Exposure to air or oxygen dramatically influences the
     nanotubes' elec. resistance, thermoelec. power, and local d. of states, as determined by
      transport measurements and scanning tunneling spectroscopy. These electronic parameters can
     be reversibly "tuned" by surprisingly small concns. of adsorbed gases, and an apparently
      semiconducting nanotube can be converted into an apparent metal through such exposure. These
      results, although demonstrating that nanotubes could find use as sensitive chemical gas
      sensors, likewise indicate that many supposedly intrinsic properties measured on as-prepared
     nanotubes may be severely compromised by extrinsic air exposure effects.
     air oxygen sensitivity electronic property carbon nanotube;
ST
     resistivity thermoelec power carbon nanotube sensitivity oxygen
     air; transport electronic property carbon nanotube sensitivity
     oxygen air; density state carbon nanotube sensitivity oxygen air
IT
     Nanotubes
     RL: PEP (Physical, engineering or chemical process); PRP (Properties);
     PROC (Process)
        (carbon; extreme air and oxygen sensitivity of electronic properties of
        carbon nanotubes)
IT
     Adsorbed substances
     Band gap
     Density of states
     Electric resistance
        (extreme air and oxygen sensitivity of electronic properties of carbon
        nanotubes)
IT
     Electron tunneling spectroscopy
        (scanning; extreme air and oxygen sensitivity of electronic properties
        of carbon nanotubes)
ΙT
     Power
        (thermoelec.; extreme air and oxygen sensitivity of electronic
        properties of carbon nanotubes)
                                    7782-44-7, Oxygen, properties
     7440-37-1, Argon, properties
TT
     RL: PEP (Physical, engineering or chemical process); PRP (Properties);
     PROC (Process)
        (extreme air and oxygen sensitivity of electronic properties of carbon
        nanotubes)
              THERE ARE 27 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT 27
RE
(1) Ahn, C; Appl Phys Lett 1998, V73, P3378 HCAPLUS
(2) Anon; Graphite Intercalation Compounds 2 1992, V18
(3) Ayappa, K; Langmuir 1998, V14, P880 HCAPLUS
 (4) Bockrath, M; Science 1997, V275, P1922 HCAPLUS
 (5) Britto, P; Adv Mater 1999, V11, P154 HCAPLUS
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 (7) Collins, P; Bull Am Phys Soc 1999, V44, P1889
 (8) Collins, P; in preparation
 (9) Dillon, A; Nature 1997, V386, P377 HCAPLUS
 (10) Dresselhaus, M; Science of Fullerenes and Carbon Nanotubes 1996
 (11) Grigorian, L; Phys Rev B 1999, V60, PR11309 HCAPLUS
 (12) Hamada, N; Phys Rev Lett 1992, V68, P1579 HCAPLUS
 (13) Hone, J; Phys Rev Lett 1998, V80, P1042 HCAPLUS
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L62 ANSWER 7 OF 14 HCAPLUS COPYRIGHT ACS on STN
     1999:723270 HCAPLUS
AN
     131:334353
DN
     Entered STN: 12 Nov 1999
ED
     Method for immobilizing and/or crystallizing biological macromolecules on
     carbon nanotubes, and applications
     Balavoine, Fabrice; Mioskowski, Charles; Schultz, Patrick; Richard,
IN
     Commissariat a l'Energie Atomique, Fr.; Centre National de la Recherche
PΑ
     Scientifique-CNRS
                                            APPLICATION NO.
                         KIND
                                DATE
     PATENT NO.
                                _____
                         ____
                                                                   19990507 <---
                                            WO 1999-FR1086
                                19991111
                          A1
     WO 9957564
PΙ
                                                                   19980525
                                            FR 1998-6539
                          A 1
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     FR 2778846
                                20010511
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     FR 2778846
                                                                   19990507 <--
                                            AU 1999-35292
                                19991123
                          Α1
     AU 9935292
                                                                   19990507 <--
                                            EP 1999-917007
     EP 1078261
                          Α1
                                20010228
                                20041027
     EP 1078261
                          В1
         R: DE, FR, GB, NL
                                                                   19990507 <--
                                20020514
                                            JP 2000-547479
                          Т2
     JP 2002513815
                                                                   20001201 <--
                                            US 2000-673668
                          В1
                                20031202
     US 6656712
                                                                   20030715 <--
                                            US 2003-618586
                                20040129
     US 2004018543
                         A1
                                19980507 <--
                         Α
PRAI EP 1998-401114
                                19980525 <--
     FR 1998-6539
                          Α
                                19990507 <--
     WO 1999-FR1086
                          W
                                20001201 <--
                          A3
     US 2000-673668
      The invention concerns the immobilization, and crystallization of biol. macromols. via self
AB
      assembly on carbon multiwall nanotubes (MWNT) by adding the macromols. to the solution that
      contains the closed end MWNT and incubating for 15 min without stirring or agitation at
      optimal conditions. Macromols. are soluble proteins, membrane and transmembrane proteins,
      enzymes, antibodies, antibody fragments, or nucleic acids. The carbon nanotubes are
      functionalized by the phys. adsorption of linkers that are of the general formula H-E-L. H
      represents a hydrophile group; with pos. or neg. charge; an analog of the biomol., a metal
      complex, e.g. Ni-NTA, Cu-IDA; the group contains a binding site to the spacer arm E. E spacer
      arm is a C1-C10 mol.; the chain can contain a phosphate group; the end group can be N, O, S
      containing L is a lipid with multiple chains, C12-C20 saturated or non-saturated; five or six
      member aromatic ring with substituents. The synthesis of a biotinylated ethoxy-anthracene-
      acetamide linker is described. The immobilized biomols. are used for structure studies, as
      receptors and bioconductors for biosensors.
 IT
      Nanotubes
      RL: PEP (Physical, engineering or chemical process); PRP (Properties);
      PROC (Process)
         (carbon; method for immobilizing and/or crystallizing biol. macromols. on
         carbon nanotubes, and applications)
      Immunoglobulins
 IT
      RL: PEP (Physical, engineering or chemical process); PRP (Properties);
      PROC (Process)
         (fragments; method for immobilizing and/or crystallizing biol. macromols. on
         carbon nanotubes, and applications)
      Proteins, specific or class
 IT
      RL: PEP (Physical, engineering or chemical process); PRP (Properties);
         (membrane; method for immobilizing and/or crystallizing biol. macromols. on
         carbon nanotubes, and applications)
      Biosensors
 TT
          (method for immobilizing and/or crystallizing biol. macromols. on carbon
         nanotubes, and applications)
      Antibodies
 IT:
      Enzymes, properties
      Nucleic acids
         (method for immobilizing and/or crystallizing biol. macromols. on carbon
         nanotubes, and applications)
```

(protein; method for immobilizing and/or crystallizing biol. macromols. on

TT

IT

Adsorption

carbon nanotubes, and applications)

Proteins, specific or class

## L32 ANSWER 43 OF 82 HCAPLUS COPYRIGHT ACS on STN

- AN 1999:690005 HCAPLUS
- DN 132:29170
- ED Entered STN: 29 Oct 1999
- TI Electronic properties and adsorption **sensitivity** of thin CdSe films with modified surface
- AU Vashpanov, Yu. A.
- CS Mechnikov Odesa State University, Odesa, 270026, Ukraine
- SO Ukrains'kii Fizichnii Zhurnal (1999), 44(8), 1017-1021 CODEN: UFZHFY; ISSN: 0372-400X
- PB Natsional'na Akademiya Nauk Ukraini, Viddilennya Fiziki i Astronomii
- DT Journal
- LA Ukrainian
- CC 76-2 (Electric Phenomena)
   Section cross-reference(s): 66
- The electronic properties and adsorption sensitivity to oxygen of thin semiconductor films of cadmium selenide whose surface is doped by atoms of indium and selenium are investigated. Reduction of the bond energy of oxygen with the surface of material Eta and occurrence of adsorption sensitivity at room temperature are found. The samples contain characteristic nanowires of In and Se atoms on their surface. The phys. mechanism of reduction of the parameter Eta is connected with the electrostatic interaction of charges on the surface of nanowires.

2/9/10
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0012084889 BIOSIS NO.: 199900344549

Fullerene nanotubes for molecular electronics

AUTHOR: Colbert Daniel T (Reprint); Smalley Richard E (Reprint) AUTHOR ADDRESS: Center for Nanoscale Science and Technology, Rice

University, Houston, TX, 77251, USA\*\*USA

JOURNAL: Trends in Biotechnology 17 (2): p46-50 Feb., 1999 1999

MEDIUM: print ISSN: 0167-7799

DOCUMENT TYPE: Article RECORD TYPE: Abstract LANGUAGE: English

ABSTRACT: Fullerene nanotubes hold tremendous promise for numerous applications, owing to their remarkable properties, including strength, toughness, chemical robustness, thermal conductivity and, perhaps most interestingly, electrical conductivity. Depending on their precise molecular symmetry, some nanotubes are semiconducting, while others exhibit truly metallic conductivity. This behaviour, coupled with their nanoscale geometry, makes them ideal, perhaps unique, candidates for wires, interconnects and even devices for true molecular electronics. DESCRIPTORS:

MAJOR CONCEPTS: Equipment, Apparatus, Devices and Instrumentation

METHODS & EQUIPMENT: fullerene nanotubes--chemical robustness, electrical conductivity, strength, thermal conductivity, equipment,

toughness; interconnects--equipment; molecular electronic devices--

equipment; wires--equipment

MISCELLANEOUS TERMS: metallic conductivity; semiconducting

CONCEPT CODES:

10502 Biophysics - General

10060 Biochemistry studies - General

00532 General biology - Miscellaneous

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L32 ANSWER 45 OF 82 HCAPLUS COPYRIGHT ACS on STN
     1999:601797 HCAPLUS
AN
DN
     131:315997
ΕD
     Entered STN: 23 Sep 1999
TI
     In-situ studies of the formation of Ga and Al wires on Si(112) facet
     surfaces
ΔIJ
     Prokes, S. M.; Glembocki, O. J.
CS
     Naval Research Laboratory, Washington, DC, 20375-5347, USA
     Materials Research Society Symposium Proceedings (1999), 570 (Epitaxial
SO
     Growth--Principles and Applications), 117-127
     CODEN: MRSPDH; ISSN: 0272-9172
PB
     Materials Research Society
DT
     Journal
     English
LA
CC
     75-1 (Crystallography and Liquid Crystals)
     Section cross-reference(s): 76
     Reflectance difference anisotropy (RDA) and LEED were used to study the formation of Ga or Al
AB
     chains and nanowires on the Si(112) surface. At T > 350^{\circ}, the Ga or Al chains form at the
     step edges by a self-limiting process, while at lower temps., Ga or Al nanowires form on the
      terraces in addition to the chains on the ledges. The process was tracked in real time from
      the rapid change of the (2+1) Si(112) reconstruction under sub-critical coverage to chain
      formation leading to a 5+1 reconstruction followed by a 6+1 reconstruction1. During
     sequential deposition of Ga and Al, the authors observe (in RDA and AES) that Ga atoms forming
     the chains can be replaced by Al, indicating a stronger Al-Si bond strength and confirming the
     chemical sensitivity of the light scattering in RDA. Low temperature depositions (in the 300°
     range) give Al (or Ga) metallic wires on the Si(111) terraces. Continued deposition of <10
     monolayers at T <250° leads to a very anisotropic but patterned Al or Ga structure in registry
     with the substrate which retains an unexpectedly large polarizability for coverages as thick
     as 40 mL.
ST
     formation gallium aluminum wire silicon facet surface
IT
     Bond energy
        (Al-Si and Ga-Si bond strength in formation of gallium and aluminum
        wires on Si(112) facet surfaces)
IT
     7429-90-5, Aluminum, properties
                                       7440-21-3, Silicon, properties
     7440-55-3, Gallium, properties
     RL: PEP (Physical, engineering or chemical process); PRP (Properties);
     PROC (Process)
```

(In-situ studies of formation of Ga and Al wires on Si(112) facet

(4) Good, R; Classical Theory of Electric and Magnetic Fields 1971, P512

(10) Prokes, S; Materials Research Society Symposium Proceedings 1997, V448,

THERE ARE 13 CITED REFERENCES AVAILABLE FOR THIS RECORD

surfaces) -

P217 HCAPLUS

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(5) Hill, I; Phys Rev B 1997, V56, P15725 HCAPLUS (6) Jung, T; J Vac Sci Technol 1994, VA12, P1838 (7) Jung, T; Surf Sci Lett 1993, V289, PL577 HCAPLUS (8) Petroff, P; Ultramicroscopy 1989, V31, P67 HCAPLUS (9) Prokes, S; J Vacuum Sci and Technol B submitted

(11) Sanderson, R; Polar Covalence 1983, P40

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(3) Glembocki, O; Appl Phys Lett 1997, V71, P2355 HCAPLUS

(12) Sung, K; J Electrochem Soc 1995, V142, P206 HCAPLUS

(2) Baski, A; Surface Science submitted

RE.CNT 13

RE

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L65 ANSWER 13 OF 35 HCAPLUS COPYRIGHT ACS on STN
    1999:567603 HCAPLUS
AN
     131:239884
DN
     Entered STN: 09 Sep 1999
ED
     Carbon nanotube tips as nanometer scale probes for
ΤI
     chemistry and biology
     Wong, Stanislaus Sherwood
ΑU
     Harvard Univ., Cambridge, MA, USA
CS
     (1999) 200 pp. Avail.: UMI, Order No. DA9921544
SO
     From: Diss. Abstr. Int., B 1999, 60(3), 1107
DT
     Dissertation
LA
     English
     9-1 (Biochemical Methods)
CC
     Section cross-reference(s): 6, 66
     Unavailable
ΑB
     carbon nanotube tip nanometer scale probe chem
ST
     biol
ΙT
     Atomic force microscopy
     Imaging
        (carbon nanotube tips as nanometer scale probes for
        chemical and biol.)
ΙT
     Nanotubes
     RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST
      (Analytical study); USES (Uses)
        (carbon; carbon nanotube tips as nanometer scale
        probes for chemical and biol.)
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## Carbon nanotube tips as nanometer-scale probes for chemistry and biology.

by Wong, Stanislaus Sherwood, Ph.D., Harvard University, 1999, 200 pages; AAT 9921544

Advisor:

Lieber, Charles M.

School:

Harvard University

School Location:

United States - Massachusetts

Index terms(keywords): Carbon, Probes, Amyloid fibrils, pH, Atomic force microscopy, Nanotube tips, Nanometer-scale

Source:

DAI-B 60/03, p. 1107, Sep 1999

Source type:

DISSERTATION

Subjects:

Chemistry, Analytical chemistry, Cellular biology

**Publication Number:** 

AAT 9921544

ISRN:

0599207647

Document URL:

http://proquest.umi.com/pqdweb?did=733939331&sid=6&Fmt=2&cli entId=19649&RQT=309&VName=PQD

ProQuest document ID: 733939331

## Abstract (Document Summary)

Of an intrinsic structural beauty, carbon nanotubes (NTs) consist of concentrically nested shells of sp <sup>2</sup> -hybridized (trivalent) carbon atoms forming a hexagonal network that is itself arranged helically within the tubular motif. Synthesized and purified NTs represent an ideal structure for the probe tips used in many scanning probe microscopies, such as atomic force +microscopy (AFM). In addition to the high aspect ratio of NTs, which allows for probing deep crevices, their unique ability to buckle elastically makes these tips very robust while limiting the maximum force applied to delicate organic and biological samples. Both multi wall (MWNT) and single-wall (SWNT) carbon nanotubes have been attached to the ends of single crystal silicon cantilever-tip assemblies.

Initial imaging studies have addressed their potential to improve lateral resolution as well as to probe biological systems. Amyloid [Special characters omitted.] (1-40) derived protofibrils and fibrils, implicated in Alzheimer's disease, have been imaged with MWNT tips, yielding a 12-30% improvement in lateral resolution, compared with conventional Si tips. With SWNT tips, the improvement in resolution is 70% for imaging amyloid and double-stranded DNA. Moreover, SWNT tips have been used to resolve substructure within dispersed SWNTs on surfaces. Because individual SWNTs have radii of 0.5-0.7 nm, strategies for achieving molecularresolution imaging are discussed.

Both MWNT and SWNT tips have been chemically modified to present acidic, basic, and hydrophobic functionality. Force titrations recorded between these NT tips and hydroxy-terminated self-assembled monolayers (SAMs) show (i) finite adhesion at low pH and no measurable adhesion at high pH for unmodified, carboxyl-terminated NT tips, (ii) no measurable adhesion at low pH and finite adhesion at high pH for amine-terminated NT tips, and (iii) pH independent adhesion for phenyl-terminated NT tips. This adhesion vs. pH behavior is consistent with the tip functionalities. Furthermore, MWNT tips modified with biotin have been used to measure the binding force between single streptavidin-biotin pairs.

In addition, functionalized nanotube tips have been used to map chemical domains on surfaces with nanometer resolution. Intermittent contact phase images obtained in ethanol on methyl/carboxyl patterned SAMs show greater phase lag between the carboxyl regions and COOH terminated NT tips, whereas phase images taken with phenyl terminated tips exhibit greater phase lag in the methyl terminated areas in agreement with the expected adhesion trends. Furthermore, images of partial bilayer structures that present carboxyl and methyl functionalities show that SWNT tips yield chemically-sensitive lateral resolution of ~3 nm. These new AFM probes provide a clear pathway for achieving molecular resolution, chemically sensitive imaging of chemical and biological systems.

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Text-only interface



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L62 ANSWER 8 OF 14 HCAPLUS COPYRIGHT ACS on STN
     1999:470213 HCAPLUS
AN
     131:254597
DN
     Entered STN: 02 Aug 1999
ED
     Helical crystallization of proteins on carbon nanotubes: a first
     step towards the development of new biosensors
     Balavoine, Fabrice; Schultz, Patrick; Richard, Cyrille; Mallouh,
ΑU
     Veronique; Ebbesen, Thomas W.; Mioskowski, Charles
     CEA Saclay-DSV/DBCM/SMM, Gif sur Yvette, 91191, Fr.
CS
     Angewandte Chemie, International Edition (1999), 38(13/14), 1912-1915
SO
     CODEN: ACIEF5; ISSN: 1433-7851
PΒ
     Wiley-VCH Verlag GmbH
DT
     Journal
     English
LA
CC
     9-16 (Biochemical Methods)
     Section cross-reference(s): 6
     To demonstrate the potential of carbon nanotubes in structural biol. and biotechnol.,
AB
      streptavidin and HupR, both are water soluble proteins, were chosen to study the
      crystallization and interaction of proteins with carbon nanotubes.
     protein crystn carbon nanotube biosensor
ST
     Biosensors
IT
     Microscopy
        (helical crystallization of proteins on carbon nanotubes and a first
        step towards the development of new biosensors)
     Proteins, general, biological studies
IT
     RL: BSU (Biological study, unclassified); PEP (Physical, engineering or
     chemical process); BIOL (Biological study); PROC (Process)
         (helical crystallization of proteins on carbon nanotubes and a first
        step towards the development of new biosensors)
     7440-44-0, Carbon, uses
     RL: TEM (Technical or engineered material use); USES (Uses)
         (helical crystallization of proteins on carbon nanotubes and a first
        step towards the development of new biosensors)
               THERE ARE 26 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
RE
(1) Amos, L; Prog Biophys Mol Biol 1982, V39, P183 HCAPLUS
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 (17) Ringler, P; Chem Eur J 1997, V3, P620 HCAPLUS
 (18) Schwidop, W; J Chromatogr 1990, V520, P325 HCAPLUS
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 (20) Tsang, S; Angew Chem 1997, V109, P2291
 (21) Tsang, S; Angew Chem Int Ed 1997, V36, P2198 HCAPLUS
 (22) Unwin, N; J Mol Biol 1993, V229, P1101 HCAPLUS
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 (25) Wilson-Kubalek, E; Proc Natl Acad Sci 1998, V95, P8040 HCAPLUS
 (26) Wong, S; Nature 1998, V394, P52 HCAPLUS
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L32 ANSWER 53 OF 82 HCAPLUS COPYRIGHT ACS on STN
     1999:418238 HCAPLUS
AN
     131:190015
DN
ED
     Entered STN: 07 Jul 1999
     Formation and characterization of metal atom nanostructures on Si(112)
     facet surfaces
     Prokes, S. M.; Glembocki, O. J.
AU
     Naval Research Laboratory, Washington, DC, 20375-5347, USA
CS
     Journal of Vacuum Science & Technology, A: Vacuum, Surfaces, and Films
SO
     (1999), 17(4, Pt. 1), 1410-1414
     CODEN: JVTAD6; ISSN: 0734-2101
     American Institute of Physics
PB
DT
     Journal
     English
LA
     66-3 (Surface Chemistry and Colloids)
CC
     Section cross-reference(s): 56, 73
     Auger electron spectroscopy (AES) and reflectance anisotropy (RA) have been used to study the
AB
      formation of Ga or Al chains and nanowires on the Si(112) surface. The Ga or Al chains form
     on the step ledges by a self-limiting process at higher temps. (>350 °C), while at lower
      temps., Ga or Al nanowires form on the terraces in addition to the chains on the ledges. The
     process has been tracked in real time from the rapid change of the (2+1) Si(112)
      reconstruction under subcrit. coverage to chain formation leading to a 5+1 reconstruction
      followed by a 6+1 reconstruction. During sequential deposition of Ga and Al, it was observed
      (in RA and AES) that Ga atoms forming the chains can be replaced by Al. This indicates that
      the Al-Si bond is stronger than the Ga-Si bond and confirms the chemical sensitivity of the
      light scattering in RA. Low temperature depositions (in the 300 °C range) are shown to lead
      to the formation of Ga or Al metallic wires on the Si(111) terraces. Continued deposition of
      less than 10 monolayers at T below 250 °C leads to a very anisotropic but patterned Al or Ga
      structure in registry with the substrate which retains an unexpectedly large polarizability
      for coverages as thick as 40 monolayers.
     Nanostructures
IT
       Nanowires (metallic)
        (formation and characterization of Ga and Al chains and
        nanowires on Si(112) surface)
                                       7440-21-3, Silicon, properties
     7429-90-5, Aluminum, properties
IT
     7440-55-3, Gallium, properties
     RL: PEP (Physical, engineering or chemical process); PRP (Properties);
     PROC (Process)
         (formation and characterization of Ga and Al chains and
        nanowires on Si(112) surface)
              THERE ARE 12 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
(1) Aspnes, D; J Vac Sci Technol A 1988, V6, P1327 HCAPLUS
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```

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(6) Jung, T; J Vac Sci Technol A 1994, V12, P1838 HCAPLUS (7) Jung, T; Surf Sci Lett 1993, V289, PL577 HCAPLUS (8) Petroff, P; Ultramicroscopy 1989, V31, P67 HCAPLUS

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L56 ANSWER 2 OF 4 HCAPLUS COPYRIGHT ACS on STN 1999:391295 HCAPLUS AN 131:137757 DN Entered STN: 25 Jun 1999 ED Functionalization of carbon nanotube AFM probes using ΤI tip-activated gases Wong, Stanislaus S.; Woolley, Adam T.; Joselevich, Ernesto; Lieber, AU Charles M. Department of Chemistry and Chemical Biology, Harvard University, CS Cambridge, MA, 02138, USA Chemical Physics Letters (1999), 306(5,6), 219-225 SO CODEN: CHPLBC; ISSN: 0009-2614 Elsevier Science B.V. PΒ DΤ Journal English 76-12 (Electric Phenomena) CC Section cross-reference(s): 66 Multiwalled C nanotube (MWNT) probe microscopy tips were functionalized with gases, activated AΒ in a transient arc produced at the tip ends. Adhesion measurements between these tips and hydroxyl-terminated monolayers vs. pH reveal that MWNT tips reacted in O2, H2 and N2 display acidic, pH-independent and basic properties, resp. MWNT tips derivatized in O2/N2 and H2/N2 mixts. demonstrate the greater reactivity of C nanotubes towards O2 and H2, resp. Also, the chemical reactivity of tips functionalized in N2 suggests termination in aromatic N heterocycles. Tip-activated gas functionalization of MWNTs provides facile generation of chemical sensitive nanoprobes. functional group carbon nanotube AFM gas reaction; oxygen ST reaction carbon nanotube tip AFM; hydrogen reaction carbon nanotube tip AFM; nitrogen reaction carbon nanotube tip 532-32-1, Sodium benzoate 1333-74-0, Hydrogen, reactions IT 2-[N-Morpholino]ethanesulfonic acid 7727-37-9, Nitrogen, reactions 25952-53-8, 1-Ethyl-3-(3-7782-44-7, Oxygen, reactions dimethylaminopropyl) carbodiimide hydrochloride RL: RCT (Reactant); RACT (Reactant or reagent) (functionalization of carbon nanotube AFM probes using tip-activated gases in arc) THERE ARE 19 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT 19 (1) Binnig, G; Phys Rev Lett 1986, V56, P930 (2) Bodanszky, M; The Practice of Peptide Synthesis 2nd edn 1994 (3) Bustamante, C; Curr Opin Struct Biol 1997, V7, P709 HCAPLUS (4) Colbert, D; Science 1994, V266, P1218 HCAPLUS (5) Dai, H; Nature 1996, V384, P147 HCAPLUS (6) Evans, J; J Electroanal Chem 1977, V80, P409 HCAPLUS (7) Gomer, R; Field Emission and Field Ionization 1961 (8) Hansma, P; Appl Phys Lett 1994, V64, P1738 HCAPLUS (9) Hiura, H; Adv Mater 1995, V7, P275 HCAPLUS (10) Noy, A; Annu Rev Mater Sci 1997, V27, P381 HCAPLUS (11) Rinzler, A; Science 1995, V269, P1550 HCAPLUS (12) Thoma, A; J Phys Chem 1992, V96, P7231 HCAPLUS (13) Vezenov, D; J Am Chem Soc 1997, V119, P2006 (14) Wandass, J; J Electrochem Soc 1987, V134, P2734 HCAPLUS (15) Wong, E; Science 1997, V277, P1971 HCAPLUS (16) Wong, S; Appl Phys Lett 1998, V73, P3465 HCAPLUS (17) Wong, S; J Am Chem Soc 1998, V120, P603 HCAPLUS

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L62 ANSWER 9 OF 14 HCAPLUS COPYRIGHT ACS on STN
     1999:328172 HCAPLUS
AN
     131:124709
DN
     Entered STN: 28 May 1999
ED
     Construction of a glucose biosensor immobilized with glucose
TI
     oxidase in the film of polypyrrole nanotubules
     Miao, Yuqing; Qi, Ming; Zhan, Shuzhong; He, Nongyue; Wang, Jian; Yuan,
AU
     National Laboratory of Molecular and Biomolecular Electronics, Southeast
     University, Nanjing, 210096, Peop. Rep. China
     Analytical Letters (1999), 32(7), 1287-1299
SO
     CODEN: ANALBP; ISSN: 0003-2719
PΒ
     Marcel Dekker, Inc.
     Journal
DT
     English
LA
     80-2 (Organic Analytical Chemistry)
CC
     Section cross-reference(s): 9
     By electrochem. adsorption of glucose oxidase (GO) on a polypyrrole (PPy) nanotubular layer, a
AB
      glucose biosensor was fabricated. PPy microtubules can be synthesized by oxidative
      polymerization of the pyrrole monomer within the pores of a polycarbonate template. The
      activities of immobilized GO were studied and the electrochem. properties were characterized
      by comparison of the GO electrode constructed by electropolymn. and doping.
     glucose biosensor immobilized oxidase film; polypyrrole
     nanotubule oxidase immobilized glucose biosensor
IT
     Biosensors
     Enzyme electrodes
     Microtubule
         (construction of a glucose biosensor immobilized with glucose
        oxidase in the film of polypyrrole nanotubules)
     50-99-7, D-Glucose, analysis
IT
     RL: ANT (Analyte); ANST (Analytical study)
         (construction of a glucose biosensor immobilized with glucose
        oxidase in the film of polypyrrole nanotubules)
                                  30604-81-0, Polypyrrole
     9001-37-0, Glucose oxidase
IT
     RL: ARU (Analytical role, unclassified); DEV (Device component use); ANST
      (Analytical study); USES (Uses)
         (construction of a glucose biosensor immobilized with glucose
         oxidase in the film of polypyrrole nanotubules)
               THERE ARE 12 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE
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L62 ANSWER 10 OF 14 HCAPLUS COPYRIGHT ACS on STN
     1999:100743 HCAPLUS
ΑN
     130:121849
DN
     Entered STN: 16 Feb 1999
ED
     Graphitic nanotubes in luminescence assays
ΤI
     Massey, Richard J.; Martin, Mark T.; Dong, Liwen; Lu, Ming; Fischer, Alan;
IN
     Jameison, Fabian; Liang, Pam; Hoch, Robert; Leland, Jonathan K.
PA
     Meso Scale Technology, USA
                                            APPLICATION NO.
                                                                  DATE
                               DATE
                        KIND
     PATENT NO.
                                                                  19960306 <--
                                           US 1996-611347
                         Α
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PΙ
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                                20010320 US 1994-352400
     US 6203814
                         В1
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                                                                   19951208 <--
                                19960613
                         AA
     CA 2207282
                                                                  19951208 <--
                         Т3
                                20040701
                                           ES 1995-944093
     ES 2210324
                                                                  19970305 <--
                                19970909
                                           ZA 1997-1915
     ZA 9701915
                         Α
                                                                  19970305 <--
                                            CA 1997-2248893
                         AA
                                19970912
     CA 2248893
                                                                  19970305 <--
                                19970912
                                            WO 1997-US3653
                         A1
     WO 9733176
                                                                  19970305 <--
                                           AU 1997-20737
                         A1.
                                19970922
     AU 9720737
     AU 724509
                         B2
                                20000921
                                            EP 1997-908967
                                                                   19970305 <--
                         A1
                                19981223
     EP 885393
                                                                   19970305 <--
                                19990526
                                            CN 1997-194334
                         Α
     CN 1217791
                                                                   19970305 <--
                                            JP 1997-531989
     JP 2001507787
                         Т2
                                20010612
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                                20020725
     IL 125985
                                                                   19970305 <--
                                20020910
                                            RU 1998-116668
                         C2
     RU 2189043
                                                                   19990202 <--
                                            US 1999-243215
     US 6362011
                         B1
                                20020326
                                                                   20011205 <--
                                            US 2001-7526
                                20020704
     US 2002086335
                         A1
                                19941208 <--
PRAI US 1994-352400
                         A2
                                19960306 <--
     US 1996-611347
                         Α
                                          <--
     WO 1997-US3653
                          W
                                19970305
                                19990202 <--
                         A1
     US 1999-243215
      Graphitic nanotubes, which include tubular fullerenes (commonly called "buckytubes") and
AB
      fibrils, which are functionalized by chemical substitution, are used as solid supports in
      electrogenerated chemiluminescence assays. The graphitic nanotubes are chemical modified with
      functional group biomols. prior to use in an assay. Association of electrochemiluminescent
      ruthenium complexes with the functional group biomol.-modified nanotubes permits detection of
      mols. including nucleic acids, antigens, enzymes, and enzyme substrates by multiple formats.
     graphitic nanotube electrochemiluminescence binding assay;
      tubular fullerene nanotube support electrochemiluminescence
     assay; biosensor electrochemiluminescence carbon
     nanotube; immunoassay electrochemiluminescence graphitic
     nanotube; ruthenium complex electrochemiluminescence graphitic
     nanotube
      Separation
 IT
         (affinity; graphitic nanotubes in luminescence assays of
         biomols. and biopolymers)
      Nanotubes
 IT
        Nanotubes
      RL: ARG (Analytical reagent use); RCT (Reactant); ANST (Analytical study);
      RACT (Reactant or reagent); USES (Uses)
         (carbon fibers; graphitic nanotubes in luminescence assays of
         biomols. and biopolymers)
 IT
      Nanotubes
      RL: ARG (Analytical reagent use); RCT (Reactant); ANST (Analytical study);
      RACT (Reactant or reagent); USES (Uses)
         (carbon; graphitic nanotubes in luminescence assays of
         biomols. and biopolymers)
      Chemiluminescence spectroscopy
 IT
         (electro-; graphitic nanotubes in luminescence assays of
         biomols. and biopolymers)
 ΙT
      Immunoassay
      Luminescence, chemiluminescence
          (electrochemiluminescence; graphitic nanotubes in
         luminescence assays of biomols. and biopolymers)
 IT
          (enzymic; graphitic nanotubes in luminescence assays of
         biomols. and biopolymers)
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Avidins

ΙT

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L19 ANSWER 4 OF 5 HCAPLUS COPYRIGHT ACS on STN
    1998:815674 HCAPLUS
AN
     130:249046
DN
     Entered STN: 01 Jan 1999
ED
     Subcellular optochemical nanobiosensors: probes encapsulated by
TI
     biologically localized embedding (PEBBLEs)
     Clark, Heather A.; Barker, Susan L. R.; Brasuel, Murphy; Miller, Michael
ΑU
     T.; Monson, Eric; Parus, Steve; Shi, Zhong-You; Song, Antonius; Thorsrud,
     Bjorn; Kopelman, Raoul; Ade, Alex; Meixner, Walter; Athey, Brian; Hoyer,
     Marion; Hill, Dwayne; Lightle, Rhonda; Philbert, Martin A.
     Department of Chemistry, University of Michigan, Ann Arbor, MI,
     48109-1055, USA
     Sensors and Actuators, B: Chemical (1998), B51(1-3), 12-16
SO
     CODEN: SABCEB; ISSN: 0925-4005
     Elsevier Science S.A.
PB
     Journal
DT
LA
     English
     9-16 (Biochemical Methods)
CC
     Described here are arguably the world's smallest stand-alone devices/sensors, consisting of
AB
      multicomponent nano-spheres with radii as small as 10 nm, occupying ≈1 ppb of a typical
      mammalian cell's volume The probe is prepared from up to seven ingredients and is optimized
      for selective and reversible analyte detection, as well as sensor stability and
      reproducibility. Such a sensor probe encapsulated by biol. localized embedding (PEBBLE), is
      delivered into a cell by a variety of minimally-invasive techniques, including a pico-
      injector, a gene gun, liposomal incorporation and natural ingestion. These remote nano-
      optodes (PEBBLEs) have been prepared for pH, calcium, magnesium, potassium and oxygen. The
      sensor PEBBLEs can be inserted into a cell individually, in clusters (single analyte), in sets
      (multi-analyte) or in ensembles (single analyte, multiple locations).
     nanobiosensor PEBBLE optrode
ST
     Animal cell line
IT
         (SH-SY5Y; subcellular optochem. nanobiosensors, probes
        encapsulated by biol. localized embedding (PEBBLEs))
ΙT
     Optrodes
     Optrodes
         (biosensors; subcellular optochem. nanobiosensors, probes
        encapsulated by biol. localized embedding (PEBBLEs))
IT
     Biosensors
         (optrodes; subcellular optochem. nanobiosensors, probes
         encapsulated by biol. localized embedding (PEBBLEs))
IT
     Nanomachines
         (subcellular optochem. nanobiosensors, probes encapsulated by
         biol. localized embedding (PEBBLEs))
      128724-35-6, Carboxynaphthofluorescein
 IT
      RL: ARG (Analytical reagent use); ANST (Analytical study); USES (Uses)
         (subcellular optochem. nanobiosensors, probes encapsulated by
         biol. localized embedding (PEBBLEs))
                                       94-36-0, Benzoyl peroxide, reactions
      79-06-1, Acrylamide, reactions
 IT
                 119-61-9, Benzophenone, reactions 3179-47-3, Decyl
      110-26-9
                                                          58264-26-9, Hexane
                     10041-19-7, Dioctyl sulfosuccinate
      methacrylate
      dioldimethacrylate
      RL: RCT (Reactant); RACT (Reactant or reagent)
         (subcellular optochem. nanobiosensors, probes encapsulated by
         biol. localized embedding (PEBBLEs))
               THERE ARE 11 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT 11
  (1) Ambrose, T; Electroanalysis 1996, V8, P1095 HCAPLUS
 (2) Barker, S; Anal Chem 1998, V70, P100 HCAPLUS
 (3) Barker, S; Anal Chem 1998, V70, P971 HCAPLUS
 (4) Kopelman, R; SPIE 1996, V2836, P2 HCAPLUS
 (5) Peterson, J; Anal Chem 1980, V52, P864 HCAPLUS
 (6) Sasaki, K; Chem Lett 1996, P141 HCAPLUS
 (7) Shortreed, M; Anal Chem 1996, V68, P2656 HCAPLUS
 (8) Shortreed, M; Sensors and Actuators B 1997, V38-39, P8
 (9) Tan, W; Science 1992, V258, P778 HCAPLUS
 (10) Wightman, R; A J Bard 1989, V15
 (11) Wightman, R; Anal Chem 1988, V60, P769A HCAPLUS
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L62 ANSWER 11 OF 14 HCAPLUS COPYRIGHT ACS on STN
    1998:801871 HCAPLUS
AN
DN
     130:135446
     Entered STN:
                   23 Dec 1998
ED
     Carriers and channels: current progress and future prospects
TΙ
ΑU
     Department of Chemistry, MS216, University of Nevada, Reno, NV, 89557, USA
CS
     Current Opinion in Chemical Biology (1998), 2(6), 711-716
SO
     CODEN: COCBF4; ISSN: 1367-5931
PB
     Current Biology Publications
     Journal; General Review
DT
     English
LA
     6-0 (General Biochemistry)
CC
     A review with 38 refs. Recent advances in the understanding of biol. transport and in the
AB
     design of artificial transport systems have resulted from the structural elucidation of the K+
     ion channel and from synthesis of artificial receptors for cations and anions, as well as
     neutral and zwitterionic organic mols. Sensors, gated carriers, and self-assembling capsules
     and nanotubes are all important offsprings of current efforts to mimic natural transport
     across biomembranes.
     review biol transport carrier channel model
ST
TΤ
     Biosensors
       Nanotubes
        (carrier- and channel-mediated biol. transport and design of artificial
        transport systems)
     Potassium channel
     RL: BPR (Biological process); BSU (Biological study, unclassified); PRP
     (Properties); BIOL (Biological study); PROC (Process)
        (carrier- and channel-mediated biol. transport and design of artificial
        transport systems)
     Receptors
IT
     RL: BPR (Biological process); BSU (Biological study, unclassified); SPN
     (Synthetic preparation); BIOL (Biological study); PREP (Preparation); PROC
         (carrier- and channel-mediated biol. transport and design of artificial
        transport systems)
IT
     Biological transport
         (carrier-mediated; carrier- and channel-mediated biol. transport and
        design of artificial transport systems)
IT
     Biological transport
         (channel-mediated; carrier- and channel-mediated biol. transport and
        design of artificial transport systems)
     Transport properties
IT
         (ionic; carrier- and channel-mediated biol. transport and design of
        artificial transport systems)
              THERE ARE 38 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
RE
(1) Anon; Chemosensors of Ion and Molecule Recognition. NATO ASI Series 1997
 (2) Bakker, E; Chem Rev 1997, V97, P3083 HCAPLUS
 (3) Bell, T; J Org Chem 1998, V63, P2232 HCAPLUS
 (4) Boerrigter, H; J Org Chem 1998, V63, P4174 HCAPLUS
 (5) Conn, M; Chem Rev 1997, V97, P1647 HCAPLUS
 (6) Cui, C; J Phys Chem A 1998, V102, P1119 HCAPLUS
 (7) de Mendoza, J; Chem Eur J 1998, V4, P1373 HCAPLUS
 (8) Doyle, D; Science 1998, V280, P69 HCAPLUS
 (9) Eisenberg, B; Accounts Chem Res 1998, V31, P117 HCAPLUS
 (10) Fyles, T; Curr Opin Chem Biol 1997, V1, P497 HCAPLUS
 (11) Hartgerink, J; Chem Eur J 1998, V4, P1367 HCAPLUS
 (12) Hirayama, H; J Membr Sci 1998, V139, P109 HCAPLUS
 (13) Jiwan, J; J Photochem Photobiol A - Chem 1998, V116, P127
 (14) Karle, I; J Am Chem Soc 1998, V120, P6903 HCAPLUS
 (15) Kim, H; J Am Chem Soc 1998, V120, P4417 HCAPLUS
 (16) Kimura, A; Chem Pharm Bull 1997, V45, P431 HCAPLUS
 (17) Lamb, J; Separ Sci Technol 1997, V32, P2749 HCAPLUS
 (18) Ma, J; Chem Rev 1997, V97, P1303 HCAPLUS
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L65 ANSWER 16 OF 35 HCAPLUS COPYRIGHT ACS on STN
    1998:602481 HCAPLUS
ΑN
     129:267168
DN
     Entered STN: 23 Sep 1998
ED
     Silver-filled carbon nanotubes used as spectroscopic enhancers
TΙ
     Garcia-Vidal, F. J.; Pitarke, J. M.; Pendry, J. B.
     Facultad de Ciencias, Departamento de Fisica Teorica de la Materia
CS
     Condensada, Universidad Autonoma de Madrid, Madrid, 28049, Spain
     Physical Review B: Condensed Matter and Materials Physics (1998), 58(11),
SO
     6783-6786
     CODEN: PRBMDO; ISSN: 0163-1829
     American Physical Society
DT
LA
     English
     73-2 (Optical, Electron, and Mass Spectroscopy and Other Related
CC
     Properties)
     Section cross-reference(s): 76
     The authors analyze from a theor. point of view the optical properties of arrays of C
AB
     nanotubes filled with Ag. Dependence of these properties on the different parameters involved
      was studied using a transfer matrix formalism able to work with tensor-like dielec. functions
      and including the full electromagnetic coupling between the nanotubes. These structures
      exhibit very strong linear optical response and hence could be used as spectroscopic enhancers
      or chemical sensors in the visible range. Very localized surface plasmons, created by the
      electromagnetic interaction between the capped Ag cylinders, are responsible for this
      enhancing ability. Enhancements of up to 106 in the Raman signal of mols. absorbed on these
      arrays could be obtained.
     silver filled carbon nanotube spectroscopic enhancer
ST
IT
     Nanotubes
     RL: DEV (Device component use); PRP (Properties); USES (Uses)
         (carbon; silver-filled carbon nanotubes used as spectroscopic
        enhancers)
TТ
     Surface plasmon
         (localized; silver-filled carbon nanotubes used as
        spectroscopic enhancers)
     Dielectric function
     Optical properties
     Optical reflection
     Sensors
         (silver-filled carbon nanotubes used as spectroscopic
        enhancers)
     Raman spectroscopy
IT
         (silver-filled carbon nanotubes used as spectroscopic
         enhancers and their applications)
      7440-22-4, Silver, properties
IT
      RL: DEV (Device component use); OCU (Occurrence, unclassified); PRP
      (Properties); OCCU (Occurrence); USES (Uses)
         (silver-filled carbon nanotubes used as spectroscopic
               THERE ARE 25 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
        25
 (1) Ajayan, P; Nature (London) 1993, V361, P333 HCAPLUS
 (2) Ajayan, P; Rep Prog Phys 1997, V60, P1025 HCAPLUS
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 (5) Collier, C; Science 1997, V277, P1978 HCAPLUS
 (6) de Heer, W; Science 1995, V268, P845 HCAPLUS
 (7) Dujardin, E; Science 1994, V265, P1850 HCAPLUS
 (8) Fleischmann, M; Chem Phys Lett 1974, V26, P163 HCAPLUS
 (9) Freeman, R; Science 1995, V267, P1629 HCAPLUS
 (10) Garcia-Vidal, F; Phys Rev Lett 1996, V77, P1163 HCAPLUS
 (11) Garcia-Vidal, F; Phys Rev Lett 1997, V78, P4289 HCAPLUS
 (12) Garcia-Vidal, F; Prog Surf Sci 1995, V50, P55 HCAPLUS
 (13) Iijima, S; Nature (London) 1991, V354, P56 HCAPLUS
 (14) Kusunoki, M; Appl Phys Lett 1997, V71, P2620 HCAPLUS
 (15) Lucas, A; Phys Rev B 1994, V49, P2888 HCAPLUS
(16) Mirkin, C; Nature (London) 1996, V382, P607 HCAPLUS
 (17) Moskovits, M; Rev Mod Phys 1985, V57, P783 HCAPLUS
```

# L19 ANSWER 5 OF 5 HCAPLUS COPYRIGHT ACS on STN

- AN 1998:524471 HCAPLUS
- ED Entered STN: 21 Aug 1998
- TI Liposomes as nanosensors in a biological environment.
- AU Rosenzweig, Zeev; McNamara, Kerry P.
- CS DEPARTMENT CHEMISTRY, UNIVERSITY NEW ORLEANS, New Orleans, LA, 70148, USA
- SO Book of Abstracts, 216th ACS National Meeting, Boston, August 23-27 (1998), ANYL-035 Publisher: American Chemical Society, Washington, D. C. CODEN: 66KYA2
- DT Conference; Meeting Abstract
- LA English
- Liposomes have been frequently used for controlled release in drug delivery applications. Taking advantage of their small size (50-100 nm) and their ability to readily penetrate into cells we demonstrate the use of liposomes encapsulating environmentally sensitive fluorescent dyes as intracellular nanobiosensors. Liposomes that are constructed from polymerizable phospholipids exhibit higher stability with respect to dye leaking compared to liposomes that are constructed from typical phospholipids such as egg phosphatidylcholine. The study focuses on monitoring intracellular oxygen levels with individual liposomes encapsulating the oxygen sensitive fluorescence indicator ruthenium tris phenanthroline.

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L56 ANSWER 3 OF 4 HCAPLUS COPYRIGHT ACS on STN
     1998:499472 HCAPLUS
AN
     129:250582
DN
     Entered STN: 12 Aug 1998
F.D
     Covalently-Functionalized Single-Walled Carbon Nanotube
     Probe Tips for Chemical Force Microscopy
     Wong, Stanislaus S.; Woolley, Adam T.; Joselevich, Ernesto; Cheung, Chin
ΑU
     Li; Lieber, Charles M.
     Department of Chemistry and Chemical Biology, Harvard University,
CS
     Cambridge, MA, 02138, USA
      Journal of the American Chemical Society (1998), 120(33), 8557-8558
SO
      CODEN: JACSAT; ISSN: 0002-7863
     American Chemical Society
PB
DT
      Journal
LA
     English
      66-3 (Surface Chemistry and Colloids)
CC
      A covalent modification of single-walled carbon nanotubes (SWCNs) is reported for creating
AB
      high-resolution, chemical- sensitive probe microscopy tips. Carboxylic acid groups at the
      open ends of SWCNs were coupled to amines to create addnl. probes with basic or hydrophobic
      functionality. Force titrns. recorded between the ends of the SWNT tips and hydroxy-
      terminated self-assembled monolayers (SAMs) confirmed the chemical sensitivity and robustness
      of these SWNT tips. Images recorded on patterned SAM and partial bilayer surfaces have
      demonstrated chemical sensitive imaging with nanometer-scale resolution These studies show
      that well-defined covalent chemical can be exploited to create functionalized SWNT probes that
      have the potential for true mol.-resolution, chemical sensitive imaging.
      Scanning force microscopes
· IT
         (tips; covalently functionalized single-walled carbon nanotube
         probe tips for chemical force microscopy)
 IT
      7440-44-0, Carbon, uses
      RL: DEV (Device component use); USES (Uses)
         (covalently functionalized single-walled carbon nanotube
         probe tips for chemical force microscopy)
               THERE ARE 26 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT
 RE
 (1) Akari, S; Adv Mater 1995, V7, P549 HCAPLUS
 (2) Bodanszky, M; The Practice of Peptide Synthesis, 2nd ed 1994
 (3) Dai, H; Nature 1996, V384, P147 HCAPLUS
 (4) Evans, J; J Electroanal Chem 1977, V80, P409 HCAPLUS
 (5) Finot, M; J Am Chem Soc 1997, V119, P8564 HCAPLUS
 (6) Frisbie, C; Science 1994, V265, P2071 HCAPLUS
 (7) Giles, M; Anal Biochem 1990, V184, P244
 (8) Green, J; J Phys Chem 1995, V99, P10960
 (9) Hiura, H. Adv Mater 1995, V7, P275 HCAPLUS
 (10) Hu, K; Langmuir 1997, V13, P5114 HCAPLUS
 (11) March, J; Advanced Organic Chemistry 1992
 (12) Marti, A; Langmuir 1995, V11, P4632 HCAPLUS
 (13) McKendry, R; Nature 1998, V391, P566 HCAPLUS
 (14) Noy, A; Annu Rev Mater Sci 1997, V27, P381 HCAPLUS
 (15) Noy, A; J Am Chem Soc 1995, V117, P7943 HCAPLUS
  (16) Noy, A; Langmuir 1998, V14, P1508 HCAPLUS
  (17) Senden, T; J Colloids Surf, A 1995, V94, P29 HCAPLUS
  (18) Sinniah, S; J Am Chem Soc 1996, V118, P8925 HCAPLUS
  (19) Thess, A; Science 1996, V273, P483 HCAPLUS
  (20) Thomas, R; J Am Chem Soc 1995, V117, P3830 HCAPLUS
  (21) van der Vegte, E; J Phys Chem 1997, V101, P9563 HCAPLUS
  (22) Vezenov, D; J Am Chem Soc 1997, V119, P2006
  (23) Wandass, J; J Electrochem Soc 1987, V134, P2734 HCAPLUS
  (24) Williams, J; Langmuir 1996, V12, P1291 HCAPLUS
  (25) Wong, S; J Am Chem Soc 1998, V120, P603 HCAPLUS
  (26) Wong, S; Nature 1998, V394, P52 HCAPLUS
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ANSWER 4 OF 4 HCAPLUS COPYRIGHT ACS on STN
     1998:447265 HCAPLUS
AN
DN
     129:167339
     Entered STN: 20 Jul 1998
ΕD
     Covalently functionalized nanotubes as nanometer-sized
ΤI
     probes in chemistry and biology
     Wong, Stanislaus S.; Joselevich, Ernesto; Woolley, Adam T.; Cheung, Chhin
ΑIJ
     Li; Lieber, Charles M.
     Dep. Chem. and Chem. Biol., Harvard Univ., Cambridge, MA, 02138, USA
CS
     Nature (London) (1998), 394 (6688), 52-55
     CODEN: NATUAS; ISSN: 0028-0836
```

PB Macmillan Magazines

A review with 25 refs. C nanotubes combine a range of properties that make them well suited AB for use as probe tips in applications such as atomic force microscopy (AFM). Their high aspect ratio, for example, opens up the possibility of probing the deep crevices that occur in microelectronic circuits, and the small effective radius of nanotube tips significantly improves the lateral resolution beyond what can be achieved using com. Si tips. Another characteristic feature of nanotubes is their ability to buckle elastically, which makes them very robust while limiting the maximum force that is applied to delicate organic and biol. samples. Earlier studies into the performance of nanotubes as scanning probe microscopy tips have focused on topog. imaging, but a potentially more significant issue is the question of whether nanotubes can be modified to create probes that can sense and manipulate matter at the mol. level. Nanotube tips with the capability of chemical and biol. discrimination can be created with acidic functionality and by coupling basic or hydrophobic functionalities or biomol. probes to the carboxyl groups that are present at the open tips ends. The authors used these modified nanotubes as AFM tips to titrate the acid and base groups, to image patterned samples based onmol. interactions, and to measure the binding force between single protein-ligand pairs. As carboxyl groups are readily derivatized by a variety of reactions, the preparation of a wide range of functionalized nanotube tips should be possible, thus creating mol. probes with potential applications in many areas of chemical and biol.

ST review functionalized nanotube probe chem biol

IT Atomic force microscopy

# Nanotubes

Scanning probe microscopy

(covalently functionalized nanotubes as nanometer-sized probes in chemical and biol.)

RE.CNT 25 THERE ARE 25 CITED REFERENCES AVAILABLE FOR THIS RECORD RE

- (1) Binnig, G; Phys Rev Lett 1986, V56, P930
- (2) Bodanszky, M; The Practice of Peptide Synthesis 2nd edn 1994
- (3) Bustamante, C; Curr Opin Struct Biol 1997, V7, P709 HCAPLUS
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- (5) Evans, J; J Electroanal Chem 1977, V80, P409 HCAPLUS
- (6) Florin, E; Science 1994, V264, P415 HCAPLUS
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- (10) Hiura, H; Adv Mater 1995, V7, P275 HCAPLUS
- (11) Keller, D; Nature 1996, V384, P111 HCAPLUS
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- (16) Marti, A; Langmuir 1995, V11, P4632 HCAPLUS
- (17) McKendry, R; Nature 1998, V391, P566 HCAPLUS
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- (21) Vezenov, D; J Am Chem Soc 1997, V119, P2006
- (22) Wandass, J; J Electrochem Soc 1987, V134, P2734 HCAPLUS
- (23) Wong, E; Science 1997, V277, P1971 HCAPLUS
- (24) Wong, S; J Am Chem Soc 1998, V120, P603 HCAPLUS
- (25) Wong, S; J Am Chem Soc submitted

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L32 ANSWER 66 OF 82 HCAPLUS COPYRIGHT ACS on STN
     1998:423846 HCAPLUS
-AN
DN
     129:182575
     Entered STN: 10 Jul 1998
ED
     Ion beam synthesis of silicon-based materials
TI
     Mantl, S.; Hollander, B.; Lenssen, D.; Loken, M.
AU
     Inst. Schicht-und Ionentech., Forschungszentrum Julich, Julich, D-52425,
CS
     Materials Chemistry and Physics (1998), 54(1-3), 280-285
so
     CODEN: MCHPDR; ISSN: 0254-0584
PB
     Elsevier Science S.A.
      Ion beam synthesis (IBS) is a useful technique to fabricate silicon-based materials. The
AB
      authors will discuss the different mechanisms of IBS for materials forming solid solns. or
      stoichiometric compds. An interesting completely miscible system is Si-Ge because epitaxial
      Sil-xGex layers will be used for future microelectronic devices. As an example for a
      stoichiometric compound the authors have studied a metallic silicide, CoSi2, which is a
      favorite material for contacts and interconnects of deep submicron transistors and which is
      structurally compatible with silicon allowing epitaxial layer formation. Also, the authors
      show the synthesis of a ternary silicide compound Col-xPdxSi2. One of the key advantages of
      IBS is the possibility of direct patterning of structures using an implantation mask. The
      authors studied the dimensional limits of the fabrication of epitaxial CoSi2 nanowires in
      Si(100). These metallic wires with diams. ≥170nm show quantum effects of the elec. transport
      by the observation of weak localization effects. The usefulness for applications of ion beam
      synthesized buried CoSi2 layers in silicon is demonstrated by the realization of an ultrafast
      vertical metal/semiconductor/metal photodetector.
      ion beam synthesis silicon material microelectronics
 ST
      Semiconductor materials
 ΙT
         (nanowires; ion beam synthesis of silicon-based materials for
         microelectronic devices)
                                        11148-21-3P
                                                      12017-12-8P, Cobalt
      7440-21-3P, Silicon, properties
 IT
                        211567-39-4P, Cobalt palladium silicide ((Co,Pd)Si2)
      silicide (CoSi2)
      RL: PEP (Physical, engineering or chemical process); PNU (Preparation,
      unclassified); PRP (Properties); TEM (Technical or engineered material
      use); PREP (Preparation); PROC (Process); USES (Uses)
         (ion beam synthesis of silicon-based materials for microelectronic
         devices)
               THERE ARE 22 CITED REFERENCES AVAILABLE FOR THIS RECORD
 RE.CNT
 RE
 (1) Bergmann, G; Phys Rep 1984, V107(1), P2
 (2) Colinge, J; Silicon-on-Insulator Technology Materials to VLSI 1991, P1
 (3) Hermanns, J; Appl Phys Lett 1993, V62, P2507
 (4) Hollander, B; Proceedings of the 9th International Conference on Ion Beam
     Modification of Materials 1995, P947
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 (8) Mantl, S; Appl Phys Lett 1992, V61, P267 HCAPLUS
 (9) Mantl, S; Mater Sci Rep 1992, V8, P1
 (10) Mantl, S; Nucl Instr Meth B 1995, V106, P355 HCAPLUS
 (11) Osten, H; J Cryst Growth 1995, V150, P931 HCAPLUS
 (12) Presting, H; Mater Res Soc Symp Proc 1995, V379, P417 HCAPLUS
 (13) Radermacher, K; Phys Rev B 1993, V48, P8002 HCAPLUS
 (14) Reiss, S; Nucl Instr Meth B 1995, V102, P256 HCAPLUS
 (15) Santhanam, P; Phys Rev B 1987, V35, P3188 HCAPLUS
 (16) Schaffler, F; Semicond Sci Technol 1992, V7, P260
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 (18) Trinkaus, H; Nucl Instr Meth B 1993, V80-81, P862
 (19) Volz, K; Nucl Instr Meth B 1997, V127-128, P355
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(20) Wahl, U; Nucl Instr Meth B 1997, V127-128, P311
(21) White, A; Appl Phys Lett 1987, V50, P95 HCAPLUS
(22) Zimmerman, N; Appl Phys Lett 1993, V62, P387 HCAPLUS

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L62 ANSWER 12 OF 14 HCAPLUS COPYRIGHT ACS on STN
AN
     1998:69441 HCAPLUS
DN
     128:138151
     Entered STN: 06 Feb 1998
ED
TΙ
     Diffusion-Limited Size-Selective Ion Sensing Based on SAM-Supported
     Peptide Nanotubes. [Erratum to document cited in CA128:32011]
AU
     Motesharei, Kianoush; Ghadiri, M. Rzea
     Departments of Chemistry Molecular Biology, Scripps Research Institute, La
CS
     Jolla, CA, 92037, USA
so
     Journal of the American Chemical Society (1998), 120(6), 1347
     CODEN: JACSAT; ISSN: 0002-7863
PB
     American Chemical Society
DT
     Journal
     English
LA
CC
     9-1 (Biochemical Methods)
     Section cross-reference(s): 79
    On page 11311, Table 1, the capacitance values for substrate surfaces 3 and 4 should read 2.70
AB
     and 1.22, resp.
     erratum diffusion limited size selective Ion; diffusion limited size
ST
     selective Ion erratum; limited size selective Ion sensing erratum; Self
     assembled monolayer supported peptide erratum; assembled monolayer
     supported peptide nanotube erratum; SAM supported peptide
     nanotubes erratum
TΤ
     IR spectroscopy
        (Fourier-transform, grazing angle FTIR spectroscopy; structural
        properties of monolayer-supported peptide nanotubes by
        grazing angle FTIR spectroscopy (Erratum))
IT
     Nanotubes
        (cyclic peptide nanotubes; diffusion-limited size-selective
        ion sensing based on SAM-supported peptide nanotubes
        (Erratum))
TΤ
     Cyclic voltammetry
        (cyclic voltammograms of SAMs in electroactive solns. (Erratum))
IT
     Peptides, uses
     RL: DEV (Device component use); USES (Uses)
        (cyclic, cyclic peptide nanotubes; diffusion-limited
        size-selective ion sensing based on SAM-supported peptide
        nanotubes (Erratum))
     Diffusion
IT
     Tons
     Self-assembled monolayers
     Sensors
     Size effect
        (diffusion-limited size-selective ion sensing based on SAM-supported
        peptide nanotubes (Erratum))
TΤ
     Biosensors
        (diffusion-limited size-selective; diffusion-limited size-selective ion
        sensing based on SAM-supported peptide nanotubes (Erratum))
ΙT
     Electric impedance
        (elec. impedance spectroscopy for ion transport activity in
        SAM-supported peptide nanotubes (Erratum))
TT
     Diffusion
        (ionic, size-selective limited diffusion; diffusion-limited
        size-selective ion sensing based on SAM-supported peptide
        nanotubes (Erratum))
IT
     Adsorbed monolayers
        (self-assembled monolayers of organosulfurs on gold film;
        diffusion-limited size-selective ion sensing based on SAM-supported
        peptide nanotubes (Erratum))
     1844-09-3, Octadecyl sulfide
                                   7440-21-3, Silicon, uses
                                                                7440-57-5, Gold,
IT
     uses
            199737-34-3
        (diffusion-limited size-selective ion sensing based on SAM-supported
        peptide nanotubes (Erratum))
     112-55-0, 1-Dodecanethiol
     RL: DEV (Device component use); USES (Uses)
        (self-assembled monolayer; diffusion-limited size-selective ion sensing
        based on SAM-supported peptide nanotubes (Erratum))
```

### L32 ANSWER 71 OF 82 HCAPLUS COPYRIGHT ACS on STN 1998:10072 HCAPLUS DN 128:172559 ED Entered STN: 09 Jan 1998 TI Microscopic patterning of oriented mesoscopic silica through guided growth Trau, M.; Yao, N.; Kim, E.; Xia, Y.; Whitesides, G. M.; Aksay, I. A. ΑU CS Dep. Chem. Eng., Princeton Mater. Inst., Princeton Univ., Princeton, NJ, 08544-5263, USA SO Nature (London) (1997), 390(6661), 674-676 CODEN: NATUAS; ISSN: 0028-0836 PB Macmillan Magazines DTJournal LA English CC 66-4 (Surface Chemistry and Colloids) The supramol. assembly of surfactant mols. at a solid-liquid interface can produce tubular AB structures with diams. of .apprx.10 nm, which can be used for the templated polymerization of mesoporous SiO2 thin films. The orientation of the tubules depends primarily on the nature of the substrate-surfactant interaction. These nanostructured films hold much promise for applications such as their use as oriented nanowires, sensor/actuator arrays and optoelectronic devices. But a method of patterning the tubules and orienting them into designed arrangements is required for many of these possibilities to be realized. Here the authors describe a method that allows the direction of growth of these tubules to be guided by infiltrating a reaction fluid into the microcapillaries of a mold in contact with a substrate. An elec. field applied tangentially to the surface within the capillaries induces electroosmotic flow, and also enhances the rates of SiO2 polymerization around the tubules by localized Joule heating. After removal of the mold, patterned bundles of oriented nanotubules remain on the surface. This method permits the formation of oriented mesoporous channels on a nonconducting substrate with an arbitrary microscopic pattern. ST microscopic patterning oriented mesoscopic silica surfactant ΙT Porous materials (mesoporous; microscopic patterning of oriented mesoscopic silica through guided growth of surfactant mols. on plastic substrate) ΙT Adsorption (microscopic patterning of oriented mesoscopic silica through guided growth by adsorption of surfactant) IΤ 78-10-4, Tetraethoxysilane 112-02-7, Cetyltrimethylammonium chloride RL: PEP (Physical, engineering or chemical process); PROC (Process) (microscopic patterning of oriented mesoscopic silica through guided growth by adsorption of surfactant containing) 7631-86-9, Silica, processes RL: PEP (Physical, engineering or chemical process); PROC (Process) (microscopic patterning of oriented mesoscopic silica through guided growth of surfactant mols. on plastic substrate) THERE ARE 26 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT 26 RE (1) Aksay, I; Science 1996, V273, P892 HCAPLUS (2) Amundson, K; Macromolecules 1991, V24, P6546 HCAPLUS (3) Broers, A; Appl Phys Lett 1978, V33, P392 HCAPLUS (4) Chou, S; Science 1996, V272, P85 HCAPLUS (5) Early, K; Microelectron Eng 1990, V11, P317 HCAPLUS (6) Fendler, J; Chem Mater 1996, V8, P1616 HCAPLUS (7) Fischer, P; Appl Phys Lett 1993, V62, P2989 HCAPLUS (8) Flanders, D; Appl Phys Lett 1980, V36, P93 HCAPLUS (9) Iler, R; The Colloid Chemistry of Silica and Silicates 1955, P36 (10) Israelachvili, J; Intermolecular and Surface Forces 1992, P374 (11) Kim, E; Nature 1995, V376, P581 HCAPLUS (12) Kramer, N; Appl Phys Lett 1995, V66, P1325 HCAPLUS (13) Kresge, C; Nature 1992, V359, P710 HCAPLUS (14) Li, W; Science 1996, V274, P1701 HCAPLUS (15) Linder, E; J Chem Soc Faraday Trans 1993, V89, P361 (16) Lu, Y; Nature 1997, V389, P364 HCAPLUS (17) Manne, S; Langmuir 1994, V10, P4409 HCAPLUS (18) Manne, S; Science 1995, V270, P1480 HCAPLUS

(19) McCord, M; J Vac Sci Technol B 1986, V4, P86 (20) Morkved, T; Science 1996, V273, P931 HCAPLUS (21) Russel, W; Colloidal Dispersions 1989, P212 (22) Sakai, H; J Phys Chem 1996, V99, P11896

```
L62 ANSWER 13 OF 14 HCAPLUS COPYRIGHT ACS on STN
     1997:740809 HCAPLUS
AN
DN
     128:32011
     Entered STN: 26 Nov 1997
ED
     Diffusion-Limited Size-Selective Ion Sensing Based on SAM-Supported
ΤI
     Peptide Nanotubes
     Motesharei, Kianoush; Ghadiri, M. Reza
ΑU
     Departments of Chemistry Molecular Biology, Scripps Research Institute, La
CS
     Jolla, CA, 92037, USA
SO
     Journal of the American Chemical Society (1997), 119(46), 11306-11312
     CODEN: JACSAT; ISSN: 0002-7863
     American Chemical Society
PR
DΤ
     Journal
LΑ
     English
     9-1 (Biochemical Methods)
CC
     Section cross-reference(s): 79
     An approach for the construction of diffusion-limited size-selective sensors is described
AB
     based on the self-assembly of cyclic peptides into tubular channels in organosulfur self-
      assembled monolayers on gold films. An eight-residue cyclic peptide of alternating units of D-
      Leu and L-Trp amino acid residues was incorporated into monolayers of dodecanethiol and
      octadecyl sulfide and shown to adopt highly oriented tubular structures under specified
      adsorption conditions. The structural properties of monolayer-supported peptide nanotubes
     have been analyzed by grazing angle FTIR spectroscopy and their selective ion transport
      activities by cyclic voltammetry and impedance spectroscopy.
     diffusion limited size selective Ion sensing; Self assembled monolayer
ST
     supported peptide nanotube; SAM supported peptide
     nanotubes
IT
     IR spectroscopy
        (Fourier-transform, grazing angle FTIR spectroscopy; structural
        properties of monolayer-supported peptide nanotubes by
        grazing angle FTIR spectroscopy)
IT
     Nanotubes
        (cyclic peptide nanotubes; diffusion-limited size-selective
        ion sensing based on SAM-supported peptide nanotubes)
     Cyclic voltammetry
IT
        (cyclic voltammograms of SAMs in electroactive solns.)
IT
     Peptides, uses
        (cyclic, cyclic peptide nanotubes; diffusion-limited
        size-selective ion sensing based on SAM-supported peptide
        nanotubes)
     Self-assembled monolayers
IT
     Size effect
        (diffusion-limited size-selective ion sensing based on SAM-supported
        peptide nanotubes)
IT
     Ions
           (diffusion-limited size-selective ion sensing based on SAM-supported
        peptide nanotubes)
IΤ
     Biosensors
     Diffusion
     Sensors
         (diffusion-limited size-selective; diffusion-limited size-selective ion
        sensing based on SAM-supported peptide nanotubes)
     Electric impedance
IT
         (elec. impedance spectroscopy for ion transport activity in
        SAM-supported peptide nanotubes)
IT
         (ionic, size-selective limited diffusion; diffusion-limited
        size-selective ion sensing based on SAM-supported peptide
        nanotubes)
     Adsorbed monolayers
IT
         (self-assembled monolayers of organosulfurs on gold film;
        diffusion-limited size-selective ion sensing based on SAM-supported
        peptide nanotubes)
                                7440-57-5, Gold, uses
                                                         199737-34-3
IT
      7440-21-3, Silicon, uses
     RL: DEV (Device component use); USES (Uses)
         (diffusion-limited size-selective ion sensing based on SAM-supported
```

peptide nanotubes)

```
1997:618265 HCAPLUS
     127:275017
DN
     Entered STN: 27 Sep 1997
ED
     Graphitic nanotubes in luminescence assays
TТ
     Massey, Richard J.; Martin, Mark T.; Dong, Liwen; Lu, Ming; Fischer, Alan;
IN
     Jameison, Fabian; Liang, Pam; Hoch, Robert; Leland, Jonathon K.
PA
     Igen, Inc., USA
     PATENT NO.
                         KIND
                                DATE
                                            APPLICATION NO.
                                                                   DATE
     _____
                         ----
                               19970912
                                                                   19970305 <--
                                            WO 1997-US3653
     WO 9733176
                        A1
PΙ
     US 5866434
                        Α
                               19990202
                                           US 1996-611347
                                                                   19960306 <--
                        A1
                                                                   19970305 <--
     AU 9720737
                               19970922
                                           AU 1997-20737
                                20000921
     AU 724509
                         В2
                                            EP 1997-908967
                                                                   19970305 <--
                         A1
                                19981223
     EP 885393
                        Т2
                                                                  19970305 <--
     JP 2001507787
                                20010612
                                            JP 1997-531989
                                                                  19970305 <--
                                            IL 1997-125985
                               20020725
     IL 125985
                         A1
                                           RU 1998-116668
                                                                  19970305 <--
     RU 2189043
                         C2
                                20020910
                                19960306 <--
PRAI US 1996-611347
                         Α
     US 1994-352400
                         A2
                                19941208 <--
                         W
                                19970305 <--
     WO 1997-US3653
     Graphitic nanotubes, which include tubular fullerenes (commonly called "buckytubes") and
AB
      fibrils, which are functionalized by chemical substitution, are used as solid supports in
      electrogenerated chemiluminescence assays. The graphitic nanotubes are chemical modified with
      functional group biomols. prior to use in an assay. Association of electrochemiluminescent
      ruthenium complexes with the functional group biomol.-modified nanotubes permits detection of
     mols. including nucleic acids, antigens, enzymes, and enzyme substrates by multiple formats.
IT
        (affinity; graphitic nanotubes in luminescence assays of
        biomols. and biopolymers)
IT
     Nanotubes
       Nanotubes
     RL: ARG (Analytical reagent use); RCT (Reactant); ANST (Analytical study);
     RACT (Reactant or reagent); USES (Uses)
        (carbon fibers; graphitic nanotubes in luminescence assays of
        biomols. and biopolymers)
IT
     Nanotubes
     RL: ARG (Analytical reagent use); RCT (Reactant); ANST (Analytical study);
     RACT (Reactant or reagent); USES (Uses)
        (carbon; graphitic nanotubes in luminescence assays of
        biomols. and biopolymers)
     Optical detectors
TT
        (chemiluminescence, electro-; graphitic nanotubes in
        luminescence assays of biomols. and biopolymers)
IT
     Luminescence, chemiluminescence
         (detectors, electro-; graphitic nanotubes in luminescence
        assays of biomols. and biopolymers)
IT
     Chemiluminescence spectroscopy
         (electro-; graphitic nanotubes in luminescence assays of
        biomols. and biopolymers)
IT
     Immunoassav
         (electrochemiluminescence; graphitic nanotubes in
         luminescence assays of biomols. and biopolymers)
IT
     Biosensors
         (enzymic; graphitic nanotubes in luminescence assays of
        biomols. and biopolymers)
     Avidins
IT
      Polyoxyalkylenes, preparation
      Proteins, general, preparation
      RL: ARG (Analytical reagent use); SPN (Synthetic preparation); ANST
      (Analytical study); PREP (Preparation); USES (Uses)
         (graphitic nanotube conjugates; graphitic nanotubes
         in luminescence assays of biomols. and biopolymers)
      Biochemical molecules
IT
        Biosensors
      Biotinylation
```

L62 ANSWER 14 OF 14 HCAPLUS COPYRIGHT ACS on STN

## L65 ANSWER 24 OF 35 HCAPLUS COPYRIGHT ACS on STN

- AN 1997:158320 HCAPLUS
- ED Entered STN: 10 Mar 1997
- TI Self-assembly of cyclic peptide based nanotubes on gold and silicon dioxide surfaces
- AU Buriak, Jillian M.; Ghadiri, M. Reza
- CS Department Chemistry, Scripps Research Institute, La Jolla, CA, 92037, USA
- SO Book of Abstracts, 213th ACS National Meeting, San Francisco, April 13-17 (1997), INOR-853 Publisher: American Chemical Society, Washington, D. C. CODEN: 64AOAA
- DT Conference; Meeting Abstract
- LA English
- AB Cyclic peptides with alternating D-,L- chirality around the ring self-assemble into hollow, hydrogen-bonded nanotube structures. Functionalization of the amide nitrogens on one face of the cyclic peptides with alkyl thiols and alkyl chlorosilanes allows binding of the peptide to gold and silicon dioxide surfaces, resp. Bidentate binding of the cyclic peptide to the surface, followed by self-assembly of one or more appropriately functionalized cyclic peptides, yields nanotubes perpendicular to the surface. Application of these nanotube arrays as biosensors will be discussed.

#### L32 ANSWER 75 OF 82 HCAPLUS COPYRIGHT ACS on STN 1997:151861 HCAPLUS DN 126:261049 ED Entered STN: 08 Mar 1997 ΤI Towards amperometric immunosensor devices Tiefenauer, Louis X.; Kossek, Sebastian; Padeste, Celestino; Thiebaud, CS Micro- and Nanostructures Laboratory, Paul scherrer Institut, Villigen PSI, CH-5235, Switz. Biosensors & Bioelectronics (1997), 12(3), 213-223 CODEN: BBIOE4; ISSN: 0956-5663 PB Elsevier Journal DT English LA CC 9-1 (Biochemical Methods) In contrast to optical immunosensors, the electrochem. detection of an immunoanal. reaction AB does require a labeling, but allows an easier discrimination of specific and non-specific binding. We present a concept and first results for a multivalent amperometric immunosensor system which is based on silicon technol. The capture mol. streptavidin, covalently immobilized on silica, allows the immobilization of biotinylated antigens at a defined d. A nanostructured gold electrode serving as a stable network of nanowires is expected to be beneficial for the electrochem. detection of bound ferrocene-labeled antibody mols. The results presented focus on site-specific immobilization of streptavidin on silica and reduction of non-specific binding of proteins. ST amperometric immunosensor devices IT Antigens RL: PEP (Physical, engineering or chemical process); RCT (Reactant); PROC (Process); RACT (Reactant or reagent) (Biotinylated; towards amperometric immunosensor devices) TT Biosensors (immunosensors, Amperometric; towards amperometric immunosensor devices) IT Immobilization, biochemical (towards amperometric immunosensor devices) ΙT 102-54-5, Ferrocene RL: ARG (Analytical reagent use); ANST (Analytical study); USES (Uses) (towards amperometric immunosensor devices)

9013-20-1, Streptavidin

ΙT

7631-86-9, Silica, uses

RL: DEV (Device component use); USES (Uses) (towards amperometric immunosensor devices)

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L64 ANSWER 5 OF 5 HCAPLUS COPYRIGHT ACS on STN
    1997:77063 HCAPLUS
ΑN
DN
    126:86777
ED
    Entered STN: 03 Feb 1997
    Probes for sensing and manipulating microscopic environments and
IN
     Baldeschwieler, John D.; Baselt, David; Unger, Mark A.; O'Connor, Stephen
PΑ
    California Institute of Technology, USA
    PATENT NO.
                       KIND DATE
                                          APPLICATION NO.
                                                                  DATE
                               -----
     _____
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                                           ______
                               19961205 WO 1996-US6777
    WO 9638705
                        A1
                                                                  19960513 <--
PΙ
     US 5824470
                        Α
                               19981020 US 1995-453958
                                                                  19950530
    AU 9658575
                        A1
                               19961218
                                         AU 1996-58575
                                                                  19960513 <--
PRAI US 1995-453958
                       Α
                               19950530 <--
    WO 1996-US6777
                        W
                               19960513 <--
     Probes for sensing and manipulating microscopic environments and structures, their method of
AB
     preparation, and methods of use are disclosed. The invention relates especially to a chemical
     functionalized scanning probe tip. Probes are provided for functions beyond the imaging of
     microscopic surfaces, e.g., tips are provided with specific functional moieties to target
     and/or interact with biol. mols. in vivo or to assist in nanochem., lithog., or
     nanofabrication techniques. Accordingly, an object of the invention is to provide a method of
     preparing a probe tip functionalized with chemical moieties. Another object involves the
     preparation of a probe tip suitable for scanning probe microscopy comprising a single
     macromol. attached at its apex. Several other objects of the invention are described.
IT
     Nanotubes
     RL: DEV (Device component use); USES (Uses)
        (carbon; probes for sensing and manipulating microscopic environments
        and structures)
     Peptides, reactions
IT
     RL: PEP (Physical, engineering or chemical process); RCT (Reactant); PROC
     (Process); RACT (Reactant or reagent)
        (cyclic, immobilized; probes for sensing and manipulating microscopic
        environments and structures)
     Alkanes, reactions
IT
     RL: RCT (Reactant); RACT (Reactant or reagent)
        (diazo; probes for sensing and manipulating microscopic environments
        and structures)
IT
     DNA
     RL: PEP (Physical, engineering or chemical process); RCT (Reactant); PROC
     (Process); RACT (Reactant or reagent)
        (double-stranded; probes for sensing and manipulating microscopic
        environments and structures)
ΙT
     Hydrocarbons, reactions
     RL: RCT (Reactant); RACT (Reactant or reagent)
        (halo; probes for sensing and manipulating microscopic environments and
        structures)
     Biochemical molecules
TT
        (immobilized; probes for sensing and manipulating microscopic
        environments and structures)
ΙT
     Biopolymers
     RL: DEV (Device component use); PEP (Physical, engineering or chemical
     process); PROC (Process); USES (Uses)
        (immobilized; probes for sensing and manipulating microscopic
        environments and structures)
TΤ
     Enzymes, reactions
     RL: PEP (Physical, engineering or chemical process); RCT (Reactant); PROC
     (Process); RACT (Reactant or reagent)
        (immobilized; probes for sensing and manipulating microscopic
        environments and structures)
TT
     Peptides, reactions
     RL: PEP (Physical, engineering or chemical process); RCT (Reactant); PROC
     (Process); RACT (Reactant or reagent)
        (immobilized; probes for sensing and manipulating microscopic
```

environments and structures)

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L32 ANSWER 78 OF 82 HCAPLUS COPYRIGHT ACS on STN
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- AN 1996:654720 HCAPLUS
- DN 125:343612
- ED Entered STN: 06 Nov 1996
- TI Nonlithographic nano-wire arrays: Fabrication, physics, and device applications
- AU Routkevitch, Dmitri; Tager, A. A.; Haruyama, Junji; Almawlawi, Diyaa; Moskovits, Martin; Xu, Jimmy M.
- CS Ontario Laser & Lightwave Research Centre, University Toronto, Toronto, ON, M5S 3H6, Can.
- SO IEEE Transactions on Electron Devices (1996), 43(10), 1646-1658 CODEN: IETDAI; ISSN: 0018-9383
- PB Institute of Electrical and Electronics Engineers
- DT Journal; General Review
- LA English
- CC 76-0 (Electric Phenomena)
- A novel system of nanostructures is described consisting of nonlithog, produced arrays of AB nano-wires directly electrodeposited into porous anodic aluminum oxide templates. Using this method regular and uniform arrays of metal or semiconductor nano-wires or nano-dots can be created with diams. ranging from .apprx.5 nm to several hundred nanometers and with areal pore densities in the .apprx.109-1011 cm-2 range. We report on the present state of their fabrication, properties, and prospective device applications. Results of X-ray diffraction, Raman and magnetic measurements on metal (Ni, Fe) and semiconductor (CdS, CdSe, CdSxSel-x, CdxZnl-xS and GaAs) wires are presented. The I-V characteristics of two terminal devices made from the nano-arrays are found to exhibit room temperature periodic conductance oscillations and Coulomb-blockade like current staircases. These observations are likely associated with the ultra-small tunnel junctions that are formed naturally in the arrays. Single-electron tunneling (SET) in the presence of interwire coupling in these arrays is shown to lead to the spontaneous electrostatic polarization of the wires. Possible device applications such as magnetic memory or sensors, electroluminescent flat-panel displays, and nanoelectronic and single-electronic devices are also discussed. 40 Refs.
- ST review semiconductor device electrochem deposition alumina
- IT Electrodeposition and Electroplating

Semiconductor devices

(electrochem. deposition techniques in fabrication of nano-wire arrays)

IT Metals, processes

Semiconductor materials

## Sensors

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(electrochem. deposition techniques in fabrication of nano-wire arrays)

IT Optical imaging devices

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(flat panel displays; electrochem. deposition techniques in fabrication of nano-wire arrays)

IT Tunneling

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(single-electron; electrochem. deposition techniques in fabrication of nano-wire arrays)

IT Memory devices

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(magnetic, electrochem. deposition techniques in fabrication of nano-wire arrays)

IT Wire

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(nanowire, electrochem. deposition techniques in fabrication
of nano-wire arrays)

IT 1344-28-1, Alumina, processes

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

- L58 ANSWER 10 OF 10 HCAPLUS COPYRIGHT ACS on STN
- AN 1996:415735 HCAPLUS
- ED Entered STN: 16 Jul 1996
- TI Molecular dynamics of ion-transport and water diffusion in self-assembling peptide nanotubes.
- AU Bashford, D.; Engels, M.; Ghadiri, M. R.
- CS Scripps Research Institute, La Jolla, CA, 92037, USA
- SO Book of Abstracts, 212th ACS National Meeting, Orlando, FL, August 25-29 (1996), PHYS-323 Publisher: American Chemical Society, Washington, D. C. CODEN: 63BFAF
- DT Conference; Meeting Abstract
- LA English
- We have performed several mol. dynamics simulations of water-filled self-assembled peptide nanotubes, and potential of mean force calcns. for ions in such tubes. The peptide structures consist of beta-sheet-like hydrogen-bonded stacks of flat cyclic peptides of alternating D and L amino acids. The simulations elucidate the way in which tube geometry and patterns of polar and non-polar atoms along the tube walls lead to a semi-regular structure of water in the tube, and anal. of trajectories shows a complex hopping mechanism by which transport rates reach much higher values than those of the analogous gramicidin channel. An analogy to the conductivity of n-type semiconductors is presented. Nanotubes of this kind can be synthesized in a variety of sizes, and can be designed to self-insert into membranes or covalently attach to electrode surfaces. Their differential ion-transport properties can potentially be exploited in devices such as biosensor arrays.

4/9/8 DIALOG(R) File 94: JICST-EPlus © Japan Science and Tech Corp(JST). All rts. reserv. JICST ACCESSION NUMBER: 96A0843707 FILE SEGMENT: JICST-E Lattice Distortion with Spatial Variation of Carbon Nanotubes in Magnetic Fields. AJIKI H (1); ANDO T (1) (1) University Tokyo, Tokyo J Phys Soc Jpn, 1996, VOL.65, NO.9, PAGE.2976-2986, FIG.12, REF.33 ISSN NO: 0031-9015 CODEN: JUPSA JOURNAL NUMBER: G0509AAI UNIVERSAL DECIMAL CLASSIFICATION: 539.124:621.315.592 COUNTRY OF PUBLICATION: Japan LANGUAGE: English DOCUMENT TYPE: Journal ARTICLE TYPE: Original paper MEDIA TYPE: Printed Publication A lattice instability of carbon nanotubes induced by a magnetic field perpendicular to the tube axis is studied in a kvp scheme. Both in-plane Kekule and out-of-plane distortions are enhanced drastically with increase of a magnetic field independent of whether a nanotube is metallic or semiconducting and magnetic flux passing through the cross section of a nanotube. The distortions become dependent on the position in the circumference direction. (author abst.) DESCRIPTORS: carbon; molecular cluster; perturbation theory; effective mass ; crystal lattice; lattice distortion; magnetic field effect; Landau level; semiconductivity; metallicity BROADER DESCRIPTORS: second row element; element; carbon group element; molecule; approximation method; mass (mechanical quantity); mechanical quantity; lattice; strain; effect; energy level; electrical property;

property

CLASSIFICATION CODE(S): BM02060N

4/9/9

DIALOG(R) File 94: JICST-EPlus

(c) Japan Science and Tech Corp(JST). All rts. reserv.

02516855 JICST ACCESSION NUMBER: 96A0835664 FILE SEGMENT: PreJICST-E Lattice Distortion with Spatial Variation of Carbon Nanotubes in Magnetic Fields.

AJIKI H (1); ANDO T (1)

(1) University Tokyo, Tokyo

Tech Rep ISSP Ser A, 1996, NO.3167, PAGE.14p

JOURNAL NUMBER: S0273AAA ISSN NO: 0082-4798 CODEN: TISSB

LANGUAGE: English COUNTRY OF PUBLICATION: Japan

DOCUMENT TYPE: Journal

MEDIA TYPE: Printed Publication

ABSTRACT: A lattice instability of carbon nanotubes induced by a magnetic field perpendicular to the tube axis is studied in a k p scheme. Both in-plane Kekule and out-of-plane distortions are enhanced drastically with increase of a magnetic field independent of whether a nanotube is metallic or semiconducting and magnetic flux passing through the cross section of a nanotube. The distortions become dependent on the position in the circumference direction. (author abst.)

4/9/10

DIALOG(R) File 94: JICST-EPlus

(c)2005 Japan Science and Tech Corp(JST). All rts. reserv.

02487384 JICST ACCESSION NUMBER: 96A0446425 FILE SEGMENT: PreJICST-E Carbon Nanotubes: Effects of Magnetic Fields on Lattice Distortions.

AJIKI H (1); ANDO T (1)

(1) University Tokyo, Tokyo Tech Rep ISSP Ser A, 1996, NO.3112, PAGE.6p

JOURNAL NUMBER: S0273AAA ISSN NO: 0082-4798 CODEN: TISSB

LANGUAGE: English COUNTRY OF PUBLICATION: Japan

DOCUMENT TYPE: Journal

MEDIA TYPE: Printed Publication

ABSTRACT: A lattice instability is studied for carbon nanotubes in a magnetic field perpendicular to the tube axis in a k p approximation. A strong magnetic field dramatically enhances the distortion at the top and bottom parts of the cylinder surface for both metallic and

semiconducting nanotubes with large circumference. (author abst.)

#### L32 ANSWER 22 OF 82 HCAPLUS COPYRIGHT ACS on STN 2000:518228 HCAPLUS AN 133:246007 DN Entered STN: 31 Jul 2000 ED Single-electron detector and counter ΤI Stone, N. J.; Ahmed, H. ΑU Microelectronics Research Centre, Cavendish Laboratory, Cambridge, CB3 CS OHE, UK Applied Physics Letters (2000), 77(5), 744-746 CODEN: APPLAB; ISSN: 0003-6951 American Institute of Physics PB Journal DTEnglish LA 76-14 (Electric Phenomena) CC An electron detector, constructed with highly doped silicon nanowires, is described. It is AΒ shown that, at a temperature of 4.2 K, the presence or absence of a single excess electron on a storage node can be recognized. The detector can also be used to count the precise number of electrons transferred to the node. single electron detector silicon nanowire ST Nanowires (metallic) IΤ (electron detectors from highly doped silicon nanowires) IT Electron detectors (single-electron detector and counter) 7440-21-3, Silicon, uses RL: DEV (Device component use); USES (Uses) (electron detectors from highly doped silicon nanowires) THERE ARE 9 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT RE (1) Dutta, A; Appl Phys Lett 1999, V75, P10 (2) Field, M; Semicond Sci Technol 1996, V11, P1498 HCAPLUS (3) Fulton, T; Phys Rev Lett 1991, V67, P3148 (4) Guo, L; Science 1997, V275, P649 HCAPLUS (5) Lafarge, P; Acad Sci, Paris 1992, V314, P883 HCAPLUS (6) Lafarge, P; Z Phys B: Condens Matter 1991, V85, P327 (7) Lotkhov, S; Appl Phys Lett 1999, V75, P2665 HCAPLUS (8) Nakazato, K; Jpn J Appl Phys, Part 1 1995, V34, P700 HCAPLUS

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# L32 ANSWER 67 OF 82 HCAPLUS COPYRIGHT ACS on STN

AN 1998:207459 HCAPLUS

DN 128:237612

ED Entered STN: 11 Apr 1998

TI Silicon bulk micromachining and nanomachining

AU Esashi, Masayoshi; Minami, Kazuyuki; Ono, Takahito

CS Faculty Engineering, Tohoku University, Sendai, 980, Japan

SO Condensed Matter News (1998), 6(3-4), 31-44

CODEN: CMAWE8; ISSN: 1056-7046

PB Gordon & Breach Science Publishers

DT Journal; General Review

LA English

CC 76-0 (Electric Phenomena)

As a review with 26 refs. on advanced Si microsensors for pressure, acceleration, angular rate, IR radiation, and atomic force developed based on bulk Si micromachining. Distortion-free, precise, or very small micro- to nanostructures enable extremely sensitive and quick response sensors. Packaged, capacitive, and integrated sensors were fabricated. Electrostatic force balancing sensors and resonant sensors performed wide dynamic range and high sensitivity, resp. Novel micromachining techniques developed and applied for the sensors are vacuum packaging, distortion-free anodic bonding, deep RIE, XeF2 Si etching, thickness monitoring during Si etching, Si nanowire growth by elec. field evaporation using UHV STM, etc.

Microactuators like microvalves, optical scanners, and active catheters that moves flexibly in a blood vessel were developed.

ST review silicon bulk micromachining nanomachining; microsensor silicon pressure acceleration radiation review; microdevice silicon fabrication review

IT Micromachines

Micromachining

Microsensors

Semiconductor device fabrication

(Si bulk micromachining and nanomachining for fabrication of microsensors and micromachines)

IT 7440-21-3, Silicon, properties

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PRP (Properties); PROC (Process); USES (Uses)

(Si bulk micromachining and nanomachining for fabrication of microsensors and micromachines)

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ANSWER 4 OF 5 HCAPLUS COPYRIGHT ACS on STN
L19
    1999:770746 HCAPLUS Full-text
AN
    132:160229
DN
     Entered STN: 07 Dec 1999
ED
     Controlled Chemical Routes to Nanotube Architectures, Physics, and Devices
TΙ
     Dai, Hongjie; Kong, Jing; Zhou, Chongwu;
ΑU
     Franklin, Nathan; Tombler, Thomas; Cassell, Alan; Fan, Shoushan;
     Chapline, Michael
     Department of Chemistry, Stanford University, Stanford, CA, 94305, USA
CS
     Journal of Physical Chemistry B (1999), 103(51), 11246-11255
SO
     CODEN: JPCBFK; ISSN: 1089-5647
PB
     American Chemical Society
DT
     Journal
LA
     English
     78-1 (Inorganic Chemicals and Reactions)
CC
     Section cross-reference(s): 76
     This article presents the authors' recent work in the controlled synthesis of multiwalled
AΒ
      (MWNT) and single-walled nanotubes (SWNT) with ordered architectures. The general synthesis
     approach involves CVD using rationally designed catalyst and substrates. The results include
      self-oriented MWNTs, individual SWNTs grown from controlled surface sites, and structures of
      suspended SWNTs along well-defined directions. The chemical derived nanotube architectures
     have opened up new possibilities in fundamental characterization and potential applications of
     nanotube materials. Systematic electron transport measurements are carried out to elucidate
      the elec. properties of various classes of SWNTs and to explore the physics in 1-dimensional
      systems. High-performance elec. devices based on individual SWNTs are enabled by combining
      synthesis and microfabrication approaches.
     carbon nanotube SWNT MWNT prepn elec property
ST
     RL: PEP (Physical, engineering or chemical process); PRP (Properties); SPN
     (Synthetic preparation); PREP (Preparation); PROC (Process)
        (carbon; growth and electron transport properties of single-walled and
        multiwalled carbon nanotubes)
     Electric conductivity
IT
     Electric current-potential relationship
     Electric resistance
     Electric transport properties
     Field effect transistors
        (growth and electron transport properties of single-walled and
        multiwalled carbon nanotubes)
     7440-44-0P, Carbon, preparation
TT
     RL: PEP (Physical, engineering or chemical process); PRP (Properties); SPN
     (Synthetic preparation); PREP (Preparation); PROC (Process)
        (growth and electron transport properties of single-walled and
        multiwalled carbon nanotubes)
              THERE ARE 68 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE.CNT
        68
RE
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